

# IGLOOe Low Power Flash FPGAs

## with Flash\*Freeze Technology

## Features and Benefits

#### **Low Power**

- 1.2 V to 1.5 V Core Voltage Support for Low Power
- Supports Single-Voltage System Operation
- Low-Power Active FPGA Operation
- Flash\*Freeze Technology Enables Ult Consumption while Maintaining FPGA Content Ultra-Low Power
- Flash\*Freeze Pin Allows Easy Entry to / Exit from Ultra-Low-Power Flash\*Freeze Mode

#### High Capacity

- 600 k to 3 Million System Gates
- 108 to 504 kbits of True Dual-Port SRAM
- Up to 341 User I/Os

#### Reprogrammable Flash Technology

- 130-nm, 7-Layer Metal (6 Copper), Flash-Based CMOS **Process**
- Instant On Level 0 Support
- Single-Chip Solution
- Retains Programmed Design when Powered Off
- 250 MHz (1.5 V systems) and 160 MHz (1.2 V systems) System Performance

#### In-System Programming (ISP) and Security

- ISP Using On-Chip 128-Bit Advanced Encryption Standard (AES) Decryption via JTAG (IEEE 1532–compliant) FlashLock® Designed to Secure FPGA Contents

#### High-Performance Routing Hierarchy

- Segmented, Hierarchical Routing and Clock Structure
- High-Performance, Low-Skew Global Network Architecture Supports Ultra-High Utilization

#### Pro (Professional) I/O

- 700 Mbps DDR, LVDS-Capable I/Os
- 1.2 V, 1.5 V, 1.8 V, 2.5 V, and 3.3 V Mixed-Voltage Operation

- Bank-Selectable I/O Voltages—Up to 8 Banks per Chip Single-Ended I/O Standards: LVTTL, LVCMOS 3.3 V / 2.5 V / 1.8 V / 1.5 V / 1.2 V, 3.3 V PCI / 3.3 V PCI-X, and LVCMOS 2.5 V / 5.0 V Input
- Differential I/O Standards: LVPECL, LVDS, B-LVDS, and M-LVDS
- Voltage-Referenced I/O Standards: GTL+ 2.5 V / 3.3 V, GTL 2.5 V / 3.3 V, HSTL Class I and II, SSTL2 Class I and II, SSTL3 Class I and II
- Wide Range Power Supply Voltage Support per JESD8-B, Allowing I/Os to Operate from 2.7 V to 3.6 V
- Wide Range Power Supply Voltage Support per JESD8-12, Allowing I/Os to Operate from 1.14 V to 1.575 V
- I/O Registers on Input, Output, and Enable Paths
- Hot-Swappable and Cold-Sparing I/Os
- Programmable Output Slew Rate and Drive Strength
- Programmable Input Delay Schmitt Trigger Option on Single-Ended Inputs
- Weak Pull-Up/-Down
- IEEE 1149.1 (JTAG) Boundary Scan Test Pin-Compatible Packages across the IGLOO®e Family

#### Clock Conditioning Circuit (CCC) and PLL

- Six CCC Blocks, Each with an Integrated PLL
- Configurable Phase Shift, Multiply/Divide, Delay Capabilities, and External Feedback
- Wide Input Frequency Range (1.5 MHz up to 250 MHz)

#### **Embedded Memory**

- 1 kbit of FlashROM User Nonvolatile Memory
- SRAMs and FIFOs with Variable-Aspect-Ratio 4,608-Bit RAM Blocks (×1, ×2, ×4, ×9, and ×18 organizations available)
- True Dual-Port SRAM (except ×18)

#### ARM Processor Support in IGLOOe FPGAs

M1 IGLOOe Devices—Cortex™-M1 Soft Processor Available with or without Debug

#### Table 1 • IGLOOe Product Family

IGLOOe Devices	AGLE600	AGLE3000
ARM-Enabled IGLOOe Devices		M1AGLE3000
System Gates	600,000	3,000,000
VersaTiles (D-flip-flops)	13,824	75,264
Quiescent Current (typical) in Flash*Freeze Mode (μW)	49	137
RAM kbits (1,024 bits)	108	504
4,608-Bit Blocks	24	112
FlashROM Kbits (1,024 bits)	1	1
Secure (AES) ISP	Yes	Yes
CCCs with Integrated PLLs	6	6
VersaNet Globals <sup>1</sup>	18	18
I/O Banks	8	8
Maximum User I/Os	165	341
Package Pins FBGA	FG256	FG484

#### Notes:

- 1. Refer to the Cortex-M1 Handbook for more information.
- 2. Six chip (main) and twelve quadrant global networks are available.
- For devices supporting lower densities, refer to the IGLOO Low-Power Flash FPGAs with Flash\*Freeze Technology datasheet.

October 2019



# I/Os Per Package 1

IGLOOe Devices	AGLE600		AGLE3000		
ARM-Enabled IGLOOe Devices	M1AGLE3000			E3000	
	I/O Types				
Package	Single-Ended I/O <sup>1</sup>	Differential I/O Pairs	Single-Ended I/O <sup>1</sup>	Differential I/O Pairs	
FG256	165	79	-	_	
	-	_	341	168	

#### Notes:

- 1. When considering migrating your design to a lower- or higher-density device, refer to the IGLOOe FPGA Fabric User's Guide to ensure compliance with design and board migration requirements.
- 2. Each used differential I/O pair reduces the number of single-ended I/Os available by two.
- 3. For AGLE3000 devices, the usage of certain I/O standards is limited as follows:
  - SSTL3(I) and (II): up to 40 I/Os per north or south bank
  - LVPECL / GTL+ 3.3 V / GTL 3.3 V: up to 48 I/Os per north or south bank
  - SSTL2(I) and (II) / GTL+ 2.5 V/ GTL 2.5 V: up to 72 I/Os per north or south bank
- 4. FG256 and FG484 are footprint-compatible packages.
- 5. When using voltage-referenced I/O standards, one I/O pin should be assigned as a voltage-referenced pin (VREF) per minibank (group of I/Os).
- 6. When the Flash\*Freeze pin is used to directly enable Flash\*Freeze mode and not as a regular I/O, the number of single-ended user I/Os available is reduced by one.
- 7. "G" indicates RoHS-compliant packages. Refer to "IGLOOe Ordering Information" on page III for the location of the "G" in the part number.

## **IGLOOe FPGAs Package Sizes Dimensions**

Package	FG256	FG484
Length × Width (mm × mm)	17 × 17	23 × 23
Nominal Area (mm2)	289	529
Pitch (mm)	1	1
Height (mm)	1.6	2.23

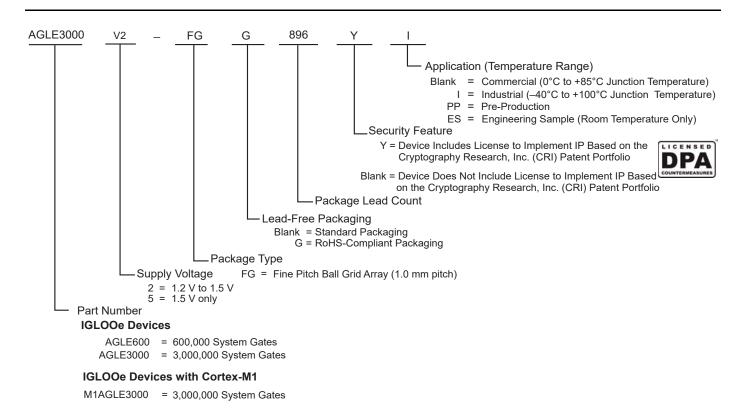
## **IGLOOe Device Status**

IGLOOe Devices	Status	M1 IGLOOe Devices	Status
AGLE600	Production		
AGLE3000	Production	M1AGLE3000	Production

Revision 14



# **IGLOOe Ordering Information**



Note: Marking Information: IGLOO V2 devices do not have V2 marking, but IGLOO V5 devices are marked accordingly.

Revision 14 III



# **Temperature Grade Offerings**

	AGLE600 AGLE3000	
Package		M1AGLPE3000
FG256	C, I	-
FG484	-	C, I

Note:  $C = Commercial temperature range: 0^{\circ}C to 85^{\circ}C junction temperature.$  $I = Industrial temperature range: -40^{\circ}C to 100^{\circ}C junction temperature.$ 

References made to IGLOOe devices also apply to ARM-enabled IGLOOe devices. The ARM-enabled part numbers start with M1 (Cortex-M1).

Contact your local Microsemi SoC Products Group representative for device availability:

http://www.microsemi.com/soc/contact/default.aspx.

Revision 14 IV



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# 1 – IGLOOe Device Family Overview

## **General Description**

The IGLOOe family of flash FPGAs, based on a 130-nm flash process, offers the lowest power FPGA, a single-chip solution, small footprint packages, reprogrammability, and an abundance of advanced features.

The Flash\*Freeze technology used in IGLOOe devices enables entering and exiting an ultra-low power mode while retaining SRAM and register data. Flash\*Freeze technology simplifies power management through I/O and clock management with rapid recovery to operation mode.

The Low Power Active capability (static idle) allows for ultra-low power consumption while the IGLOOe device is completely functional in the system. This allows the IGLOOe device to control system power management based on external inputs (e.g., scanning for keyboard stimulus) while consuming minimal power.

Nonvolatile flash technology gives IGLOOe devices the advantage of being a secure, low power, singlechip solution that is Instant On. IGLOOe is reprogrammable and offers time-to-market benefits at an ASIC-level unit cost.

These features enable designers to create high-density systems using existing ASIC or FPGA design flows and tools.

IGLOOe devices offer 1 kbit of on-chip, programmable, nonvolatile FlashROM storage as well as clock conditioning circuitry based on 6 integrated phase-locked loops (PLLs). IGLOOe devices have up to 3 million system gates, supported with up to 504 kbits of true dual-port SRAM and up to 341 user I/Os.

M1 IGLOOe devices support the high-performance, 32-bit Cortex-M1 processor developed by ARM for implementation in FPGAs. Cortex-M1 is a soft processor that is fully implemented in the FPGA fabric. It has a three-stage pipeline that offers a good balance between low power consumption and speed when implemented in an M1 IGLOOe device. The processor runs the ARMv6-M instruction set, has a configurable nested interrupt controller, and can be implemented with or without the debug block. Cortex-M1 is available for free from Microsemi for use in M1 IGLOOe FPGAs.

The ARM-enabled devices have Microsemi ordering numbers that begin with M1AGLE and do not support AES decryption.

## Flash\*Freeze Technology

The IGLOOe device offers unique Flash\*Freeze technology, allowing the device to enter and exit ultralow power Flash\*Freeze mode. IGLOOe devices do not need additional components to turn off I/Os or clocks while retaining the design information, SRAM content, and registers. Flash\*Freeze technology is combined with in-system programmability, which enables users to quickly and easily upgrade and update their designs in the final stages of manufacturing or in the field. The ability of IGLOOe V2 devices to support a wide range of core voltage (1.2 V to 1.5 V) allows further reduction in power consumption, thus achieving the lowest total system power.

When the IGLOOe device enters Flash\*Freeze mode, the device automatically shuts off the clocks and inputs to the FPGA core; when the device exits Flash\*Freeze mode, all activity resumes and data is retained

The availability of low power modes, combined with reprogrammability, a single-chip and single-voltage solution, and availability of small-footprint, high pin-count packages, make IGLOOe devices the best fit for portable electronics.



## Flash Advantages

#### Low Power

Flash-based IGLOOe devices exhibit power characteristics similar to those of an ASIC, making them an ideal choice for power-sensitive applications. IGLOOe devices have only a very limited power-on current surge and no high-current transition period, both of which occur on many FPGAs.

IGLOOe devices also have low dynamic power consumption to further maximize power savings; power is even further reduced by the use of a 1.2 V core voltage.

Low dynamic power consumption, combined with low static power consumption and Flash\*Freeze technology, gives the IGLOOe device the lowest total system power offered by any FPGA.

## Security

The nonvolatile, flash-based IGLOOe devices do not require a boot PROM, so there is no vulnerable external bitstream that can be easily copied. IGLOOe devices incorporate FlashLock, which provides a unique combination of reprogrammability and design security without external overhead, advantages that only an FPGA with nonvolatile flash programming can offer.

IGLOOe devices utilize a 128-bit flash-based lock and a separate AES key to provide the highest level of protection in the FPGA industry for programmed intellectual property and configuration data. In addition, all FlashROM data in IGLOOe devices can be encrypted prior to loading, using the industry-leading AES-128 (FIPS192) bit block cipher encryption standard. AES was adopted by the National Institute of Standards and Technology (NIST) in 2000 and replaces the 1977 DES standard. IGLOOe devices have a built-in AES decryption engine and a flash-based AES key that make them the most comprehensive programmable logic device security solution available today. IGLOOe devices with AES-based security provide a high level of protection for remote field updates over public networks such as the Internet, and are designed to ensure that valuable IP remains out of the hands of system overbuilders, system cloners, and IP thieves.

Security, built into the FPGA fabric, is an inherent component of the IGLOOe family. The flash cells are located beneath seven metal layers, and many device design and layout techniques have been used to make invasive attacks extremely difficult. The IGLOOe family, with FlashLock and AES security, is unique in being highly resistant to both invasive and noninvasive attacks. Your valuable IP is protected with industry-standard security, making remote ISP possible. An IGLOOe device provides the best available security for programmable logic designs.

#### Single Chip

Flash-based FPGAs store their configuration information in on-chip flash cells. Once programmed, the configuration data is an inherent part of the FPGA structure, and no external configuration data needs to be loaded at system power-up (unlike SRAM-based FPGAs). Therefore, flash-based IGLOOe FPGAs do not require system configuration components such as EEPROMs or microcontrollers to load device configuration data. This reduces bill-of-materials costs and PCB area, and increases security and system reliability.

#### Instant On

Flash-based IGLOOe devices support Level 0 of the Instant On classification standard. This feature helps in system component initialization, execution of critical tasks before the processor wakes up, setup and configuration of memory blocks, clock generation, and bus activity management. The Instant On feature of flash-based IGLOOe devices greatly simplifies total system design and reduces total system cost, often eliminating the need for CPLDs and clock generation PLLs. In addition, glitches and brownouts in system power will not corrupt the IGLOOe device's flash configuration, and unlike SRAM-based FPGAs, the device will not have to be reloaded when system power is restored. This enables the reduction or complete removal of the configuration PROM, expensive voltage monitor, brownout detection, and clock generator devices from the PCB design. Flash-based IGLOOe devices simplify total system design and reduce cost and design risk while increasing system reliability and improving system initialization time.



## Reduced Cost of Ownership

Advantages to the designer extend beyond low unit cost, performance, and ease of use. Unlike SRAM-based FPGAs, Flash-based IGLOOe devices allow all functionality to be Instant On; no external boot PROM is required. On-board security mechanisms prevent access to all the programming information and enable secure remote updates of the FPGA logic. Designers can perform secure remote in-system reprogramming to support future design iterations and field upgrades with confidence that valuable intellectual property cannot be compromised or copied. Secure ISP can be performed using the industry-standard AES algorithm. The IGLOOe family device architecture mitigates the need for ASIC migration at higher user volumes. This makes the IGLOOe family a cost-effective ASIC replacement solution, especially for applications in the consumer, networking/communications, computing, and avionics markets.

## Firm-Error Immunity

Firm errors occur most commonly when high-energy neutrons, generated in the upper atmosphere, strike a configuration cell of an SRAM FPGA. The energy of the collision can change the state of the configuration cell and thus change the logic, routing, or I/O behavior in an unpredictable way. These errors are impossible to prevent in SRAM FPGAs. The consequence of this type of error can be a complete system failure. Firm errors do not exist in the configuration memory of IGLOOe flash-based FPGAs. Once it is programmed, the flash cell configuration element of IGLOOe FPGAs cannot be altered by high-energy neutrons and is therefore immune to them. Recoverable (or soft) errors occur in the user data SRAM of all FPGA devices. These can easily be mitigated by using error detection and correction (EDAC) circuitry built into the FPGA fabric.

## Advanced Flash Technology

The IGLOOe family offers many benefits, including nonvolatility and reprogrammability, through an advanced flash-based, 130-nm LVCMOS process with seven layers of metal. Standard CMOS design techniques are used to implement logic and control functions. The combination of fine granularity, enhanced flexible routing resources, and abundant flash switches allows for very high logic utilization without compromising device routability or performance. Logic functions within the device are interconnected through a four-level routing hierarchy.

IGLOOe family FPGAs utilize design and process techniques to minimize power consumption in all modes of operation.

#### Advanced Architecture

The proprietary IGLOOe architecture provides granularity comparable to standard-cell ASICs. The IGLOOe device consists of five distinct and programmable architectural features (Figure 1-1 on page 4):

- Flash\*Freeze technology
- FPGA VersaTiles
- · Dedicated FlashROM
- Dedicated SRAM/FIFO memory
- · Extensive CCCs and PLLs
- Pro I/O structure

The FPGA core consists of a sea of VersaTiles. Each VersaTile can be configured as a three-input logic function, a D-flip-flop (with or without enable), or a latch by programming the appropriate flash switch interconnections. The versatility of the IGLOOe core tile as either a three-input lookup table (LUT) equivalent or a D-flip-flop/latch with enable allows for efficient use of the FPGA fabric. The VersaTile capability is unique to the Microsemi ProASIC<sup>®</sup> family of third-generation-architecture flash FPGAs. VersaTiles are connected with any of the four levels of routing hierarchy. Flash switches are distributed throughout the device to provide nonvolatile, reconfigurable interconnect programming. Maximum core utilization is possible for virtually any design.



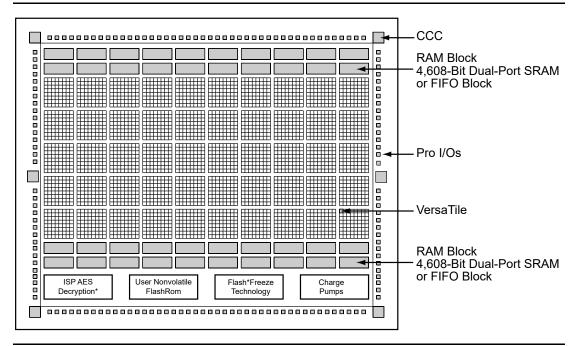


Figure 1-1 • IGLOOe Device Architecture Overview

## Flash\*Freeze Technology

The IGLOOe device has an ultra-low power static mode, called Flash\*Freeze mode, which retains all SRAM and register information and can still quickly return to normal operation. Flash\*Freeze technology enables the user to quickly (within 1 µs) enter and exit Flash\*Freeze mode by activating the Flash\*Freeze pin while all power supplies are kept at their original values. In addition, I/Os and global I/Os can still be driven and can be toggling without impact on power consumption, clocks can still be driven or can be toggling without impact on power consumption, and the device retains all core registers, SRAM information, and states. I/O states are tristated during Flash\*Freeze mode or can be set to a certain state using weak pull-up or pull-down I/O attribute configuration. No power is consumed by the I/O banks, clocks, JTAG pins, or PLL in this mode.

Flash\*Freeze technology allows the user to switch to active mode on demand, thus simplifying the power management of the device.

The Flash\*Freeze pin (active low) can be routed internally to the core to allow the user's logic to decide when it is safe to transition to this mode. It is also possible to use the Flash\*Freeze pin as a regular I/O if Flash\*Freeze mode usage is not planned, which is advantageous because of the inherent low power static and dynamic capabilities of the IGLOOe device. Refer to Figure 1-2 for an illustration of entering/exiting Flash\*Freeze mode.

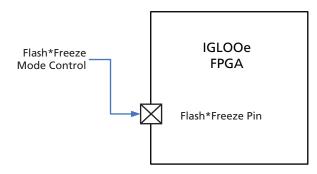


Figure 1-2 • IGLOOe Flash\*Freeze Mode



#### VersaTiles

The IGLOOe core consists of VersaTiles, which have been enhanced beyond the ProASICPLUS® core tiles. The IGLOOe VersaTile supports the following:

- · All 3-input logic functions—LUT-3 equivalent
- · Latch with clear or set
- · D-flip-flop with clear or set
- · Enable D-flip-flop with clear or set

Refer to Figure 1-3 for VersaTile configurations.

# LUT-3 Equivalent D-Flip-Flop with Clear or Set Data CLK CLR D-FF CLR CLR CLR CLR CLR

Figure 1-3 • VersaTile Configurations

#### User Nonvolatile FlashROM

IGLOOe devices have 1 kbit of on-chip, user-accessible, nonvolatile FlashROM. The FlashROM can be used in diverse system applications:

- · Internet protocol addressing (wireless or fixed)
- · System calibration settings
- Device serialization and/or inventory control
- Subscription-based business models (for example, set-top boxes)
- Secure key storage for secure communications algorithms
- Asset management/tracking
- Date stamping
- Version management

The FlashROM is written using the standard IGLOOe IEEE 1532 JTAG programming interface. The core can be individually programmed (erased and written), and on-chip AES decryption can be used selectively to securely load data over public networks, as in security keys stored in the FlashROM for a user design.

The FlashROM can be programmed via the JTAG programming interface, and its contents can be read back either through the JTAG programming interface or via direct FPGA core addressing. Note that the FlashROM can only be programmed from the JTAG interface and cannot be programmed from the internal logic array.

The FlashROM is programmed as 8 banks of 128 bits; however, reading is performed on a byte-by-byte basis using a synchronous interface. A 7-bit address from the FPGA core defines which of the 8 banks and which of the 16 bytes within that bank are being read. The three most significant bits (MSBs) of the FlashROM address determine the bank, and the four least significant bits (LSBs) of the FlashROM address define the byte.

The IGLOOe development software solutions, Libero<sup>®</sup> System-on-Chip (SoC) and Designer, have extensive support for the FlashROM. One such feature is auto-generation of sequential programming files for applications requiring a unique serial number in each part. Another feature allows the inclusion of static data for system version control. Data for the FlashROM can be generated quickly and easily using Libero SoC and Designer software tools. Comprehensive programming file support is also included to allow for easy programming of large numbers of parts with differing FlashROM contents.



#### SRAM and FIFO

IGLOOe devices have embedded SRAM blocks along their north and south sides. Each variable-aspect-ratio SRAM block is 4,608 bits in size. Available memory configurations are 256×18, 512×9, 1k×4, 2k×2, and 4k×1 bits. The individual blocks have independent read and write ports that can be configured with different bit widths on each port. For example, data can be sent through a 4-bit port and read as a single bitstream. The embedded SRAM blocks can be initialized via the device JTAG port (ROM emulation mode) using the UJTAG macro.

In addition, every SRAM block has an embedded FIFO control unit. The control unit allows the SRAM block to be configured as a synchronous FIFO without using additional core VersaTiles. The FIFO width and depth are programmable. The FIFO also features programmable Almost Empty (AEMPTY) and Almost Full (AFULL) flags in addition to the normal Empty and Full flags. The embedded FIFO control unit contains the counters necessary for generation of the read and write address pointers. The embedded SRAM/FIFO blocks can be cascaded to create larger configurations.

#### PLL and CCC

IGLOOe devices provide designers with very flexible clock conditioning capabilities. Each member of the IGLOOe family contains six CCCs, each with an integrated PLL.

The six CCC blocks are located at the four corners and the centers of the east and west sides. One CCC (center west side) has a PLL.

The inputs of the six CCC blocks are accessible from the FPGA core or from one of several inputs located near the CCC that have dedicated connections to the CCC block.

The CCC block has these key features:

- Wide input frequency range (f<sub>IN CCC</sub>) = 1.5 MHz up to 250 MHz
- Output frequency range (f<sub>OUT CCC</sub>) = 0.75 MHz up to 250 MHz
- 2 programmable delay types for clock skew minimization
- · Clock frequency synthesis

#### Additional CCC specifications:

- Internal phase shift = 0°, 90°, 180°, and 270°. Output phase shift depends on the output divider configuration.
- Output duty cycle = 50% ± 1.5% or better
- Low output jitter: worst case < 2.5% × clock period peak-to-peak period jitter when single global network used
- Maximum acquisition time is 300 µs
- Exceptional tolerance to input period jitter—allowable input jitter is up to 1.5 ns
- Four precise phases; maximum misalignment between adjacent phases of 40 ps × 250 MHz / fout\_ccc

#### Global Clocking

IGLOOe devices have extensive support for multiple clocking domains. In addition to the CCC and PLL support described above, there is a comprehensive global clock distribution network.

Each VersaTile input and output port has access to nine VersaNets: six chip (main) and three quadrant global networks. The VersaNets can be driven by the CCC or directly accessed from the core via multiplexers (MUXes). The VersaNets can be used to distribute low-skew clock signals or for rapid distribution of high-fanout nets.



## Pro I/Os with Advanced I/O Standards

The IGLOOe family of FPGAs features a flexible I/O structure, supporting a range of voltages (1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.0 V wide range, and 3.3 V). IGLOOe FPGAs support 19 different I/O standards, including single-ended, differential, and voltage-referenced. The I/Os are organized into banks, with eight banks per device (two per side). The configuration of these banks determines the I/O standards supported. Each I/O bank is subdivided into VREF minibanks, which are used by voltage-referenced I/Os. VREF minibanks contain 8 to 18 I/Os. All the I/Os in a given minibank share a common VREF line. Therefore, if any I/O in a given VREF minibank is configured as a VREF pin, the remaining I/Os in that minibank will be able to use that reference voltage.

Each I/O module contains several input, output, and enable registers. These registers allow the implementation of the following:

- Single-Data-Rate applications (e.g., PCI 66 MHz, bidirectional SSTL 2 and 3, Class I and II)
- Double-Data-Rate applications (e.g., DDR LVDS, B-LVDS, and M-LVDS I/Os for point-to-point communications, and DDR 200 MHz SRAM using bidirectional HSTL Class II).

IGLOOe banks support M-LVDS with 20 multi-drop points.

Hot-swap (also called hot-plug, or hot-insertion) is the operation of hot-insertion or hot-removal of a card in a powered-up system.

Cold-sparing (also called cold-swap) refers to the ability of a device to leave system data undisturbed when the system is powered up, while the component itself is powered down, or when power supplies are floating.

## Wide Range I/O Support

IGLOOe devices support JEDEC-defined wide range I/O operation. IGLOOe devices support both the JESD8-B specification, covering 3.0 V and 3.3 V supplies, for an effective operating range of 2.7 V to 3.6 V, and JESD8-12 with its 1.2 V nominal, supporting an effective operating range of 1.14 V to 1.575 V.

Wider I/O range means designers can eliminate power supplies or power conditioning components from the board or move to less costly components with greater tolerances. Wide range eases I/O bank management and provides enhanced protection from system voltage spikes, while providing the flexibility to easily run custom voltage applications.

## **Specifying I/O States During Programming**

You can modify the I/O states during programming in FlashPro. In FlashPro, this feature is supported for PDB files generated from Designer v8.5 or greater. See the *FlashPro User's Guide* for more information.

Note: PDB files generated from Designer v8.1 to Designer v8.4 (including all service packs) have limited display of Pin Numbers only.

- Load a PDB from the FlashPro GUI. You must have a PDB loaded to modify the I/O states during programming.
- From the FlashPro GUI, click PDB Configuration. A FlashPoint Programming File Generator window appears.
- Click the Specify I/O States During Programming button to display the Specify I/O States During Programming dialog box.
- 4. Sort the pins as desired by clicking any of the column headers to sort the entries by that header. Select the I/Os you wish to modify (Figure 1-4 on page 1-8).
- Set the I/O Output State. You can set Basic I/O settings if you want to use the default I/O settings for your pins, or use Custom I/O settings to customize the settings for each pin. Basic I/O state settings:
  - 1 I/O is set to drive out logic High
  - 0 I/O is set to drive out logic Low

Last Known State – I/O is set to the last value that was driven out prior to entering the programming mode, and then held at that value during programming

Z -Tri-State: I/O is tristated



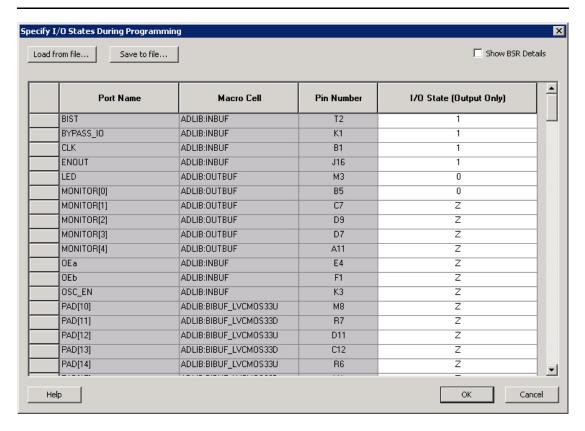


Figure 1-4 • I/O States During Programming Window

6. Click OK to return to the FlashPoint - Programming File Generator window.

Note: I/O States During programming are saved to the ADB and resulting programming files after completing programming file generation.



# 2 - IGLOOe DC and Switching Characteristics

## **General Specifications**

## **Operating Conditions**

Stresses beyond those listed in Table 2-1 may cause permanent damage to the device.

Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Absolute Maximum Ratings are stress ratings only; functional operation of the device at these or any other conditions beyond those listed under the Recommended Operating Conditions specified in Table 2-2 on page 2-2 is not implied.

Table 2-1 • Absolute Maximum Ratings

Symbol	Parameter	Limits		
VCC	DC core supply voltage	-0.3 to 1.65	V	
VJTAG	JTAG DC voltage	-0.3 to 3.75	V	
VPUMP	Programming voltage	-0.3 to 3.75	V	
VCCPLL	Analog power supply (PLL)	-0.3 to 1.65	V	
VCCI and VMV <sup>3</sup>	DC I/O buffer supply voltage	-0.3 to 3.75	V	
VI	I/O input voltage	-0.3 V to 3.6 V (when I/O hot insertion mode is enabled) -0.3 V to (VCCI + 1 V) or 3.6 V, whichever voltage is lower (when I/O hot-insertion mode is disabled)		
T <sub>STG</sub> <sup>2</sup>	Storage temperature	-65 to +150	°C	
T <sub>J</sub> <sup>2</sup>	Junction temperature	+125	°C	

## Notes:

- 1. The device should be operated within the limits specified by the datasheet. During transitions, the input signal may undershoot or overshoot according to the limits shown in Table 2-4 on page 2-3.
- 2. For flash programming and retention maximum limits, refer to Table 2-3 on page 2-3, and for recommended operating limits, refer to Table 2-2 on page 2-2.
- 3. VMV pins must be connected to the corresponding VCCI pins. See the "VMVx I/O Supply Voltage (quiet)" section on page 3-1 for further information.



Table 2-2 • Recommended Operating Conditions <sup>1</sup>

Symbol	Paran	neter	Commercial	Industrial	Units
T <sub>J</sub>	Junction Temperature <sup>2</sup>		0 to + 85	-40 to +100	°C
VCC <sup>3</sup>	1.5 V DC core supply voltage <sup>4</sup>		1.425 to 1.575	1.425 to 1.575	V
	1.2 V–1.5 V wide range DC core voltage <sup>5, 6</sup>		1.14 to 1.575	1.14 to 1.575	V
VJTAG	JTAG DC voltage		1.4 to 3.6	1.4 to 3.6	V
VPUMP	Programming voltage <sup>6</sup>	Programming Mode	3.15 to 3.45	3.15 to 3.45	V
		Operation <sup>7</sup>	0 to 3.6	0 to 3.6	V
VCCPLL <sup>8</sup>	Analog power supply (PLL)	1.5 V DC core supply voltage <sup>4</sup>	1.425 to 1.575	1.425 to 1.575	V
		1.2 V–1.5 V DC core supply voltage <sup>5</sup>	1.14 to 1.575	1.14 to 1.575	V
VCCI and	1.2 V DC supply voltage <sup>5</sup>		1.14 to 1.26	1.14 to 1.26	V
VMV <sup>9</sup>	1.2 V wide range DC supply voltage <sup>5</sup>		1.14 to 1.575	1.14 to 1.575	V
	1.5 V DC supply voltage		1.425 to 1.575	1.425 to 1.575	V
	1.8 V DC supply voltage		1.7 to 1.9	1.7 to 1.9	V
	2.5 V DC supply voltage		2.3 to 2.7	2.3 to 2.7	V
	3.0 V DC supply voltage <sup>10</sup>		2.7 to 3.6	2.7 to 3.6	V
	3.3 V DC supply voltage		3.0 to 3.6	3.0 to 3.6	V
	LVDS differential I/O		2.375 to 2.625	2.375 to 2.625	V
	LVPECL differential I/O		3.0 to 3.6	3.0 to 3.6	V

#### Notes:

- 1. All parameters representing voltages are measured with respect to GND unless otherwise specified.
- 2. Software Default Junction Temperature Range is set to 0°C 70°C for commercial, and -40°C 85°C for industrial. To ensure targeted reliability standards are met across the full range of junction temperatures, Microsemi recommends using temperature custom settings for running timing and power analysis tools. For more information regarding custom settings, please refer to the New Project Dialog Box component in the Designer in Libero SOC section of the Libero User Guide.
- 3. The ranges given here are for power supplies only. The recommended input voltage ranges specific to each I/O standard are given in Table 2-21 on page 2-20. VCCI should be at the same voltage within a given I/O bank.
- 4. For IGLOOe V5 devices
- 5. For IGLOOe V2 devices only, operating at VCCI ≥ VCC
- 6. All IGLOOe devices (V5 and V2) must be programmed with the VCC core voltage at 1.5 V. Applications using the V2 devices powered by a 1.2 V supply must switch the core supply to 1.5 V for in-system programming.
- 7. VPUMP can be left floating during operation (not programming mode).
- 8. VCCPLL pins should be tied to VCC pins. See the "VCCPLA/B/C/D/E/F PLL Supply Voltage" section for further information.
- 9. VMV pins must be connected to the corresponding VCCI pins. See the "VMVx I/O Supply Voltage (quiet)" section for further information.
- 10. 3.3 V wide range is compliant to the JESD8-B specification and supports 3.0 V VCCI operation.



Table 2-3 • Flash Programming Limits – Retention, Storage, and Operating Temperature<sup>1</sup>

Product Grade	•	Program Retention (biased/unbiased)	Maximum Storage Temperature T <sub>STG</sub> (°C) <sup>2</sup>	Maximum Operating Junction Temperature T <sub>J</sub> (°C) <sup>2</sup>
Commercial	500	20 years	110	100
Industrial	500	20 years	110	100

#### Notes:

- 1. This is a stress rating only; functional operation at any condition other than those indicated is not implied.
- These limits apply for program/data retention only. Refer to Table 2-1 on page 2-1 and Table 2-2 for device operating conditions and absolute limits.

Table 2-4 • Overshoot and Undershoot Limits 1,3

VCCI	Average VCCI–GND Overshoot or Undershoot Duration as a Percentage of Clock Cycle <sup>2</sup>	Maximum Overshoot/ Undershoot <sup>2</sup>
2.7 V or less	10%	1.4 V
	5%	1.49 V
3 V	10%	1.1 V
	5%	1.19 V
3.3 V	10%	0.79 V
	5%	0.88 V
3.6 V	10%	0.45 V
	5%	0.54 V

#### Notes:

- 1. Based on reliability requirements at junction temperature at 85°C.
- 2. The duration is allowed at one out of six clock cycles. If the overshoot/undershoot occurs at one out of two cycles, the maximum overshoot/undershoot has to be reduced by 0.15 V.
- 3. This table does not provide PCI overshoot/undershoot limits.

# I/O Power-Up and Supply Voltage Thresholds for Power-On Reset (Commercial and Industrial)

Sophisticated power-up management circuitry is designed into every IGLOOe device. These circuits ensure easy transition from the powered-off state to the powered-up state of the device. The many different supplies can power up in any sequence with minimized current spikes or surges. In addition, the I/O will be in a known state through the power-up sequence. The basic principle is shown in Figure 2-1 on page 2-4 and Figure 2-2 on page 2-5.

There are five regions to consider during power-up.

IGLOOe I/Os are activated only if ALL of the following three conditions are met:

- 1. VCC and VCCI are above the minimum specified trip points (Figure 2-1 on page 2-4 and Figure 2-2 on page 2-5).
- 2. VCCI > VCC 0.75 V (typical)
- 3. Chip is in the operating mode.

#### **VCCI Trip Point:**

Ramping up: 0.6 V < trip\_point\_up < 1.2 V Ramping down: 0.5 V < trip\_point\_down < 1.1 V

**VCC Trip Point:** 

Ramping up: 0.6 V < trip\_point\_up < 1.1 V Ramping down: 0.5 V < trip\_point\_down < 1 V

VCC and VCCI ramp-up trip points are about 100 mV higher than ramp-down trip points. This specifically built-in hysteresis prevents undesirable power-up oscillations and current surges. Note the following:

During programming, I/Os become tristated and weakly pulled up to VCCI.



 JTAG supply, PLL power supplies, and charge pump VPUMP supply have no influence on I/O behavior.

#### PLL Behavior at Brownout Condition

Microsemi recommends using monotonic power supplies or voltage regulators to ensure proper powerup behavior. Power ramp-up should be monotonic at least until VCC and VCCPLX exceed brownout activation levels. The VCC activation level is specified as 1.1 V worst-case (see Figure 2-1 and Figure 2-2 on page 2-5 for more details).

When PLL power supply voltage and/or VCC levels drop below the VCC brownout levels (0.75 V  $\pm$  0.25 V), the PLL output lock signal goes low and/or the output clock is lost. Refer to the "Power-Up/-Down Behavior of Low Power Flash Devices" chapter of the *IGLOOe FPGA Fabric User's Guide* for information on clock and lock recovery.

#### Internal Power-Up Activation Sequence

- 1. Core
- 2. Input buffers

Output buffers, after 200 ns delay from input buffer activation.

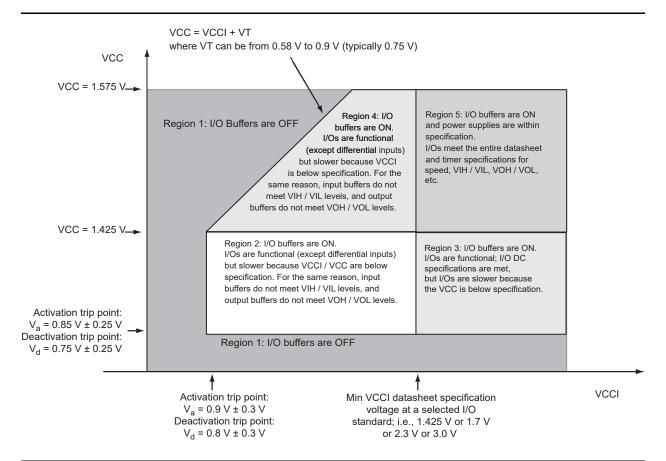


Figure 2-1 • V5 – I/O State as a Function of VCCI and VCC Voltage Levels



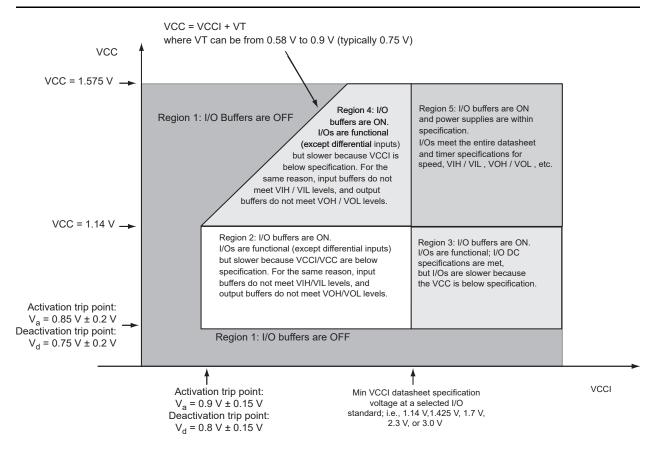


Figure 2-2 • V2 Devices - I/O State as a Function of VCCI and VCC Voltage Levels

#### **Thermal Characteristics**

#### Introduction

The temperature variable in Microsemi Designer software refers to the junction temperature, not the ambient temperature. This is an important distinction because dynamic and static power consumption cause the chip junction to be higher than the ambient temperature.

EQ 1 can be used to calculate junction temperature.

 $T_J$  = Junction Temperature =  $\Delta T + T_A$ 

EQ1

#### where:

T<sub>A</sub> = Ambient Temperature

 $\Delta T$  = Temperature gradient between junction (silicon) and ambient  $\Delta T$  =  $\theta_{ia}$  \* P

 $\theta_{ia}$  = Junction-to-ambient of the package.  $\theta_{ia}$  numbers are located in Table 2-5.

P = Power dissipation



## Package Thermal Characteristics

The device junction-to-case thermal resistivity is  $\theta_{jc}$  and the junction-to-ambient air thermal resistivity is  $\theta_{ja}$ . The thermal characteristics for  $\theta_{ja}$  are shown for two air flow rates. The absolute maximum junction temperature is 100°C. EQ 2 shows a sample calculation of the absolute maximum power dissipation allowed for an 896-pin FBGA package at commercial temperature and in still air.

Maximum Power Allowed = 
$$\frac{\text{Max. junction temp. (°C)} - \text{Max. ambient temp. (°C)}}{\theta_{ja}(°\text{C/W})} = \frac{100°\text{C} - 70°\text{C}}{13.6°\text{C/W}} = 2.206 \text{ W}$$

EQ 2

Table 2-5 • Package Thermal Resistivities

			$ heta_{ja}$			
Package Type	Pin Count	$\theta_{ extsf{jc}}$	Still Air	200 ft./min.	500 ft./min.	Units
Plastic Quad Flat Package (PQFP)	208	8.0	26.1	22.5	20.8	C/W
Plastic Quad Flat Package (PQFP) with embedded heat spreader	208	3.8	16.2	13.3	11.9	C/W
Fine Pitch Ball Grid Array (FBGA)	256	3.8	26.9	22.8	21.5	C/W
	484	3.2	20.5	17.0	15.9	C/W
	676	3.2	16.4	13.0	12.0	C/W
	896	2.4	13.6	10.4	9.4	C/W

## Temperature and Voltage Derating Factors

Table 2-6 • Temperature and Voltage Derating Factors for Timing Delays (normalized to T<sub>J</sub> = 70°C,VCC = 1.425 V)
For IGLOOe V2 or V5 devices, 1.5 V DC Core Supply Voltage

Array Voltage			Junction Tem	perature (°C)		
ACC (A)	-40°C	0°C	25°C	70°C	85°C	100°C
1.425	0.945	0.965	0.978	1.000	1.008	1.013
1.500	0.876	0.893	0.906	0.927	0.934	0.940
1.575	0.824	0.840	0.852	0.872	0.879	0.884

Table 2-7 • Temperature and Voltage Derating Factors for Timing Delays (normalized to T<sub>J</sub> = 70°C, VCC = 1.14 V)
For IGLOOe V2, 1.2 V DC Core Supply Voltage

Array Voltage			Junction Tem	perature (°C)		
VCC (V)	-40°C	0°C	25°C	70°C	85°C	100°C
1.14	0.968	0.978	0.991	1.000	1.006	1.010
1.20	0.864	0.873	0.885	0.893	0.898	0.902
1.26	0.793	0.803	0.813	0.821	0.826	0.829



## **Calculating Power Dissipation**

## **Quiescent Supply Current**

Quiescent supply current (IDD) calculation depends on multiple factors, including operating voltages (VCC, VCCI, and VJTAG), operating temperature, system clock frequency, and power modes usage. Microsemi recommends using the PowerCalculator and SmartPower software estimation tools to evaluate the projected static and active power based on the user design, power mode usage, operating voltage, and temperature.

Table 2-8 • Power Supply State per Mode

Power Supply Configurations					
Modes/power supplies	vcc	VCCPLL	VCCI	VJTAG	VPUMP
Flash*Freeze	On	On	On	On	On/off/floating
Sleep	Off	Off	On	Off	Off
Shutdown	Off	Off	Off	Off	Off
No Flash*Freeze	On	On	On	On	On/off/floating

Note: Off: Power supply level = 0 V

Table 2-9 • Quiescent Supply Current (IDD), IGLOOe Flash\*Freeze Mode\*

	Core Voltage	AGLE600	AGLE3000	Units
Typical (25°C)	1.2 V	34	95	μΑ
	1.5 V	72	310	μΑ

Note: \*IDD includes VCC, VPUMP, VCCI, VCCPLL, and VMV currents. Values do not include I/O static contribution, which is shown in Table 2-13 on page 2-9 and Table 2-14 on page 2-10 (PDC6 and PDC7).

Table 2-10 • Quiescent Supply Current (IDD) Characteristics, IGLOOe Sleep Mode\*

	Core Voltage	AGLE600	AGLE3000	Units
VCCI/VJTAG = 1.2 V (per bank) Typical (25°C)	1.2 V	1.7	1.7	μA
VCCI/VJTAG = 1.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.8	1.8	μA
VCCI/VJTAG = 1.8 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.9	1.9	μA
VCCI/VJTAG = 2.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.2	2.2	μA
VCCI/VJTAG= 3.3 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.5	2.5	μA

Note: \*IDD =  $N_{BANKS}$  × ICCI. Values do not include I/O static contribution, which is shown in Table 2-13 on page 2-9 and Table 2-14 on page 2-10 (PDC6 and PDC7).

Table 2-11 • Quiescent Supply Current (IDD) Characteristics, IGLOOe Shutdown Mode\*

	Core Voltage	AGLE600	AGLE3000	Units
Typical (25°C)	1.2 V / 1.5 V	0	0	μΑ



Table 2-12 • Quiescent Supply Current (IDD) Characteristics, No Flash\*Freeze Mode<sup>1</sup>

	Core Voltage	AGLE600	AGLE3000	Units
ICCA Current <sup>2</sup>			•	
Typical (25°C)	1.2 V	28	89	μΑ
	1.5 V	82	320	μA
ICCI or IJTAG Current <sup>3</sup>				
VCCI/VJTAG = 1.2 V (per bank) Typical (25°C)	1.2 V	1.7	1.7	μΑ
VCCI/VJTAG = 1.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.8	1.8	μΑ
VCCI/VJTAG = 1.8 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.9	1.9	μΑ
VCCI/VJTAG = 2.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.2	2.2	μΑ
VCCI/VJTAG= 3.3 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.5	2.5	μΑ

#### Notes:

- 1.  $IDD = N_{BANKS} \times ICCI + ICCA$ . JTAG counts as one bank when powered. 2. Includes VCC and VPUMP and VCCPLL currents.
- 3. Values do not include I/O static contribution (PDC6 and PDC7).



## Power per I/O Pin

Table 2-13 • Summary of I/O Input Buffer Power (per pin) - Default I/O Software Settings

	VCCI (V)	Static Power PDC6 (mW) <sup>1</sup>	Dynamic Power PAC9 (μW/MHz) <sup>2</sup>
Single-Ended	l.		L
3.3 V LVTTL/LVCMOS	3.3	_	16.34
3.3 V LVTTL/LVCMOS – Schmitt trigger	3.3	_	24.49
3.3 V LVCMOS Wide Range <sup>3</sup>	3.3	_	16.34
3.3 V LVCMOS Wide Range – Schmitt trigger <sup>3</sup>	3.3	_	24.49
2.5 V LVCMOS	2.5	-	4.71
2.5 V LVCMOS	2.5	_	6.13
1.8 V LVCMOS	1.8	_	1.66
1.8 V LVCMOS – Schmitt trigger	1.8	_	1.78
1.5 V LVCMOS (JESD8-11)	1.5	_	1.01
1.5 V LVCMOS (JESD8-11) – Schmitt trigger	1.5	_	0.97
1.2 V LVCMOS <sup>4</sup>	1.2	-	0.60
1.2 V LVCMOS – Schmitt trigger <sup>4</sup>	1.2	-	0.53
1.2 V LVCMOS Wide Range <sup>4</sup>	1.2	_	0.60
1.2 V LVCMOS Wide Range – Schmitt trigger <sup>4</sup>	1.2	_	0.53
3.3 V PCI	3.3	_	17.76
3.3 V PCI – Schmitt trigger	3.3	_	19.10
3.3 V PCI-X	3.3	_	17.76
3.3 V PCI-X – Schmitt trigger	3.3	-	19.10
Voltage-Referenced	•	•	•
3.3 V GTL	3.3	2.90	7.14
2.5 V GTL	2.5	2.13	3.54
3.3 V GTL+	3.3	2.81	2.91
2.5 V GTL+	2.5	2.57	2.61
HSTL (I)	1.5	0.17	0.79
HSTL (II)	1.5	0.17	.079
SSTL2 (I)	2.5	1.38	3.26
SSTL2 (II)	2.5	1.38	3.26
SSTL3 (I)	3.3	3.21	7.97
SSTL3 (II)	3.3	3.21	7.97
Differential			
LVDS	2.5	2.26	0.89
LVPECL	3.3	5.71	1.94

#### Notes:

- 1. PDC6 is the static power (where applicable) measured on VCCI.
- 2. PAC9 is the total dynamic power measured on VCCI.
- 3. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8b specification.
- 4. Applicable for IGLOOe V2 devices only.



Table 2-14 • Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings<sup>1</sup>

	C <sub>LOAD</sub> (pF)	VCCI (V)	Static Power PDC7 (mW) <sup>2</sup>	Dynamic Power PAC10 (μW/MHz) <sup>3</sup>
Single-Ended		•	•	•
3.3 V LVTTL/LVCMOS	5	3.3	_	148.00
3.3 V LVCMOS Wide Range <sup>4</sup>	5	3.3	-	148.00
2.5 V LVCMOS	5	2.5	_	83.23
1.8 V LVCMOS	5	1.8	_	54.58
1.5 V LVCMOS (JESD8-11)	5	1.5	-	37.05
1.2 V LVCMOS (JESD8-11)	5	1.2	_	17.94
1.2 V LVCMOS (JESD8-11) – Wide Range				17.94
3.3 V PCI	10	3.3	_	204.61
3.3 V PCI-X	10	3.3	_	204.61
Voltage-Referenced				
3.3 V GTL	10	3.3	_	24.08
2.5 V GTL	10	2.5	_	13.52
3.3 V GTL+	10	3.3	-	24.10
2.5 V GTL+	10	2.5	_	13.54
HSTL (I)	20	1.5	7.08	26.22
HSTL (II)	20	1.5	13.88	27.18
SSTL2 (I)	30	2.5	16.69	105.56
SSTL2 (II)	30	2.5	25.91	116.60
SSTL3 (I)	30	3.3	26.02	114.67
SSTL3 (II)	30	3.3	42.21	131.69
Differential			•	•
LVDS	_	2.5	7.70	89.62
LVPECL	-	3.3	19.42	167.86

#### Notes:

- 1. Dynamic power consumption is given for standard load and software default drive strength and output slew.
- 2. PDC7 is the static power (where applicable) measured on VCCI.
- 3. PAC10 is the total dynamic power measured on VCCI.
- 4. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8b specification.



## **Power Consumption of Various Internal Resources**

Table 2-15 • Different Components Contributing to the Dynamic Power Consumption in IGLOOe Devices For IGLOOe V2 or V5 Devices, 1.5 V DC Core Supply Voltage

		Device-Specific Dynamic Contributions (μW/MHz)	
Parameter	Definition	AGLE600	AGLE3000
PAC1	Clock contribution of a Global Rib	19.7	12.77
PAC2	Clock contribution of a Global Spine	4.16	1.85
PAC3	Clock contribution of a VersaTile row	0	.88
PAC4	Clock contribution of a VersaTile used as a sequential module	0.11	
PAC5	First contribution of a VersaTile used as a sequential module	0.057	
PAC6	Second contribution of a VersaTile used as a sequential module	0.207	
PAC7	Contribution of a VersaTile used as a combinatorial module	0.	207
PAC8	Average contribution of a routing net	(	).7
PAC9	Contribution of an I/O input pin (standard-dependent)	See Table 2-	13 on page 2-9.
PAC10	Contribution of an I/O output pin (standard-dependent)	See Table 2-14 on page 2-10.	
PAC11	Average contribution of a RAM block during a read operation	25.00	
PAC12	Average contribution of a RAM block during a write operation	30.00	
PAC13	Dynamic contribution for PLL	2	.70

Note: For a different output load, drive strength, or slew rate, Microsemi recommends using the Microsemi power calculator or SmartPower in Libero SoC software.

Table 2-16 • Different Components Contributing to the Static Power Consumption in IGLOO Devices For IGLOOe V2 or V5 Devices, 1.5 V DC Core Supply Voltage

		Device Specific Static Power (mW	
Parameter	Definition	AGLE600	AGLE3000
PDC1	Array static power in Active mode	See Table 2-12 on page 2-8.	
PDC2	Array static power in Static (Idle) mode	See Table 2-11 on page 2-7.	
PDC3	Array static power in Flash*Freeze mode	See Table 2-9	on page 2-7.
PDC4	Static PLL contribution	1.84	1
PDC5	Bank quiescent power (VCCI-dependent)	See Table 2-12	on page 2-8.
PDC6	I/O input pin static power (standard-dependent)	See Table 2-13 on page 2-9.	
PDC7	I/O output pin static power (standard-dependent)	See Table 2-14	on page 2-10.



Table 2-17 • Different Components Contributing to the Dynamic Power Consumption in IGLOOe Devices For IGLOOe V2 Devices, 1.2 V DC Core Supply Voltage

			cific Dynamic ons (µW/MHz)	
Parameter	Definition	AGLE600	AGLE3000	
PAC1	Clock contribution of a Global Rib	12.61	8.17	
PAC2	Clock contribution of a Global Spine	2.66	1.18	
PAC3	Clock contribution of a VersaTile row	C	0.56	
PAC4	Clock contribution of a VersaTile used as a sequential module	0	.071	
PAC5	First contribution of a VersaTile used as a sequential module	0	.045	
PAC6	Second contribution of a VersaTile used as a sequential module	0	.186	
PAC7	Contribution of a VersaTile used as a combinatorial module	0	.109	
PAC8	Average contribution of a routing net	0.	449	
PAC9	Contribution of an I/O input pin (standard-dependent)	See Table 2-	9 on page 2-7.	
PAC10	Contribution of an I/O output pin (standard-dependent)		10 on page 2-7 11 on page 2-7.	
PAC11	Average contribution of a RAM block during a read operation	2	25.00	
PAC12	Average contribution of a RAM block during a write operation	3	30.00	
PAC13	Dynamic PLL contribution	2	2.10	

Note: For a different output load, drive strength, or slew rate, Microsemi recommends using the Microsemi power calculator or SmartPower in Libero SoC software.

Table 2-18 • Different Components Contributing to the Static Power Consumption in IGLOO Devices For IGLOOe V2 Devices, 1.2 V DC Core Supply Voltage

		Device Specific S	Device Specific Static Power (mW)			
Parameter	Definition	AGLE600	AGLE3000			
PDC1	Array static power in Active mode	See Table 2-12	on page 2-8.			
PDC2	Array static power in Static (Idle) mode	See Table 2-11	See Table 2-11 on page 2-7.			
PDC3	Array static power in Flash*Freeze mode	See Table 2-9	See Table 2-9 on page 2-7.			
PDC4	Static PLL contribution	0.9	0.90			
PDC5	Bank quiescent power (VCCI-dependent)	See Table 2-12	on page 2-8.			
PDC6	I/O input pin static power (standard-dependent)	See Table 2-13	See Table 2-13 on page 2-9.			
PDC7	I/O output pin static power (standard-dependent)	See Table 2-14	See Table 2-14 on page 2-10.			



## **Power Calculation Methodology**

This section describes a simplified method to estimate power consumption of an application. For more accurate and detailed power estimations, use the SmartPower tool in the Libero SoC software.

The power calculation methodology described below uses the following variables:

- · The number of PLLs as well as the number and the frequency of each output clock generated
- · The number of combinatorial and sequential cells used in the design
- · The internal clock frequencies
- · The number and the standard of I/O pins used in the design
- · The number of RAM blocks used in the design
- Toggle rates of I/O pins as well as VersaTiles—guidelines are provided in Table 2-19 on page 2-15.
- Enable rates of output buffers—guidelines are provided for typical applications in Table 2-20 on page 2-15.
- Read rate and write rate to the memory—guidelines are provided for typical applications in Table 2-20 on page 2-15. The calculation should be repeated for each clock domain defined in the design.

## Methodology

#### Total Power Consumption—P<sub>TOTAL</sub>

 $P_{TOTAL} = P_{STAT} + P_{DYN}$ 

P<sub>STAT</sub> is the total static power consumption.

P<sub>DYN</sub> is the total dynamic power consumption.

#### Total Static Power Consumption—P<sub>STAT</sub>

P<sub>STAT</sub> = (PDC1 or PDC2 or PDC3) + N<sub>BANKS</sub> \* PDC5 + N<sub>INPUTS</sub>\* PDC6 + N<sub>OUTPUTS</sub>\* P<sub>DC7</sub>

N<sub>INPUTS</sub> is the number of I/O input buffers used in the design.

N<sub>OUTPUTS</sub> is the number of I/O output buffers used in the design.

N<sub>BANKS</sub> is the number of I/O banks powered in the design.

## Total Dynamic Power Consumption—P<sub>DYN</sub>

PDYN = PCLOCK + PS-CELL + PC-CELL + PNET + PINPUTS + POUTPUTS + PMEMORY + PPLL

#### Global Clock Contribution—P<sub>CLOCK</sub>

N<sub>SPINE</sub> is the number of global spines used in the user design—guidelines are provided in the "Spine Architecture" section of the Global Resources chapter in the *IGLOOe FPGA Fabric User's Guide*.

N<sub>ROW</sub> is the number of VersaTile rows used in the design—guidelines are provided in the "Spine Architecture" section of the Global Resources chapter in the *IGLOOe FPGA Fabric User's Guide*.

F<sub>CLK</sub> is the global clock signal frequency.

N<sub>S-CELL</sub> is the number of VersaTiles used as sequential modules in the design.

PAC1, PAC2, PAC3, and PAC4 are device-dependent.

## Sequential Cells Contribution—P<sub>S-CELL</sub>

$$P_{S-CELL}$$
 =  $N_{S-CELL}$  \* (PAC5 +  $\alpha_1$  / 2 \* PAC6) \*  $F_{CLK}$ 

N<sub>S-CELL</sub> is the number of VersaTiles used as sequential modules in the design. When a multi-tile sequential cell is used, it should be accounted for as 1.

 $\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in Table 2-19 on page 2-15.

F<sub>CLK</sub> is the global clock signal frequency.



#### Combinatorial Cells Contribution—P<sub>C-CELL</sub>

 $P_{C\text{-CELL}} = N_{C\text{-CELL}} * \alpha_1 / 2 * PAC7 * F_{CLK}$ 

N<sub>C-CFLL</sub> is the number of VersaTiles used as combinatorial modules in the design.

 $\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in Table 2-19 on page 2-15.

F<sub>CLK</sub> is the global clock signal frequency.

## Routing Net Contribution—P<sub>NET</sub>

 $P_{NET} = (N_{S-CELL} + N_{C-CELL}) * \alpha_1 / 2 * PAC8 * F_{CLK}$ 

N<sub>S-CELL</sub> is the number of VersaTiles used as sequential modules in the design.

N<sub>C-CFLL</sub> is the number of VersaTiles used as combinatorial modules in the design.

 $\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in Table 2-19 on page 2-15.

F<sub>CLK</sub> is the global clock signal frequency.

#### I/O Input Buffer Contribution—PINPUTS

 $P_{INPUTS} = N_{INPUTS} * \alpha_2 / 2 * PAC9 * F_{CLK}$ 

N<sub>INPUTS</sub> is the number of I/O input buffers used in the design.

 $\alpha_2$  is the I/O buffer toggle rate—guidelines are provided in Table 2-19 on page 2-15.

F<sub>CLK</sub> is the global clock signal frequency.

## I/O Output Buffer Contribution—POUTPUTS

 $P_{OUTPUTS} = N_{OUTPUTS} * \alpha_2 / 2 * \beta_1 * PAC10 * F_{CLK}$ 

 $N_{\mbox{OUTPUTS}}$  is the number of I/O output buffers used in the design.

 $\alpha_2$  is the I/O buffer toggle rate—guidelines are provided in Table 2-19 on page 2-15.

 $\beta_{\text{1}}$  is the I/O buffer enable rate—guidelines are provided in Table 2-20 on page 2-15.

F<sub>CLK</sub> is the global clock signal frequency.

#### RAM Contribution—P<sub>MEMORY</sub>

 $P_{MEMORY} = PAC11 * N_{BLOCKS} * F_{READ-CLOCK} * \beta_2 + PAC12 * N_{BLOCK} * F_{WRITE-CLOCK} * \beta_3$ 

N<sub>BLOCKS</sub> is the number of RAM blocks used in the design.

F<sub>READ-CLOCK</sub> is the memory read clock frequency.

 $\beta_2$  is the RAM enable rate for read operations—guidelines are provided in Table 2-20 on page 2-15.

F<sub>WRITE-CLOCK</sub> is the memory write clock frequency.

 $\beta_3$  is the RAM enable rate for write operations—guidelines are provided in Table 2-20 on page 2-15.

## PLL Contribution—P<sub>PLL</sub>

P<sub>PLL</sub> = PDC4 + PAC13 \* F<sub>CLKOUT</sub>

F<sub>CLKOUT</sub> is the output clock frequency. <sup>1</sup>

If a PLL is used to generate more than one output clock, include each output clock in the formula by adding its corresponding contribution (P<sub>AC13</sub>\* F<sub>CLKOUT</sub> product) to the total PLL contribution.



#### Guidelines

#### **Toggle Rate Definition**

A toggle rate defines the frequency of a net or logic element relative to a clock. It is a percentage. If the toggle rate of a net is 100%, this means that this net switches at half the clock frequency. Below are some examples:

- The average toggle rate of a shift register is 100% as all flip-flop outputs toggle at half of the clock frequency.
- The average toggle rate of an 8-bit counter is 25%:
  - Bit 0 (LSB) = 100%
  - Bit 1 = 50%
  - Bit 2 = 25%
  - ...
  - Bit 7 (MSB) = 0.78125%
  - Average toggle rate = (100% + 50% + 25% + 12.5% + . . . + 0.78125%) / 8

#### **Enable Rate Definition**

Output enable rate is the average percentage of time during which tristate outputs are enabled. When nontristate output buffers are used, the enable rate should be 100%.

Table 2-19 • Toggle Rate Guidelines Recommended for Power Calculation

Component	Definition				
$\alpha_1$	Toggle rate of VersaTile outputs				
$\alpha_2$	I/O buffer toggle rate	10%			

Table 2-20 • Enable Rate Guidelines Recommended for Power Calculation

Component	Definition	Guideline		
$\beta_1$	I/O output buffer enable rate	100%		
$\beta_2$	RAM enable rate for read operations	12.5%		
$\beta_3$	RAM enable rate for write operations	12.5%		



## **User I/O Characteristics**

## **Timing Model**

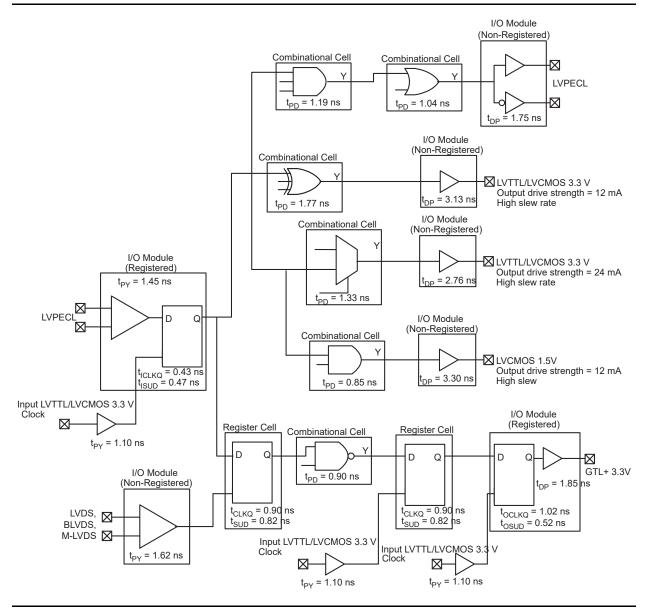


Figure 2-3 • Timing Model
Operating Conditions: Std. Speed, Commercial Temperature Range (T<sub>J</sub> = 70°C), Worst-Case
VCC = 1.425 V, Applicable to 1.5 V DC Core Voltage, V2 and V5 devices



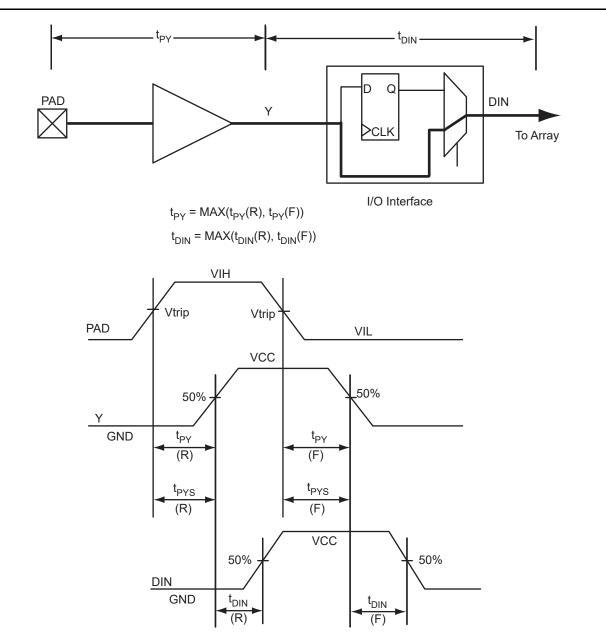


Figure 2-4 • Input Buffer Timing Model and Delays (example)



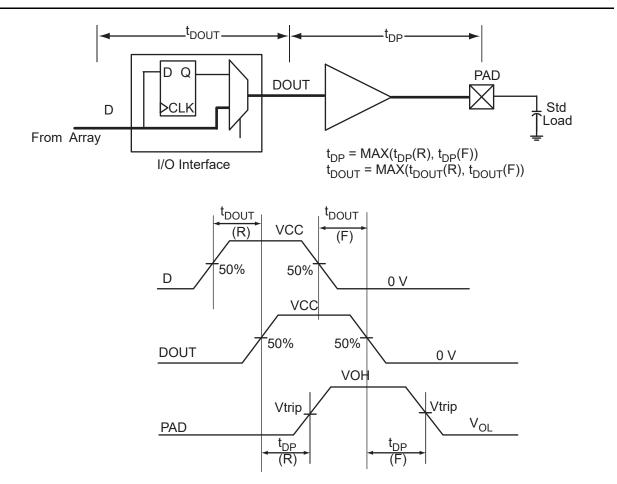


Figure 2-5 • Output Buffer Model and Delays (example)



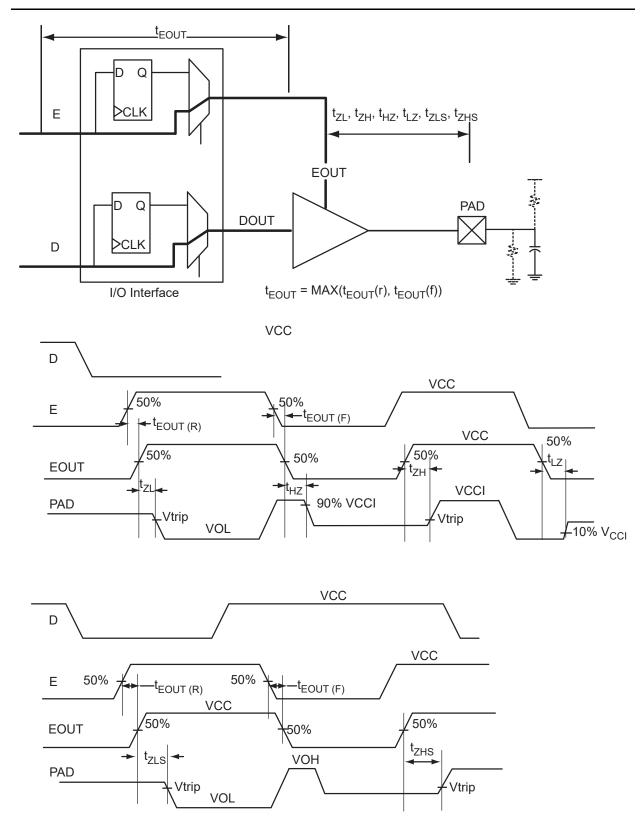


Figure 2-6 • Tristate Output Buffer Timing Model and Delays (example)



## **Overview of I/O Performance**

# Summary of I/O DC Input and Output Levels – Default I/O Software Settings

**Table 2-21 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions** 

		Equivalent			VIL	VIH		VOL	VOH	IOL <sup>1</sup> IOH <sup>1</sup>	
I/O Standard	Drive Strength	Software Default Drive Strength <sup>2</sup>	Slew Rate	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA
3.3 V LVTTL / 3.3 V LVCMOS	12 mA	12 mA	High	-0.3	0.8	2	3.6	0.4	2.4	12	12
3.3 V LVCMOS Wide Range <sup>3</sup>	100 μΑ	12 mA	High	-0.3	0.8	2	3.6	0.2	VCCI - 0.2	0.1	0.1
2.5 V LVCMOS	12 mA	12 mA	High	-0.3	0.7	1.7	3.6	0.7	1.7	12	12
1.8 V LVCMOS	12 mA	12 mA	High	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	12	12
1.5 V LVCMOS	12 mA	12 mA	High	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	12	12
1.2 V LVCMOS	2 mA	2 mA	High	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	2	2
1.2 V LVCMOS Wide Range <sup>4</sup>	100 μΑ	2 mA	High	-0.3	0.3 * VCCI	0.7 * VCCI	3.6	0.1	VCCI - 0.1	0.1	0.1
3.3 V PCI					Per P	CI Specification	n			•	•
3.3 V PCI-X		Per PCI-X Specification									
3.3 V GTL	20 mA <sup>5</sup>	20 mA <sup>5</sup>	High	-0.3	VREF - 0.05	VREF + 0.05	3.6	0.4	_	20	20
2.5 V GTL	20 mA <sup>5</sup>	20 mA <sup>5</sup>	High	-0.3	VREF - 0.05	VREF + 0.05	3.6	0.4	-	20	20
3.3 V GTL+	35 mA	35 mA	High	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.6	-	35	35
2.5 V GTL+	33 mA	33 mA	High	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.6	_	33	33
HSTL (I)	8 mA	8 mA	High	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.4	VCCI - 0.4	8	8

#### Notes:

- 1. Currents are measured at 85°C junction temperature.
- 2. The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 3. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-12 specification.
- 4. All LVCMOS 1.2 V software macros support LVCMOS 1.2 V wide range as specified in the JESD8-12 specification.
- 5. Output drive strength is below JEDEC specification.
- 6. Output Slew Rates can be extracted from IBIS Models, http://www.microsemi.com/soc/download/ibis/default.aspx.



Table 2-21 • Summary of Maximum and Minimum DC Input and Output Levels (continued)
Applicable to Commercial and Industrial Conditions

		Equivalent		VIL		VIH		VOL	VOH	IOL <sup>1</sup>	IOH <sup>1</sup>
I/O Standard	Drive Strength	Software Default Drive Strength <sup>2</sup>	Slew Rate		Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA
HSTL (II)	15 mA <sup>5</sup>	15 mA <sup>5</sup>	High	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.4	VCCI - 0.4	15	15
SSTL2 (I)	15 mA	15 mA	High	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.54	VCCI - 0.62	15	15
SSTL2 (II)	18 mA	18 mA	High	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.35	VCCI - 0.43	18	18
SSTL3 (I)	14 mA	14 mA	High	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.7	VCCI - 1.1	14	14
SSTL3 (II)	21 mA	21 mA	High	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.5	VCCI - 0.9	21	21

#### Notes:

- 1. Currents are measured at 85°C junction temperature.
- 2. The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 3. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-12 specification.
- 4. All LVCMOS 1.2 V software macros support LVCMOS 1.2 V wide range as specified in the JESD8-12 specification.
- 5. Output drive strength is below JEDEC specification.
- 6. Output Slew Rates can be extracted from IBIS Models, http://www.microsemi.com/soc/download/ibis/default.aspx.



Table 2-22 • Summary of Maximum and Minimum DC Input Levels **Applicable to Commercial and Industrial Conditions** 

	Com	mercial <sup>1</sup>	Indu	ıstrial <sup>2</sup>
	IIL <sup>3</sup>	IIH <sup>4</sup>	IIL <sup>3</sup>	IIH <sup>4</sup>
DC I/O Standards	μΑ	μА	μA	μA
3.3 V LVTTL / 3.3 V LVCMOS	10	10	15	15
3.3 V LVCMOS Wide Range	10	10	15	15
2.5 V LVCMOS	10	10	15	15
1.8 V LVCMOS	10	10	15	15
1.5 V LVCMOS	10	10	15	15
1.2 V LVCMOS <sup>5</sup>	10	10	15	15
1.2 V LVCOMS Wide Range <sup>5</sup>	10	10	15	15
3.3 V PCI	10	10	15	15
3.3 V PCI-X	10	10	15	15
3.3 V GTL	10	10	15	15
2.5 V GTL	10	10	15	15
3.3 V GTL+	10	10	15	15
2.5 V GTL+	10	10	15	15
HSTL (I)	10	10	15	15
HSTL (II)	10	10	15	15
SSTL2 (I)	10	10	15	15
SSTL2 (II)	10	10	15	15
SSTL3 (I)	10	10	15	15
SSTL3 (II)	10	10	15	15

#### Notes:

- Commercial range (0°C < T<sub>A</sub> < 70°C)</li>
   Industrial range (-40°C < T<sub>A</sub> < 85°C)</li>
- 3. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 4. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 5. Applicable to V2 devices operating at VCCI ≥ VCC.



# Summary of I/O Timing Characteristics – Default I/O Software Settings

Table 2-23 • Summary of AC Measuring Points

Standard	Input Reference Voltage (VREF_TYP)	Board Termination Voltage (VTT_REF)	Measuring Trip Point (Vtrip)
3.3 V LVTTL / 3.3 V LVCMOS	-	_	1.4 V
3.3 V LVCMOS Wide Range	-	_	1.4 V
2.5 V LVCMOS	-	_	1.2 V
1.8 V LVCMOS	-	_	0.90 V
1.5 V LVCMOS	-	_	0.75 V
1.2 V LVCMOS*	-	_	0.6 V
1.2 V LVCMOS – Wide Range*	-	_	0.6 V
3.3 V PCI	-	_	0.285 * VCCI (RR)
	-	_	0.615 * VCCI (FF))
3.3 V PCI-X	-	_	0.285 * VCCI (RR)
	-	_	0.615 * VCCI (FF)
3.3 V GTL	0.8 V	1.2 V	VREF
2.5 V GTL	0.8 V	1.2 V	VREF
3.3 V GTL+	1.0 V	1.5 V	VREF
2.5 V GTL+	1.0 V	1.5 V	VREF
HSTL (I)	0.75 V	0.75 V	VREF
HSTL (II)	0.75 V	0.75 V	VREF
SSTL2 (I)	1.25 V	1.25 V	VREF
SSTL2 (II)	1.25 V	1.25 V	VREF
SSTL3 (I)	1.5 V	1.485 V	VREF
SSTL3 (II)	1.5 V	1.485 V	VREF
LVDS	-	-	Cross point
LVPECL	-	_	Cross point

Note: \*Applicable to V2 devices ONLY operating in the 1.2 V core range.



# Table 2-24 • I/O AC Parameter Definitions

Parameter	Definition
t <sub>DP</sub>	Data to Pad delay through the Output Buffer
t <sub>PY</sub>	Pad to Data delay through the Input Buffer with Schmitt trigger disabled
t <sub>DOUT</sub>	Data to Output Buffer delay through the I/O interface
t <sub>EOUT</sub>	Enable to Output Buffer Tristate Control delay through the I/O interface
t <sub>DIN</sub>	Input Buffer to Data delay through the I/O interface
t <sub>PYS</sub>	Pad to Data delay through the Input Buffer with Schmitt trigger enabled
t <sub>HZ</sub>	Enable to Pad delay through the Output Buffer—HIGH to Z
$t_{ZH}$	Enable to Pad delay through the Output Buffer—Z to HIGH
$t_{LZ}$	Enable to Pad delay through the Output Buffer—LOW to Z
$t_{ZL}$	Enable to Pad delay through the Output Buffer—Z to LOW
t <sub>ZHS</sub>	Enable to Pad delay through the Output Buffer with delayed enable—Z to HIGH
t <sub>ZLS</sub>	Enable to Pad delay through the Output Buffer with delayed enable—Z to LOW



Table 2-25 • Summary of I/O Timing Characteristics—Software Default Settings
Std. Speed Grade, Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI (per standard)

I/O Standard	Drive Strength (mA)	Equivalent Software Default Drive Strength Option (mA)	Slew Rate	Capacitive Load (pF)	External Resistor $(\Omega)$	t <sub>DOUT</sub> (ns)	t <sub>DP</sub> (ns)	t <sub>DIN</sub> (ns)	t <sub>pY</sub> (ns)	t <sub>PYS</sub> (ns)	t <sub>EOUT</sub> (ns)	t <sub>ZL</sub> (ns)	(su) <sup>HZ</sup>	t <sub>LZ</sub> (ns)	t <sub>HZ</sub> (ns)	t <sub>ZLS</sub> (ns)	t <sub>ZHS</sub> (ns)	Units
3.3 V LVTTL / 3.3 V LVCMOS	12	12	High	5	-	0.97	2.12	0.18		1.34	0.66		1.69	2.71	3.08	5.76		ns
3.3 V LVCMOS Wide Range <sup>1, 2</sup>	100 μΑ	12	High	5	ı	0.97	2.96	0.18	1.42	1.84	0.66	2.98	2.28	3.86	4.36	6.58	5.87	ns
2.5 V LVCMOS	12	12	High	5	-	.097	2.15	0.18	1.31	1.41	0.66	2.20	1.85	2.78	2.98	5.80	5.45	ns
1.8 V LVCMOS	12	12	High	5	_	0.97	2.37	0.18	1.27	1.59	0.66	2.42	2.03	3.07	3.57	6.02	5.62	ns
1.5 V LVCMOS	12	12	High	5	_	0.97	2.69	0.18	1.47	1.77	0.66	2.75	2.30	3.24	3.67	6.35	5.89	ns
3.3 V PCI	Per PCI spec	-	High	10	25 <sup>3</sup>	0.97	2.38	0.18	0.96	1.42	0.66	2.43	1.80	2.72	3.08	6.03	5.39	ns
3.3 V PCI-X	Per PCI-X spec	_	High	10	25 <sup>3</sup>	0.97	2.38	0.19	0.92	1.34	0.66	2.43	1.80	2.72	3.08	6.03	5.39	ns
3.3 V GTL	20 <sup>4</sup>	-	High	10	25	0.97	1.78	0.19	2.35	_	0.66	1.80	1.78	_	_	5.39	5.38	ns
2.5 V GTL	20 <sup>4</sup>	_	High	10	25	0.97	1.85	0.19	1.98	_	0.66	1.89	1.82	-	_	5.49	5.42	ns
3.3 V GTL+	35	_	High	10	25	0.97	1.80	0.19	1.32	-	0.66	1.84	1.77	_	-	5.44	5.36	ns
2.5 V GTL+	33	-	High	10	25	0.97	1.92	0.19	1.26	-	0.66	1.96	1.80	-	_	5.56	5.40	ns
HSTL (I)	8	ı	High	20	50	0.97	2.67	0.18	1.72	_	0.66	2.72	2.67	-	-	6.32	6.26	ns
HSTL (II)	15	ı	High	20	25	0.97	2.55	0.18	1.72	_	0.66	2.60	2.34	-	-	6.20	5.93	ns
SSTL2 (I)	15	_	High	30	50	0.97	1.86	0.19	1.12	-	0.66	1.90	1.68	-	_	5.50		ns
SSTL2 (II)	18	_	High	30	25	0.97	1.89	0.19		-	0.66		1.62	-	-	5.53		ns
SSTL3 (I)	14	_	High	30	50		2.00	0.19	1.06	_	0.66	2.04	1.67	_	_	5.64		ns
SSTL3 (II)	21	_	High	30	25	0.97		0.19		_	0.66	1.85	1.55	-	-	5.45	5.14	ns
LVDS	24	_	High	_	-	0.97		0.19		_	-	-	_	-	-	-	-	ns
LVPECL	24	_	High	_	_	0.97	1.65	0.18	1.42	_	_	_	_	_	_	_	_	ns

- The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.
- 3. Resistance is used to measure I/O propagation delays as defined in PCI Specifications. See Figure 2-12 on page 2-49 for connectivity. This resistor is not required during normal operation.
- 4. Output drive strength is below JEDEC specification.
- 5. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



Table 2-26 • Summary of I/O Timing Characteristics—Software Default Settings
Std. Speed Grade, Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V,
Worst-Case VCCI (per standard)

														_	ı		_	
I/O Standard	Drive Strength (mA)	Equivalent Software Default Drive Strength Option <sup>1</sup> (mA)	Slew Rate	Capacitive Load (pF)	External Resistor $(\Omega)$	t <sub>DOUT</sub> (ns)	t <sub>DP</sub> (ns)	t <sub>DIN</sub> (ns)	t <sub>PY</sub> (ns)	t <sub>PYS</sub> (ns)	t <sub>EOUT</sub> (ns)	t <sub>ZL</sub> (ns)	t <sub>ZH</sub> (ns)	t <sub>LZ</sub> (ns)	t <sub>HZ</sub> (ns)	t <sub>ZLS</sub> (ns)	t <sub>ZHS</sub> (ns)	Units
3.3 V LVTTL / 3.3 V LVCMOS	12	12	High	5	-	1.55	2.47	0.26	1.31	1.58	1.10	2.51	2.04	3.28	3.97	8.29	7.82	ns
3.3 V LVCMOS Wide Range <sup>1,2</sup>	100 µA	12	High	35	-	1.55	3.40	0.26	1.66	2.14	1.10	3.40	2.68	4.55	5.49	9.19	8.46	ns
2.5 V LVCMOS	12	12	High	5	_	1.55	2.51	0.26	1.55	1.77	1.10	2.54	2.22	3.36	3.85	8.33	8.00	ns
1.8 V LVCMOS	12	12	High	5	-	1.55	2.75	0.26	1.53	1.96	1.10	2.78	2.40	3.68	4.56	8.57	8.19	ns
1.5 V LVCMOS	12	12	High	5	_	1.55	3.10	0.26	1.72	2.16	1.10	3.15	2.70	3.86	4.68	8.93	8.49	ns
1.2 V LVCMOS	2	2	High	5	_	1.55	4.06	0.26	2.09	2.95	1.10	3.92	3.46	4.01	3.79	9.71	9.24	ns
1.2 V LVCMOS Wide Range <sup>1,3</sup>	100 µA	2	High	5	-	1.55	4.06	0.26	2.09	2.95	1.10	3.92	3.46	4.01	3.79	9.71	9.24	ns
3.3 V PCI	Per PCI spec	_	High	10	25 <sup>4</sup>	1.55	2.76	0.26	1.19	1.63	1.10	2.79	2.16	3.29	3.97	8.58	7.94	ns
3.3 V PCI-X	Per PCI-X spec	_	High	10	25 <sup>4</sup>	1.55	2.76	0.25	1.22	1.58	1.10	2.79	2.16	3.29	3.97	8.58	7.94	ns
3.3 V GTL	20 <sup>5</sup>	_	High	10	25	1.55	2.08	0.25	2.76	_	1.10	2.09	2.08	-	_	7.88	7.87	ns
2.5 V GTL	20 <sup>5</sup>	_	High	10	25	1.55	2.17	0.25	2.35	_	1.10	2.20	2.13	_	_	7.99	7.91	ns
3.3 V GTL+	35	_	High	10	25	1.55	2.12	0.25	1.62	_	1.10	2.14	2.07	_	_	7.93	7.85	ns
2.5 V GTL+	33	_	High	10	25	1.55	2.25	0.25	1.55	_	1.10	2.27	2.10	-	_	8.06	7.89	ns
HSTL (I)	8	_	High	20	50		3.09		1.95	-	1.10		3.09	-	_	8.90	8.88	ns
HSTL (II)	15	_	High	20	25		2.94			_		2.98		_	_	8.77		ns
SSTL2 (I)	15	_	High	30	50		2.18			_	1.10		2.03	_	_	7.99		ns
SSTL2 (II)	18	-	High	30	25	1.55		0.25	1.40	-		2.24		_	_	8.03		ns
SSTL3 (I)	14	-	High	30	50		2.33		1.33	-		2.36		_	_	8.15		ns
SSTL3 (II)	21	_	High	30	25	1.55	2.13	0.25	1.33	_	1.10	2.16	1.89	_	_	7.94	7.67	ns

- The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.
- 3. All LVCMOS 1.2 V software macros support LVCMOS 1.2 V wide range as specified in the JESD8-12 specification.
- 4. Resistance is used to measure I/O propagation delays as defined in PCI specifications. See Figure 2-12 on page 2-49 for connectivity. This resistor is not required during normal operation.
- 5. Output drive strength is below JEDEC specification.
- 6. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



Table 2-26 • Summary of I/O Timing Characteristics—Software Default Settings (continued)
Std. Speed Grade, Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V,
Worst-Case VCCI (per standard)

I/O Standard	Drive Strength (mA)	Equivalent Software Default Drive Strength Option <sup>1</sup> (mA)		Capacitive Load (pF)	External Resistor (Ω)	t <sub>DOUT</sub> (ns)	t <sub>DP</sub> (ns)	t <sub>DIN</sub> (ns)	t <sub>PY</sub> (ns)	t <sub>PYS</sub> (ns)	t <sub>EOUT</sub> (ns)	t <sub>ZL</sub> (ns)	t <sub>ZH</sub> (ns)	t <sub>LZ</sub> (ns)	t <sub>HZ</sub> (ns)	t <sub>ZLS</sub> (ns)	t <sub>ZHS</sub> (ns)	Units
LVDS	24	_	High	_	_	1.55	2.26	0.25	1.95	_	_	_	_	-	_	_	_	ns
LVPECL	24	_	High	_	_	1.55	2.17	0.25	1.70	1	-	-	_	_	_	_	_	ns

- The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.
- 3. All LVCMOS 1.2 V software macros support LVCMOS 1.2 V wide range as specified in the JESD8-12 specification.
- 4. Resistance is used to measure I/O propagation delays as defined in PCI specifications. See Figure 2-12 on page 2-49 for connectivity. This resistor is not required during normal operation.
- 5. Output drive strength is below JEDEC specification.
- 6. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



# **Detailed I/O DC Characteristics**

Table 2-27 • Input Capacitance

Symbol	Definition	Conditions	Min.	Max.	Units
C <sub>IN</sub>	Input capacitance	VIN = 0, f = 1.0 MHz		8	pF
C <sub>INCLK</sub>	Input capacitance on the clock pin	VIN = 0, f = 1.0 MHz		8	pF

Table 2-28 • I/O Output Buffer Maximum Resistances<sup>1</sup>

Standard	Drive Strength	$R_{PULL-DOWN} (\Omega)^2$	R <sub>PULL-UP</sub> (Ω) <sup>3</sup>	
3.3 V LVTTL / 3.3 V LVCMOS	4 mA	100	300	
	8 mA	50	150	
	12 mA	25	75	
	16 mA	17	50	
	24 mA	11	33	
3.3 V LVCMOS Wide Range	100 μΑ	Same as regular 3.3 V LVCMOS	Same as regular 3.3 V LVCMOS	
2.5 V LVCMOS	4 mA	100	200	
	8 mA	50	100	
	12 mA	25	50	
	16 mA	20	40	
	24 mA	11	22	
1.8 V LVCMOS	2 mA	200	225	
	4 mA	100	112	
	6 mA	50	56	
	8 mA	50	56	
	12 mA	20	22	
	16 mA	20	22	
1.5 V LVCMOS	2 mA	200	224	
	4 mA	100	112	
	6 mA	67	75	
	8 mA	33	37	
	12 mA	33	37	
1.2 V LVCMOS <sup>4</sup>	2 mA	158	164	
1.2 V LVCMOS Wide Range <sup>4</sup>	100 μΑ	Same as regular 1.2 V LVCMOS	Same as regular 1.2 V LVCMOS	

#### Notes:

- 1. These maximum values are provided for informational reasons only. Minimum output buffer resistance values depend on VCCI, drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website at <a href="http://www.microsemi.com/soc/techdocs/models/ibis.html">http://www.microsemi.com/soc/techdocs/models/ibis.html</a>.
- 2.  $R_{(PULL\text{-}DOWN\text{-}MAX)} = (VOLspec) / IOLspec$
- 3.  $R_{(PULL-UP-MAX)} = (VCCImax VOHspec) / IOHspec$
- 4. Applicable to IGLOOe V2 devices operating in the 1.2 V core range ONLY.
- 5. Output drive strength is below JEDEC specification.



Table 2-28 • I/O Output Buffer Maximum Resistances<sup>1</sup> (continued)

Standard	Drive Strength	R <sub>PULL-DOWN</sub> (Ω) <sup>2</sup>	R <sub>PULL-UP</sub> (Ω) <sup>3</sup>
3.3 V PCI/PCI-X	Per PCI/PCI-X specification	25	75
3.3 V GTL	20 mA <sup>5</sup>	11	-
2.5 V GTL	20 mA <sup>5</sup>	14	-
3.3 V GTL+	35 mA	12	-
2.5 V GTL+	33 mA	15	-
HSTL (I)	8 mA	50	50
HSTL (II)	15 mA	25	25
SSTL2 (I)	15 mA	27	31
SSTL2 (II)	18 mA	13	15
SSTL3 (I)	14 mA	44	69
SSTL3 (II)	21 mA	18	32

- 1. These maximum values are provided for informational reasons only. Minimum output buffer resistance values depend on VCCI, drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website at <a href="http://www.microsemi.com/soc/techdocs/models/ibis.html">http://www.microsemi.com/soc/techdocs/models/ibis.html</a>.
- 2.  $R_{(PULL-DOWN-MAX)} = (VOLspec) / IOLspec$
- 3.  $R_{(PULL-UP-MAX)} = (VCCImax VOHspec) / IOHspec$
- 4. Applicable to IGLOOe V2 devices operating in the 1.2 V core range ONLY.
- 5. Output drive strength is below JEDEC specification.

Table 2-29 • I/O Weak Pull-Up/Pull-Down Resistances
Minimum and Maximum Weak Pull-Up/Pull-Down Resistance Values

	R( <sub>(WEAK</sub>	PULL-UP) <sup>1</sup> Ω)	$R_{(WEAK\;PULL\text{-DOWN})}^2 \ (\Omega)$			
VCCI	Minimum	Maximum	Minimum	Maximum		
3.3 V	10 k	45 k	10 k	45 k		
3.3 V (wide range I/Os)	10 k	45 k	10 k	45 k		
2.5 V	11 k	55 k	12 k	74 k		
1.8 V	18 k	70 k	17 k	110 k		
1.5 V	19 k	90 k	19 k	140 k		
1.2 V	25 k	110 k	25 k	150 k		
1.2 V (wide range I/Os)	19 k	110 k	19 k	150 k		

#### Notes:

- 1.  $R_{(WEAK\ PULL\ -UP\ -MAX)} = (VCCImax VOHspec) / I_{(WEAK\ PULL\ -UP\ -MIN)}$
- 2.  $R_{(WEAK\ PULL-DOWN-MAX)} = (VOLspec) / I_{(WEAK\ PULL-DOWN-MIN)}$



Table 2-30 • I/O Short Currents IOSH/IOSL

	Drive Strength	IOSH (mA)*	IOSL (mA)*
3.3 V LVTTL / 3.3 V LVCMOS	4 mA	25	27
	8 mA	51	54
	12 mA	103	109
	16 mA	132	127
	24 mA	268	181
3.3 V LVCMOS Wide Range	100 μΑ	Same as regular 3.3 V LVCMOS	Same as regular 3.3 V LVCMOS
2.5 V LVCMOS	4 mA	16	18
	8 mA	32	37
	12 mA	65	74
	16 mA	83	87
	24 mA	169	124
1.8 V LVCMOS	2 mA	9	11
	4 mA	17	22
	6 mA	35	44
	8 mA	45	51
	12 mA	91	74
	16 mA	91	74
1.5 V LVCMOS	2 mA	13	16
	4 mA	25	33
	6 mA	32	39
	8 mA	66	55
	12 mA	66	55
1.2 V LVCMOS	2 mA	20	26
1.2 V LVCMOS Wide Range	100 μA	20	26
3.3 V PCI/PCIX	Per PCI/PCI-X Specification	Per PC	I Curves
3.3 V GTL	25 mA	268	181
2.5 V GTL	25 mA	169	124
3.3 V GTL+	35 mA	268	181
2.5 V GTL+	33 mA	169	124
HSTL (I)	8 mA	32	39
HSTL (II)	15 mA	66	55
SSTL2 (I)	15 mA	83	87
SSTL2 (II)	18 mA	169	124
SSTL3 (I)	14 mA	51	54
SSTL3 (II)	21 mA	103	109

Note:  $T_J = 100$ °C



The length of time an I/O can withstand IOSH/IOSL events depends on the junction temperature. The reliability data below is based on a 3.3 V, 36 mA I/O setting, which is the worst case for this type of analysis.

For example, at 100°C, the short current condition would have to be sustained for more than six months to cause a reliability concern. The I/O design does not contain any short circuit protection, but such protection would only be needed in extremely prolonged stress conditions.

Table 2-31 • Duration of Short Circuit Event before Failure

Temperature	Time before Failure
-40°C	> 20 years
0°C	> 20 years
25°C	> 20 years
70°C	5 years
85°C	2 years
100°C	6 months

Table 2-32 • Schmitt Trigger Input Hysteresis
Hysteresis Voltage Value (Typ.) for Schmitt Mode Input Buffers

Input Buffer Configuration	Hysteresis Value (typ.)
3.3 V LVTTL/LVCMOS/PCI/PCI-X (Schmitt trigger mode)	240 mV
2.5 V LVCMOS (Schmitt trigger mode)	140 mV
1.8 V LVCMOS (Schmitt trigger mode)	80 mV
1.5 V LVCMOS (Schmitt trigger mode)	60 mV
1.2 V LVCMOS (Schmitt trigger mode)	40 mV

Table 2-33 • I/O Input Rise Time, Fall Time, and Related I/O Reliability\*

Input Buffer	Input Rise/Fall Time (min.)	Input Rise/Fall Time (max.)	Reliability
LVTTL/LVCMOS (Schmitt trigger disabled)	No requirement	10 ns*	20 years (100°C)
LVTTL/LVCMOS (Schmitt trigger enabled)	No requirement	No requirement, but input noise voltage cannot exceed Schmitt hysteresis.	20 years (100°C)
HSTL/SSTL/GTL	No requirement	10 ns*	10 years (100°C)
LVDS/B-LVDS/M-LVDS/LVPECL	No requirement	10 ns*	10 years (100°C)

Note: \*The maximum input rise/fall time is related to the noise induced into the input buffer trace. If the noise is low, then the rise time and fall time of input buffers can be increased beyond the maximum value. The longer the rise/fall times, the more susceptible the input signal is to the board noise. Microsemi recommends signal integrity evaluation/characterization of the system to ensure that there is no excessive noise coupling into input signals.



# Single-Ended I/O Characteristics

# 3.3 V LVTTL / 3.3 V LVCMOS

Low-Voltage Transistor-Transistor Logic is a general purpose standard (EIA/JESD) for 3.3 V applications. It uses an LVTTL input buffer and push-pull output buffer. The 3.3 V LVCMOS standard is supported as part of the 3.3 V LVTTL support.

Table 2-34 • Minimum and Maximum DC Input and Output Levels

3.3 V LVTTL / 3.3 V LVCMOS	VIL		V	ΙΗ	VOL	VOH	IOL	ЮН	IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
4 mA	-0.3	8.0	2	3.6	0.4	2.4	4	4	25	27	10	10
8 mA	-0.3	8.0	2	3.6	0.4	2.4	8	8	51	54	10	10
12 mA	-0.3	8.0	2	3.6	0.4	2.4	12	12	103	109	10	10
16 mA	-0.3	0.8	2	3.6	0.4	2.4	16	16	132	127	10	10
24 mA	-0.3	8.0	2	3.6	0.4	2.4	24	24	268	181	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

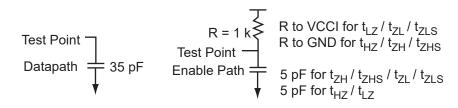


Figure 2-7 • AC Loading

Table 2-35 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	3.3	1.4	_	5

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.



## 1.5 V DC Core Voltage

Table 2-36 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Unit s
4 mA	Std.	0.97	4.90	0.18	1.08	1.34	0.66	5.00	3.99	2.27	2.16	8.60	7.59	ns
8 mA	Std.	0.97	4.05	0.18	1.08	1.34	0.66	4.13	3.45	2.53	2.65	7.73	7.05	ns
12 mA	Std.	0.97	3.44	0.18	1.08	1.34	0.66	3.51	3.05	2.71	2.95	7.11	6.64	ns
16 mA	Std.	0.97	3.27	0.18	1.08	1.34	0.66	3.34	2.96	2.74	3.04	6.93	6.55	ns
24 mA	Std.	0.97	3.18	0.18	1.08	1.34	0.66	3.24	2.97	2.79	3.36	6.84	6.56	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-37 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
4 mA	Std.	0.97	2.85	0.18	1.08	1.34	0.66	2.92	2.27	2.27	2.27	6.51	5.87	ns
8 mA	Std.	0.97	2.39	0.18	1.08	1.34	0.66	2.44	1.88	2.53	2.76	6.03	5.47	ns
12 mA	Std.	0.97	2.12	0.18	1.08	1.34	0.66	2.17	1.69	2.71	3.08	5.76	5.28	ns
16 mA	Std.	0.97	2.08	0.18	1.08	1.34	0.66	2.12	1.65	2.75	3.17	5.72	5.25	ns
24 mA	Std.	0.97	2.10	0.18	1.08	1.34	0.66	2.14	1.60	2.80	3.49	5.74	5.20	ns

#### Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## 1.2 V DC Core Voltage

Table 2-38 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew – Applies to 1.2 V DC Core Voltage Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 3.0 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
4 mA	Std.	1.55	5.54	0.26	1.31	1.58	1.10	5.63	4.53	2.79	2.87	11.42	10.32	ns
8 mA	Std.	1.55	4.60	0.26	1.31	1.58	1.10	4.67	3.94	3.09	3.45	10.45	9.73	ns
12 mA	Std.	1.55	3.93	0.26	1.31	1.58	1.10	3.99	3.51	3.28	3.82	9.77	9.29	ns
16 mA	Std.	1.55	3.74	0.26	1.31	1.58	1.10	3.79	3.41	3.32	3.92	9.58	9.20	ns
24 mA	Std.	1.55	3.64	0.26	1.31	1.58	1.10	3.69	3.42	3.38	4.30	9.48	9.21	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.

Table 2-39 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: TJ = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 3.0 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
4 mA	Std.	1.55	3.26	0.26	1.31	1.58	1.10	3.33	2.67	2.79	3.01	9.12	8.46	ns
8 mA	Std.	1.55	2.77	0.26	1.31	1.58	1.10	2.80	2.24	3.09	3.59	8.59	8.03	ns
12 mA	Std.	1.55	2.47	0.26	1.31	1.58	1.10	2.51	2.04	3.28	3.97	8.29	7.82	ns
16 mA	Std.	1.55	2.42	0.26	1.31	1.58	1.10	2.46	2.00	3.33	4.08	8.24	7.79	ns
24 mA	Std.	1.55	2.45	0.26	1.31	1.58	1.10	2.48	1.95	3.38	4.46	8.26	7.73	ns

#### Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



# 3.3 V LVCMOS Wide Range

Table 2-40 • Minimum and Maximum DC Input and Output Levels

3.3 V LVC	MOS Wide Range	VI	L	'	/IH	VOL	VOH	IOL	ЮН	IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Equivalent Software Default Drive Strength Option <sup>3</sup>	Min. (V)	Max. (V)	Min. (V)	Max (V)	Max. (V)	Min. (V)	μΑ	μΑ	Max. (mA) <sup>4</sup>	Max. (mA) <sup>4</sup>	μ <b>Α</b> <sup>5</sup>	μ <b>Α</b> <sup>5</sup>
100 μΑ	2 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	25	27	10	10
100 μΑ	4 mA	-0.3	8.0	2	3.6	0.2	VDD - 0.2	100	100	25	27	10	10
100 μΑ	6 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	51	54	10	10
100 μΑ	8 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	51	54	10	10
100 μΑ	12 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	103	109	10	10
100 μΑ	16 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	132	127	10	10
100 μΑ	24 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	268	181	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 4. Currents are measured at 85°C junction temperature.
- 5. All LVCMOS 3.3 V software macros supports LVCMOS 3.3 V wide range as specified in the JDEC8a specification.
- 6. Software default selection highlighted in gray.

Table 2-41 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	3.3	1.4	_	5

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.



## 1.5 V DC Core Voltage

Table 2-42 • 3.3 V LVCMOS Wide Range Low Slew – Applies to 1.5 V DC Core Voltage Commercial-Case Conditions: T<sub>.I</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option <sup>1</sup>	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>zH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zhs</sub>	Units
100 μΑ	4 mA	Std.	0.97	7.26	0.18	1.42	1.84	0.66	7.28	5.78	3.18	2.93	10.88	9.38	ns
100 μΑ	8 mA	Std.	0.97	5.94	0.18	1.42	1.84	0.66	5.96	4.96	3.59	3.69	9.56	8.56	ns
100 μΑ	12 mA	Std.	0.97	5.00	0.18	1.42	1.84	0.66	5.02	4.34	3.86	4.16	8.62	7.94	ns
100 μΑ	16 mA	Std.	0.97	4.73	0.18	1.42	1.84	0.66	4.75	4.21	3.92	4.29	8.35	7.81	ns
100 μΑ	24 mA	Std.	0.97	4.59	0.18	1.42	1.84	0.66	4.61	4.23	3.99	4.78	8.21	7.82	ns

#### Notes:

Table 2-43 • 3.3 V LVCMOS Wide Range High Slew – Applies to 1.5 V DC Core Voltage
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option <sup>1</sup>	Speed Grade		t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>zh</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>zLS</sub>	t <sub>zhs</sub>	Units
100 μΑ	4 mA	Std.	0.97	4.10	0.18	1.42	1.84	0.66	4.12	3.17	3.18	3.11	7.71	6.77	ns
100 μΑ	8 mA	Std.	0.97	3.37	0.18	1.42	1.84	0.66	3.39	2.57	3.59	3.87	6.99	6.16	ns
100 μΑ	12 mA	Std.	0.97	2.96	0.18	1.42	1.84	0.66	2.98	2.28	3.86	4.36	6.58	5.87	ns
100 μΑ	16 mA	Std.	0.97	2.90	0.18	1.42	1.84	0.66	2.92	2.22	3.93	4.49	6.51	5.82	ns
100 μΑ	24 mA	Std.	0.97	2.92	0.18	1.42	1.84	0.66	2.94	2.15	4.00	4.99	6.54	5.75	ns

#### Notes:

- 1. The minimum drive strength for any or LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.
- 3. Software default selection highlighted in gray.

The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.

<sup>2.</sup> For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## 1.2 V DC Core Voltage

Table 2-44 • 3.3 V LVCMOS Wide Range Low Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option <sup>1</sup>	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>zh</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zHS</sub>	Units
100 μΑ	4 mA	Std.	1.55	8.14	0.26	1.66	2.14	1.10	8.14	6.46	3.80	3.79	13.93	12.25	ns
100 μΑ	8 mA	Std.	1.55	6.68	0.26	1.66	2.14	1.10	6.68	5.57	4.25	4.69	12.47	11.36	ns
100 μΑ	12 mA	Std.	1.55	5.65	0.26	1.66	2.14	1.10	5.65	4.91	4.55	5.25	11.44	10.69	ns
100 μΑ	16 mA	Std.	1.55	5.36	0.26	1.66	2.14	1.10	5.36	4.76	4.61	5.41	11.14	10.55	ns
100 μΑ	24 mA	Std.	1.55	5.20	0.26	1.66	2.14	1.10	5.20	4.78	4.69	6.00	10.99	10.56	ns

#### Notes:

Table 2-45 • 3.3 V LVCMOS Wide Range High Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: TJ = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option <sup>1</sup>	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>zh</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zHS</sub>	Units
100 μΑ	4 mA	Std.	1.55	4.65	0.26	1.66	2.14	110	4.65	3.64	3.80	4.00	10.44	9.43	ns
100 μΑ	8 mA	Std.	1.55	3.85	0.26	1.66	2.14	1.10	3.85	2.99	4.25	4.91	9.64	8.77	ns
100 μΑ	12 mA	Std.	1.55	3.40	0.26	1.66	2.14	1.10	3.40	2.68	4.55	5.49	9.19	8.46	ns
100 μΑ	16 mA	Std.	1.55	3.33	0.26	1.66	2.14	1.10	3.33	2.62	4.62	5.65	9.11	8.41	ns
100 μΑ	24 mA	Std.	1.55	3.36	0.26	1.66	2.14	1.10	3.36	2.54	4.71	6.24	9.15	8.32	ns

# Notes:

- 2. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.
- 3. Software default selection highlighted in gray.

<sup>1.</sup> The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.

<sup>2.</sup> For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.

<sup>1.</sup> The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.



## 2.5 V LVCMOS

Low-Voltage CMOS for 2.5 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 2.5 V applications.

Table 2-46 • Minimum and Maximum DC Input and Output Levels

2.5 V LVCMOS	٧	ΊL	٧	IH	VOL	VOH	IOL	ЮН	IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
4 mA	-0.3	0.7	1.7	3.6	0.7	1.7	4	4	16	18	10	10
8 mA	-0.3	0.7	1.7	3.6	0.7	1.7	8	8	32	37	10	10
12 mA	-0.3	0.7	1.7	3.6	0.7	1.7	12	12	65	74	10	10
16 mA	-0.3	0.7	1.7	3.6	0.7	1.7	16	16	83	87	10	10
24 mA	-0.3	0.7	1.7	3.6	0.7	1.7	24	24	169	124	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

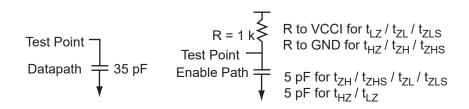


Figure 2-8 • AC Loading

Table 2-47 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	2.5	1.2	-	5

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.



# 1.5 V DC Core Voltage

Table 2-48 • 2.5 V LVCMOS Low Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Unit s
4 mA	Std.	0.97	5.55	0.18	1.31	1.41	0.66	5.66	4.75	2.28	1.96	9.26	8.34	ns
8 mA	Std.	0.97	4.58	0.18	1.31	1.41	0.66	4.67	4.07	2.58	2.53	8.27	7.66	ns
12 mA	Std.	0.97	3.89	0.18	1.31	1.41	0.66	3.97	3.58	2.78	2.91	7.56	7.17	ns
16 mA	Std.	0.97	3.68	0.18	1.31	1.41	0.66	3.75	3.47	2.82	3.01	7.35	7.06	ns
24 mA	Std.	0.97	3.59	0.18	1.31	1.41	0.66	3.66	3.48	2.88	3.37	7.26	7.08	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-49 • 2.5 V LVCMOS High Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V

	Speed													Unit
Drive Strength	Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	s
4 mA	Std.	0.97	2.94	0.18	1.31	1.41	0.66	3.00	2.68	2.28	2.03	6.60	6.27	ns
8 mA	Std.	0.97	2.45	0.18	1.31	1.41	0.66	2.50	2.12	2.58	2.62	6.10	5.72	ns
12 mA	Std.	0.97	2.15	0.18	1.31	1.41	0.66	2.20	1.85	2.78	2.98	5.80	5.45	ns
16 mA	Std.	0.97	2.10	0.18	1.31	1.41	0.66	2.15	1.80	2.82	3.08	5.75	5.40	ns
24 mA	Std.	0.97	2.11	0.18	1.31	1.41	0.66	2.16	1.74	2.88	3.47	5.75	5.33	ns

#### Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## 1.2 V DC Core Voltage

Table 2-50 • 2.5 V LVCMOS Low Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
4 mA	Std.	1.55	6.25	0.26	1.55	1.77	1.10	6.36	5.34	2.81	2.63	12.14	11.13	ns
8 mA	Std.	1.55	5.18	0.26	1.55	1.77	1.10	5.26	4.61	3.13	3.32	11.05	10.39	ns
12 mA	Std.	1.55	4.42	0.26	1.55	1.77	1.10	4.49	4.08	3.36	3.76	10.28	9.86	ns
16 mA	Std.	1.55	4.19	0.26	1.55	1.77	1.10	4.25	3.96	3.40	3.89	10.04	9.75	ns
24 mA	Std.	1.55	4.09	0.26	1.55	1.76	1.10	4.15	3.97	3.47	4.32	9.94	9.76	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.

Table 2-51 • 2.5 V LVCMOS High Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.3 V

	Speed													
Drive Strength	Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	$t_{ZL}$	t <sub>ZH</sub>	$t_{LZ}$	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
4 mA	Std.	1.55	3.38	0.26	1.55	1.77	1.10	3.42	3.11	2.81	2.72	9.21	8.89	ns
8 mA	Std.	1.55	2.83	0.26	1.55	1.77	1.10	2.87	2.51	3.13	3.42	8.66	8.30	ns
12 mA	Std.	1.55	2.51	0.26	1.55	1.77	1.10	2.54	2.22	3.36	3.85	8.33	8.00	ns
16 mA	Std.	1.55	2.45	0.26	1.55	1.77	1.10	2.48	2.16	3.40	3.97	8.27	7.95	ns
24 mA	Std.	1.55	2.46	0.26	1.55	1.77	1.10	2.49	2.09	3.47	4.44	8.28	7.88	ns

#### Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



## 1.8 V LVCMOS

Low-Voltage CMOS for 1.8 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 1.8 V applications. It uses a 1.8 V input buffer and a push-pull output buffer.

Table 2-52 • Minimum and Maximum DC Input and Output Levels

1.8 V LVCMOS		VIL	VIH		VOL	VOH	IOL	ЮН	IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mΑ	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	2	2	9	11	10	10
4 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	4	4	17	22	10	10
6 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	6	6	35	44	10	10
8 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	8	8	45	51	10	10
12 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	12	12	91	74	10	10
16 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	16	16	91	74	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

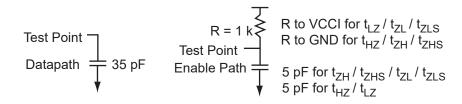


Figure 2-9 • AC Loading

Table 2-53 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	1.8	0.9	_	5

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.



# 1.5 V DC Core Voltage

Table 2-54 • 1.8 V LVCMOS Low Slew – Applies to 1.5 V DC Core Voltage
Commercial-Case Conditions: TJ = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.7 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zhs</sub>	Units
2 mA	Std.	0.97	7.33	0.18	1.27	1.59	0.66	7.47	6.18	2.34	1.18	11.07	9.77	ns
4 mA	Std.	0.97	6.07	0.18	1.27	1.59	0.66	6.20	5.25	2.69	2.42	9.79	8.84	ns
6 mA	Std.	0.97	5.18	0.18	1.27	1.59	0.66	5.29	4.61	2.93	2.88	8.88	8.21	ns
8 mA	Std.	0.97	4.88	0.18	1.27	1.59	0.66	4.98	4.48	2.99	3.01	8.58	8.08	ns
12 mA	Std.	0.97	4.80	0.18	1.27	1.59	0.66	4.89	4.49	3.07	3.47	8.49	8.09	ns
16 mA	Std.	0.97	4.80	0.18	1.27	1.59	0.66	4.89	4.49	3.07	3.47	8.49	8.09	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-55 • 1.8 V LVCMOS High Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.7 V

	Speed													
Drive Strength	Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	$t_{LZ}$	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	0.97	3.43	0.18	1.27	1.59	0.66	3.51	3.39	2.33	1.19	7.10	6.98	ns
4 mA	Std.	0.97	2.83	0.18	1.27	1.59	0.66	2.89	2.59	2.69	2.49	6.48	6.18	ns
6 mA	Std.	0.97	2.45	0.18	1.27	1.59	0.66	2.51	2.19	2.93	2.95	6.10	5.79	ns
8 mA	Std.	0.97	2.38	0.18	1.27	1.59	0.66	2.43	2.12	2.98	3.08	6.03	5.71	ns
12 mA	Std.	0.97	2.37	0.18	1.27	1.59	0.66	2.42	2.03	3.07	3.57	6.02	5.62	ns
16 mA	Std.	0.97	2.37	0.18	1.27	1.59	0.66	2.42	2.03	3.07	3.57	6.02	5.62	ns

## Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## 1.2 V DC Core Voltage

Table 2-56 • 1.8 V LVCMOS Low Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: TJ = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.7 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	1.55	8.21	0.26	1.53	1.96	1.10	8.35	6.88	2.87	1.70	14.14	12.67	ns
4 mA	Std.	1.55	6.83	0.26	1.53	1.96	1.10	6.94	5.88	3.27	3.18	12.73	11.67	ns
6 mA	Std.	1.55	5.85	0.26	1.53	1.96	1.10	5.94	5.19	3.53	3.37	11.73	10.98	ns
8 mA	Std.	1.55	5.52	0.26	1.53	1.96	1.10	5.61	5.06	3.59	3.88	11.39	10.84	ns
12 mA	Std.	1.55	5.42	0.26	1.53	1.96	1.10	5.51	5.06	3.68	4.44	11.30	10.85	ns
16 mA	Std.	1.55	5.42	0.26	1.53	1.96	1.10	5.51	5.06	3.68	4.44	11.30	10.85	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.

Table 2-57 • 1.8 V LVCMOS High Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.7 V

	Speed													
Drive Strength	Grade	t <sub>DOUT</sub>	$t_{DP}$	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	$t_{LZ}$	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	1.55	3.82	0.26	1.53	1.96	1.10	3.98	3.87	2.86	1.72	9.76	9.66	ns
4 mA	Std.	1.55	3.25	0.26	1.53	1.96	1.10	3.30	3.01	3.26	3.26	9.08	8.79	ns
6 mA	Std.	1.55	2.84	0.26	1.53	1.96	1.10	2.88	2.58	3.53	3.81	8.66	8.37	ns
8 mA	Std.	1.55	2.76	0.26	1.53	1.96	1.10	2.80	2.50	3.58	3.97	8.58	8.29	ns
12 mA	Std.	1.55	2.75	0.26	1.53	1.96	1.10	2.78	2.40	3.68	4.56	8.57	8.19	ns
16 mA	Std.	1.55	2.75	0.26	1.53	1.96	1.10	2.78	2.40	3.68	4.56	8.57	8.19	ns

#### Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



# 1.5 V LVCMOS (JESD8-11)

Low-Voltage CMOS for 1.5 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 1.5 V applications. It uses a 1.5 V input buffer and a push-pull output buffer.

Table 2-58 • Minimum and Maximum DC Input and Output Levels

1.5 V LVCMOS		VIL	VIH		VOL	VOH	IOL	ЮН	IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. Max. V V		Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	2	2	13	16	10	10
4 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	4	4	25	33	10	10
6 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	6	6	32	39	10	10
8 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	8	8	66	55	10	10
12 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	12	12	66	55	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

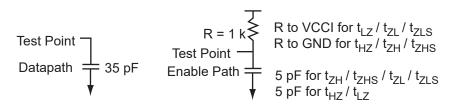


Figure 2-10 • AC Loading

Table 2-59 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	1.5	0.75	_	5

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.



# 1.5 V DC Core Voltage

Table 2-60 • 1.5 V LVCMOS Low Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	0.97	7.61	0.18	1.47	1.77	0.66	7.76	6.33	2.81	2.34	11.36	9.92	ns
4 mA	Std.	0.97	6.54	0.18	1.47	1.77	0.66	6.67	5.56	3.09	2.88	10.26	9.16	ns
6 mA	Std.	0.97	6.15	0.18	1.47	1.77	0.66	6.27	5.42	3.15	3.02	9.87	9.02	ns
8 mA	Std.	0.97	6.07	0.18	1.47	1.77	0.66	6.20	5.42	2.64	3.56	9.79	9.02	ns
12 mA	Std.	0.97	6.07	0.18	1.47	1.77	0.66	6.20	5.42	2.64	3.56	9.79	9.02	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-61 • 1.5 V LVCMOS High Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	0.97	3.25	0.18	1.47	1.77	0.66	3.32	3.00	2.80	2.43	6.92	6.59	ns
4 mA	Std.	0.97	2.81	0.18	1.47	1.77	0.66	2.87	2.51	3.08	2.97	6.46	6.10	ns
6 mA	Std.	0.97	2.72	0.18	1.47	1.77	0.66	2.78	2.41	3.14	3.12	6.37	6.01	ns
8 mA	Std.	0.97	2.69	0.18	1.47	1.77	0.66	2.75	2.30	3.24	3.67	6.35	5.89	ns
12 mA	Std.	0.97	2.69	0.18	1.47	1.77	0.66	2.75	2.30	3.24	3.67	6.35	5.89	ns

#### Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



# 1.2 V DC Core Voltage

Table 2-62 • 1.5 V LVCMOS Low Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.4 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	1.55	8.53	0.26	1.72	2.16	1.10	8.67	7.05	3.39	3.09	14.46	12.83	ns
4 mA	Std.	1.55	7.34	0.26	1.72	2.16	1.10	7.46	6.22	3.70	3.73	13.25	12.01	ns
6 mA	Std.	1.55	6.91	0.26	1.72	2.16	1.10	7.03	6.07	3.77	3.90	12.82	11.85	ns
8 mA	Std.	1.55	6.83	0.26	1.72	2.16	1.10	6.94	6.07	2.91	4.54	12.73	11.86	ns
12 mA	Std.	1.55	6.83	0.26	1.72	2.16	1.10	6.94	6.07	2.91	4.54	12.73	11.86	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.

Table 2-63 • 1.5 V LVCMOS High Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.4 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	1.55	3.72	0.26	1.72	2.16	1.10	3.78	3.45	3.38	3.19	9.56	9.24	ns
4 mA	Std.	1.55	3.23	0.26	1.72	2.16	1.10	3.27	2.92	3.69	3.83	9.06	8.71	ns
6 mA	Std.	1.55	3.13	0.26	1.72	2.16	1.10	3.18	2.82	3.76	4.01	8.96	8.61	ns
8 mA	Std.	1.55	3.10	0.26	1.72	2.16	1.10	3.15	2.70	3.86	4.68	8.93	8.49	ns
12 mA	Std.	1.55	3.10	0.26	1.72	2.16	1.10	3.15	2.70	3.86	4.68	8.93	8.49	ns

#### Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



# 1.2 V LVCMOS (JESD8-12A)

Low-Voltage CMOS for 1.2 V complies with the LVCMOS standard JESD8-12A for general purpose 1.2 V applications. It uses a 1.2 V input buffer and a push-pull output buffer.

Table 2-64 • Minimum and Maximum DC Input and Output Levels
Applicable to Advanced I/O Banks

1.2 V LVCMOS <sup>1</sup>		VIL	VIH		VOL	VOH	IOL	ЮН	IOSH	IOSL	IIL <sup>2</sup>	IIH <sup>3</sup>
Drive Strength	Min. V	Max. V	Min. V	Min. Max. V		Min. V	mA	mA	Max. mA <sup>4</sup>	Max. mA <sup>4</sup>	μ <b>Α</b> <sup>5</sup>	μ <b>Α</b> <sup>5</sup>
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	2	2	20	26	10	10

#### Notes:

- 1. Applicable to V2 devices ONLY.
- 2. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 3. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 4. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 5. Currents are measured at 85°C junction temperature.
- 6. Software default selection highlighted in gray.

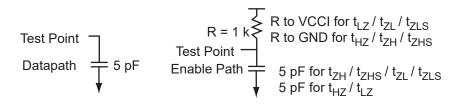


Figure 2-11 • AC Loading

Table 2-65 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	1.2	0.6	-	5

Note: \*Measuring point = Vtrip See Table 2-23 on page 2-23 for a complete table of trip points.



## 1.2 V DC Core Voltage

Table 2-66 • 1.2 LVCMOS Low Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>.I</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.14 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	1.55	9.92	0.26	2.09	2.95	1.10	9.53	7.48	4.02	3.67	15.31	13.26	ns

#### Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.

Table 2-67 • 1.2 LVCMOS High Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>.I</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.14 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	1.55	4.06	0.26	2.09	2.95	1.10	3.92	3.46	4.01	3.79	9.71	9.24	ns

#### Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.

# 1.2 V LVCMOS Wide Range

Table 2-68 • Minimum and Maximum DC Input and Output Levels

1.2 V LV0 Wide Raı			VIL	VIH		VOL	VOH	IOL	ЮН	юзн	IOSL	IIL <sup>2</sup>	IIH <sup>3</sup>
Drive Strength	Equivalent Software Default Drive Strength Option <sup>4</sup>		Max. (V)	Min. (V)	Max (V)	Max. (V)	Min. (V)	μΑ	μΑ	Max. (mA) <sup>5</sup>		μ <b>Α</b> <sup>6</sup>	μ <b>Α</b> <sup>6</sup>
100 μΑ	2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	100	100	20	26	10	10

#### Notes:

- 1. Applicable to V2 devices ONLY.
- 2. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 3. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 4. The minimum drive strength for any LVCMOS 1.2 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 5. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 6. Currents are measured at 85°C junction temperature.
- 7. Software default selection highlighted in gray.

## **Timing Characteristics**

Refer to LVCMOS 1.2 V (normal range) "Timing Characteristics" on page 2-48 for worst-case timing.



## 3.3 V PCI, 3.3 V PCI-X

Peripheral Component Interface for 3.3 V standard specifies support for 33 MHz and 66 MHz PCI Bus applications.

Table 2-69 • Minimum and Maximum DC Input and Output Levels

3.3 V PCI/PCI-X	V	IL	V	IH	VOL	VOH	IOL	ЮН	IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min., V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
Per PCI specification					Per P	CI curve	s				10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

AC loadings are defined per the PCI/PCI-X specifications for the datapath; Microsemi loadings for enable path characterization are described in Figure 2-12.

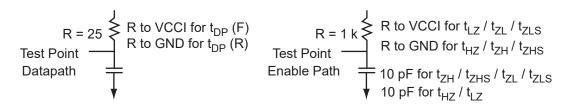


Figure 2-12 • AC Loading

AC loadings are defined per PCI/PCI-X specifications for the datapath; Microsemi loading for tristate is described in Table 2-70.

Table 2-70 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	3.3	0.285 * VCCI for t <sub>DP(R)</sub> 0.615 * VCCI for t <sub>DP(F)</sub>	I	10

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.



# 1.5 V DC Core Voltage

Table 2-71 • 3.3 V PCI/PCI-X – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.97	2.38	0.18	0.96	1.42	0.66	2.43	1.80	2.72	3.08	6.03	5.39	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

# 1.2 V DC Core Voltage

Table 2-72 • 3.3 V PCI/PCI-X – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 3.0 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	1.55	2.76	0.26	1.19	1.63	1.10	2.79	2.16	3.29	3.97	8.58	7.94	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



# **Voltage-Referenced I/O Characteristics**

# 3.3 V GTL

Gunning Transceiver Logic is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 3.3 V.

Table 2-73 • Minimum and Maximum DC Input and Output Levels

3.3 V GTL		VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
20 mA <sup>5</sup>	-0.3	VREF - 0.05	VREF + 0.05	3.6	0.4	-	20	20	268	181	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operating conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Output drive strength is below JEDEC specification.

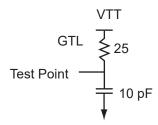


Figure 2-13 • AC Loading

Table 2-74 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.05	VREF + 0.05	0.8	0.8	1.2	10

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.



## 1.5 V DC Core Voltage

# Table 2-75 • 3.3 V GTL – Applies to 1.5 V DC Core Voltage Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V VREF = 0.8 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.98	1.83	0.19	2.41	0.67	1.84	1.83			5.47	5.46	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

#### 1.2 V DC Core Voltage

# Table 2-76 • 3.3 V GTL – Applies to 1.2 V DC Core Voltage Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 3.0 V VREF = 0.8 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	1.55	2.09	0.26	2.75	1.10	2.10	2.09			7.91	7.89	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



#### 2.5 V GTL

Gunning Transceiver Logic is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 2.5 V.

Table 2-77 • Minimum and Maximum DC Input and Output Levels

2.5 GTL		VIL	VIH		VOL	VOH	IOL	ЮН	IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
20 mA <sup>5</sup>	-0.3	VREF - 0.05	VREF + 0.05	3.6	0.4	_	20	20	169	124	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operating conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Output drive strength is below JEDEC specification.

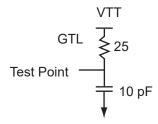


Figure 2-14 • AC Loading

Table 2-78 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.05	VREF + 0.05	0.8	0.8	1.2	10

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.

## **Timing Characteristics**

## 1.5 V DC Core Voltage

Table 2-79 • 2.5 V GTL – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,

Worst-Case VCCI = 3.0 V VREF = 0.8 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.98	1.90	0.19	2.04	0.67	1.94	1.87			5.57	5.50	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

## 1.2 V DC Core Voltage

Table 2-80 • 2.5 V GTL – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V,

Worst-Case VCCI = 3.0 V VREF = 0.8 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	1.55	2.16	0.26	2.35	1.10	2.20	2.13			8.01	7.94	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



## 3.3 V GTL+

Gunning Transceiver Logic Plus is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 3.3 V

Table 2-81 • Minimum and Maximum DC Input and Output Levels

3.3 V GTL+		VIL	VIH		VOL	VOH	IOL	ЮН	IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
35 mA	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.6	_	35	35	268	181	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operating conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

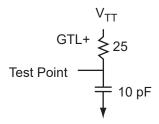


Figure 2-15 • AC Loading

Table 2-82 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.1	VREF + 0.1	1.0	1.0	1.5	10

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.

#### **Timing Characteristics**

## 1.5 V DC Core Voltage

Table 2-83 • 3.3 V GTL+ – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,

Worst-Case VCCI = 3.0 V VREF = 1.0 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.98	1.85	0.19	1.35	0.67	1.88	1.81			5.51	5.44	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

## 1.2 V DC Core Voltage

Table 2-84 • 3.3 V GTL+ – Applies to 1.2 V DC Core Voltage
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V,
Worst-Case VCCI = 3.0 V VREF = 1.0 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	1.55	2.11	0.26	1.61	1.10	2.15	2.07			7.95	7.88	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



## 2.5 V GTL+

Gunning Transceiver Logic Plus is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 2.5 V.

Table 2-85 • Minimum and Maximum DC Input and Output Levels

2.5 V GTL+		VIL	VIH		VOL	VOH	IOL	ЮН	IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
33 mA	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.6	-	33	33	169	124	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operating conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

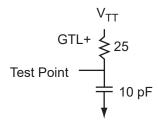


Figure 2-16 • AC Loading

Table 2-86 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.1	VREF + 0.1	1.0	1.0	1.5	10

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.

# **Timing Characteristics**

# 1.5 V DC Core Voltage

Table 2-87 • 2.5 V GTL+ – Applies to 1.5 V DC Core Voltage
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 2.3 V VREF = 1.0 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.98	1.97	0.19	1.29	0.67	2.00	1.84			5.63	5.47	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

#### 1.2 V DC Core Voltage

Table 2-88 • 2.5 V GTL+ – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V,

Worst-Case VCCI = 2.3 V VREF = 1.0 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	1.55	2.23	0.26	1.55	1.10	2.28	2.11			8.08	7.91	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



## **HSTL Class I**

High-Speed Transceiver Logic is a general-purpose high-speed 1.5 V bus standard (EIA/JESD8-6). IGLOOe devices support Class I. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-89 · Minimum and Maximum DC Input and Output Levels

HSTL Class I		VIL	VIH		VOL	VOH	IOL	ЮН	IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mΑ	mΑ	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
8 mA	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.4	VCCI - 0.4	8	8	32	39	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operating conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

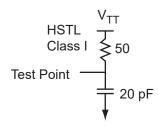


Figure 2-17 • AC Loading

Table 2-90 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.1	VREF + 0.1	0.75	0.75	0.75	20

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.

# **Timing Characteristics**

# 1.5 V DC Core Voltage

Table 2-91 • HSTL Class I – Applies to 1.5 V DC Core Voltage
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 1.4 V VREF = 0.75 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.98	2.74	0.19	1.77	0.67	2.79	2.73			6.42	6.36	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

#### 1.2 V DC Core Voltage

Table 2-92 • HSTL Class I – Applies to 1.2 V DC Core Voltage Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.4 V VREF = 0.75 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	1.55	3.10	0.26	1.94	1.10	3.12	3.10			8.93	8.91	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



## **HSTL Class II**

High-Speed Transceiver Logic is a general-purpose high-speed 1.5 V bus standard (EIA/JESD8-6). IGLOOe devices support Class II. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-93 · Minimum and Maximum DC Input and Output Levels

HSTL Class II		VIL	VIH		VOL	VOH	IOL IOH		IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Max. Min. Max. V V		Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
15 mA <sup>5</sup>	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.4	VCCI - 0.4	15	15	66	55	10	10

#### Notes:

- IIL is the input leakage current per I/O pin over recommended operating conditions where -0.3 V < VIN < VIL.</li>
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Output drive strength is below JEDEC specification.

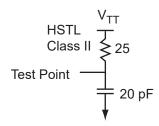


Figure 2-18 • AC Loading

Table 2-94 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.1	VREF + 0.1	0.75	0.75	0.75	20

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.

#### **Timing Characteristics**

## 1.5 V DC Core Voltage

Table 2-95 • HSTL Class II – Applies to 1.5 V DC Core Voltage Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V VREF = 0.75 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.98	2.62	0.19	1.77	0.67	2.66	2.40			6.29	6.03	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

#### 1.2 V DC Core Voltage

Table 2-96 • HSTL Class II – Applies to 1.2 V DC Core Voltage Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.4 V VREF = 0.75 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	1.55	2.93	0.26	1.94	1.10	2.98	2.75			8.79	8.55	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



## SSTL2 Class I

Stub-Speed Terminated Logic for 2.5 V memory bus standard (JESD8-9). IGLOOe devices support Class I. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-97 • Minimum and Maximum DC Input and Output Levels

SSTL2 Class I	VIL		VIH		VOL	VOL VOH I		ЮН	IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
15 mA	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.54	VCCI - 0.62	15	15	83	87	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operating conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

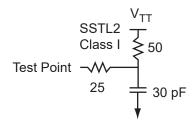


Figure 2-19 • AC Loading

Table 2-98 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.2	VREF + 0.2	1.25	1.25	1.25	30

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.

## **Timing Characteristics**

## 1.5 V DC Core Voltage

Table 2-99 • SSTL 2 Class I – Applies to 1.5 V DC Core Voltage
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 2.3 V VREF = 1.25 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.98	1.91	0.19	1.15	0.67	1.94	1.72			5.57	5.35	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

## 1.2 V DC Core Voltage

Table 2-100 • SSTL 2 Class I – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V,

Worst-Case VCCI = 2.3 V VREF = 1.25 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	1.55	2.17	0.26	1.39	1.10	2.21	2.04			8.02	7.84	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



#### SSTL2 Class II

Stub-Speed Terminated Logic for 2.5 V memory bus standard (JESD8-9). IGLOOe devices support Class II. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-101 • Minimum and Maximum DC Input and Output Levels

SSTL2 Class II		VIL	VIH		VOL	VOH	IOL	ЮН	юзн	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
18 mA	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.35	VCCI - 0.43	18	18	169	124	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operating conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

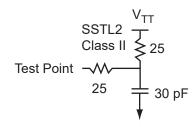


Figure 2-20 • AC Loading

Table 2-102 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input HIGH (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.2	VREF + 0.2	1.25	1.25	1.25	30

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.

#### **Timing Characteristics**

## 1.5 V DC Core Voltage

# Table 2-103 • SSTL 2 Class II – Applies to 1.5 V DC Core Voltage Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V VREF = 1.25 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.98	1.94	0.19	1.15	0.67	1.97	1.66			5.60	5.29	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

#### 1.2 V DC Core Voltage

Table 2-104 • SSTL 2 Class II – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V,

Worst-Case VCCI = 2.3 V VREF = 1.25 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	1.55	2.20	0.26	1.39	1.10	2.24	1.97			8.05	7.78	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



#### SSTL3 Class I

Stub-Speed Terminated Logic for 3.3 V memory bus standard (JESD8-8). IGLOOe devices support Class I. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-105 • Minimum and Maximum DC Input and Output Levels

SSTL3 Class I		VIL	VIH		VOL	VOH	IOL	ЮН	IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
14 mA	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.7	VCCI - 1.1	14	14	51	54	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operating conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

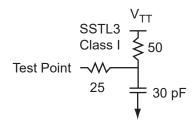


Figure 2-21 • AC Loading

Table 2-106 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.2	VREF + 0.2	1.5	1.5	1.485	30

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.

#### **Timing Characteristics**

#### 1.5 V DC Core Voltage

# Table 2-107 • SSTL 3 Class I – Applies to 1.5 V DC Core Voltage Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V VREF = 1.5 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.98	2.05	0.19	1.09	0.67	2.09	1.71			5.72	5.34	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

## 1.2 V DC Core Voltage

Table 2-108 • SSTL 3 Class I – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V,

Worst-Case VCCI = 3.0 V VREF = 1.5 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	1.55	2.32	0.26	1.32	1.10	2.37	2.02			8.17	7.83	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



#### SSTL3 Class II

Stub-Speed Terminated Logic for 3.3 V memory bus standard (JESD8-8). IGLOOe devices support Class II. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-109 • Minimum and Maximum DC Input and Output Levels

SSTL3 Class II		VIL	VIH		VOL	VOH	IOL	ЮН	IOSH	IOSL	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
21 mA	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.5	VCCI - 0.9	21	21	103	109	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operating conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

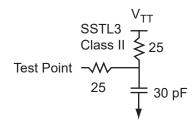


Figure 2-22 • AC Loading

Table 2-110 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.2	VREF + 0.2	1.5	1.5	1.485	30

Note: Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.

#### **Timing Characteristics**

#### 1.5 V DC Core Voltage

Table 2-111 • SSTL 3 Class II – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: TJ = 70°C, Worst-Case VCC = 1.425 V,

Worst-Case VCCI = 3.0 V VREF = 1.5 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.98	1.86	0.19	1.09	0.67	1.89	1.58			5.52	5.21	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

## 1.2 V DC Core Voltage

Table 2-112 • SSTL 3 Class II – Applies to 1.2 V DC Core Voltage Commercial-Case Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 3.0 V VREF = 1.5 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	1.55	2.12	0.26	1.32	1.10	2.16	1.89			7.97	7.70	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



#### **Differential I/O Characteristics**

## Physical Implementation

Configuration of the I/O modules as a differential pair is handled by the Microsemi Designer software when the user instantiates a differential I/O macro in the design.

Differential I/Os can also be used in conjunction with the embedded Input Register (InReg), Output Register (OutReg), Enable Register (EnReg), and DDR. However, there is no support for bidirectional I/Os or tristates with the LVPECL standards.

#### **LVDS**

Low-Voltage Differential Signaling (ANSI/TIA/EIA-644) is a high-speed, differential I/O standard. It requires that one data bit be carried through two signal lines, so two pins are needed. It also requires external resistor termination.

The full implementation of the LVDS transmitter and receiver is shown in an example in Figure 2-23. The building blocks of the LVDS transmitter-receiver are one transmitter macro, one receiver macro, three board resistors at the transmitter end, and one resistor at the receiver end. The values for the three driver resistors are different from those used in the LVPECL implementation because the output standard specifications are different.

Along with LVDS I/O, IGLOOe also supports Bus LVDS structure and Multipoint LVDS (M-LVDS) configuration (up to 40 nodes).

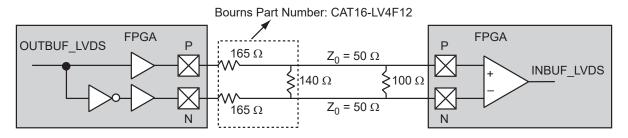


Figure 2-23 • LVDS Circuit Diagram and Board-Level Implementation



Table 2-113 • Minimum and Maximum DC Input and Output Levels

DC Parameter	Description	Min.	Тур.	Max.	Units
VCCI	Supply Voltage	2.375	2.5	2.625	V
VOL	Output Low Voltage	0.9	1.075	1.25	V
VOH	Output High Voltage	1.25	1.425	1.6	V
IOL <sup>1</sup>	Output Lower Current	0.65	0.91	1.16	mA
IOH <sup>1</sup>	Output High Current	0.65	0.91	1.16	mA
VI	Input Voltage	0		2.925	V
IIH <sup>2,3</sup>	Input High Leakage Current			10	μA
IIL <sup>2,4</sup>	Input Low Leakage Current			10	μΑ
VODIFF	Differential Output Voltage	250	350	450	mV
VOCM	Output Common Mode Voltage	1.125	1.25	1.375	V
VICM	Input Common Mode Voltage	0.05	1.25	2.35	V
VIDIFF	Input Differential Voltage	100	350		mV

#### Notes:

- 1. IOL/IOH is defined by VODIFF/(resistor network).
- 2. Currents are measured at 85°C junction temperature.
- 3. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 4. IIL is the input leakage current per I/O pin over recommended operating conditions where -0.3 V < VIN < VIL.

Table 2-114 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)
1.075	1.325	Cross point	-

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.

#### **Timing Characteristics**

#### 1.5 V DC Core Voltage

Table 2-115 • LVDS – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	Units
Std.	0.98	1.77	0.19	1.62	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

## 1.2 V DC Core Voltage

Table 2-116 • LVDS – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.3 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	Units
Std.	1.55	2.19	0.26	1.88	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



#### **B-LVDS/M-LVDS**

Bus LVDS (B-LVDS) and Multipoint LVDS (M-LVDS) specifications extend the existing LVDS standard to high-performance multipoint bus applications. Multidrop and multipoint bus configurations may contain any combination of drivers, receivers, and transceivers. Microsemi LVDS drivers provide the higher drive current required by B-LVDS and M-LVDS to accommodate the loading. The drivers require series terminations for better signal quality and to control voltage swing. Termination is also required at both ends of the bus since the driver can be located anywhere on the bus. These configurations can be implemented using the TRIBUF\_LVDS and BIBUF\_LVDS macros along with appropriate terminations. Multipoint designs using Microsemi LVDS macros can achieve up to 200 MHz with a maximum of 20 loads. A sample application is given in Figure 2-24. The input and output buffer delays are available in the LVDS section in Table 2-115 on page 2-63 and Table 2-116 on page 2-63.

Example: For a bus consisting of 20 equidistant loads, the following terminations provide the required differential voltage, in worst-case Industrial operating conditions, at the farthest receiver:  $R_S$  = 60  $\Omega$  and  $R_T$  = 70  $\Omega$ , given  $Z_0$  = 50  $\Omega$  (2") and  $Z_{stub}$  = 50  $\Omega$  (~1.5").

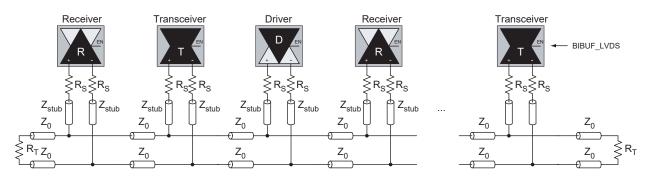


Figure 2-24 • B-LVDS/M-LVDS Multipoint Application Using LVDS I/O Buffers

#### **LVPECL**

Low-Voltage Positive Emitter-Coupled Logic (LVPECL) is another differential I/O standard. It requires that one data bit be carried through two signal lines. Like LVDS, two pins are needed. It also requires external resistor termination.

The full implementation of the LVDS transmitter and receiver is shown in an example in Figure 2-25. The building blocks of the LVPECL transmitter-receiver are one transmitter macro, one receiver macro, three board resistors at the transmitter end, and one resistor at the receiver end. The values for the three driver resistors are different from those used in the LVDS implementation because the output standard specifications are different.

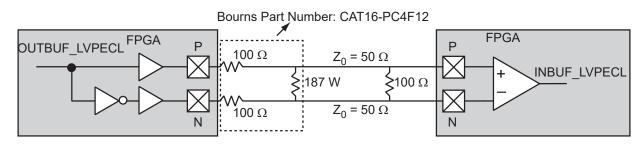


Figure 2-25 • LVPECL Circuit Diagram and Board-Level Implementation



Table 2-117 • Minimum and Maximum DC Input and Output Levels

DC Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Units
VCCI	Supply Voltage	3	.0	3.	.3	3	.6	V
VOL	Output Low Voltage	0.96	1.27	1.06	1.43	1.30	1.57	V
VOH	Output High Voltage	1.8	2.11	1.92	2.28	2.13	2.41	V
VIL, VIH	Input Low, Input High Voltages	0	3.6	0	3.6	0	3.6	V
VODIFF	Differential Output Voltage	0.625	0.97	0.625	0.97	0.625	0.97	V
VOCM	Output Common Mode Voltage	1.762	1.98	1.762	1.98	1.762	1.98	V
VICM	Input Common Mode Voltage	1.01	2.57	1.01	2.57	1.01	2.57	V
VIDIFF	Input Differential Voltage	300		300		300		mV

Table 2-118 • AC Waveforms, Measuring Points, and Capacitive Loads

Input LOW (V)	Input HIGH (V)	Measuring Point* (V)	VREF (typ.) (V)
1.64	1.94	Cross point	-

Note: \*Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.

#### **Timing Characteristics**

1.5 V DC Core Voltage

Table 2-119 • LVPECL - Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	Units
Std.	0.98	1.75	0.19	1.45	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

#### 1.2 V DC Core Voltage

Table 2-120 • LVPECL - Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 3.0 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	Units
Std.	1.55	2.16	0.26	1.70	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



# **I/O Register Specifications**

# Fully Registered I/O Buffers with Synchronous Enable and Asynchronous Preset

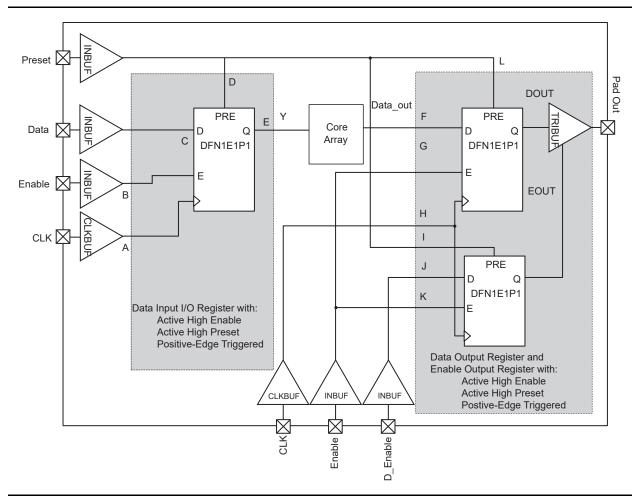


Figure 2-26 • Timing Model of Registered I/O Buffers with Synchronous Enable and Asynchronous Preset



Table 2-121 • Parameter Definition and Measuring Nodes

Parameter Name	Parameter Definition	Measuring Nodes (from, to)*
t <sub>OCLKQ</sub>	Clock-to-Q of the Output Data Register	H, DOUT
tosup	Data Setup Time for the Output Data Register	F, H
t <sub>OHD</sub>	Data Hold Time for the Output Data Register	F, H
tosuE	Enable Setup Time for the Output Data Register	G, H
t <sub>OHE</sub>	Enable Hold Time for the Output Data Register	G, H
t <sub>OPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Data Register	L, DOUT
t <sub>OREMPRE</sub>	Asynchronous Preset Removal Time for the Output Data Register	L, H
t <sub>ORECPRE</sub>	Asynchronous Preset Recovery Time for the Output Data Register	L, H
t <sub>OECLKQ</sub>	Clock-to-Q of the Output Enable Register	H, EOUT
toesud	Data Setup Time for the Output Enable Register	J, H
t <sub>OEHD</sub>	Data Hold Time for the Output Enable Register	J, H
toesue	Enable Setup Time for the Output Enable Register	K, H
t <sub>OEHE</sub>	Enable Hold Time for the Output Enable Register	K, H
t <sub>OEPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Enable Register	I, EOUT
t <sub>OEREMPRE</sub>	Asynchronous Preset Removal Time for the Output Enable Register	I, H
t <sub>OERECPRE</sub>	Asynchronous Preset Recovery Time for the Output Enable Register	I, H
t <sub>ICLKQ</sub>	Clock-to-Q of the Input Data Register	A, E
t <sub>ISUD</sub>	Data Setup Time for the Input Data Register	C, A
t <sub>IHD</sub>	Data Hold Time for the Input Data Register	C, A
t <sub>ISUE</sub>	Enable Setup Time for the Input Data Register	B, A
t <sub>IHE</sub>	Enable Hold Time for the Input Data Register	B, A
t <sub>IPRE2Q</sub>	Asynchronous Preset-to-Q of the Input Data Register	D, E
t <sub>IREMPRE</sub>	Asynchronous Preset Removal Time for the Input Data Register	D, A
t <sub>IRECPRE</sub>	Asynchronous Preset Recovery Time for the Input Data Register	D, A

Note: See Figure 2-26 on page 2-66 for more information.



# Fully Registered I/O Buffers with Synchronous Enable and Asynchronous Clear

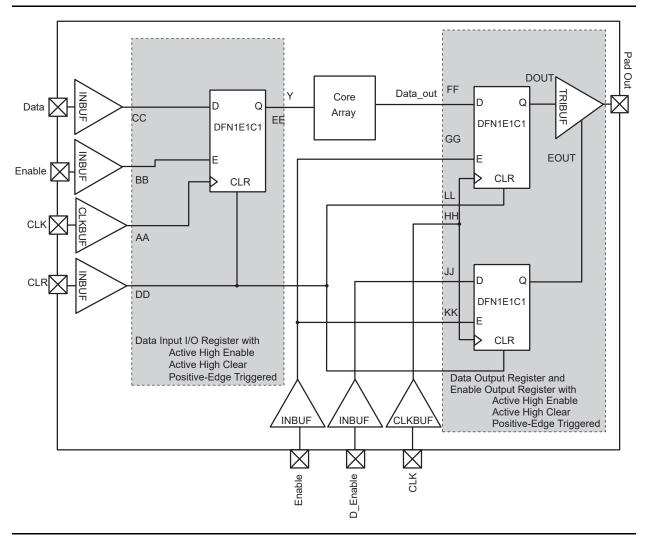


Figure 2-27 • Timing Model of the Registered I/O Buffers with Synchronous Enable and Asynchronous Clear



Table 2-122 • Parameter Definition and Measuring Nodes

Parameter Name	Parameter Definition	Measuring Nodes (from, to)*
t <sub>OCLKQ</sub>	Clock-to-Q of the Output Data Register	HH, DOUT
tosud	Data Setup Time for the Output Data Register	FF, HH
t <sub>OHD</sub>	Data Hold Time for the Output Data Register	FF, HH
tosuE	Enable Setup Time for the Output Data Register	GG, HH
t <sub>OHE</sub>	Enable Hold Time for the Output Data Register	GG, HH
t <sub>OCLR2Q</sub>	Asynchronous Clear-to-Q of the Output Data Register	LL, DOUT
tOREMCLR	Asynchronous Clear Removal Time for the Output Data Register	LL, HH
torecclr	Asynchronous Clear Recovery Time for the Output Data Register	LL, HH
t <sub>OECLKQ</sub>	Clock-to-Q of the Output Enable Register	HH, EOUT
t <sub>OESUD</sub>	Data Setup Time for the Output Enable Register	JJ, HH
t <sub>OEHD</sub>	Data Hold Time for the Output Enable Register	JJ, HH
t <sub>OESUE</sub>	Enable Setup Time for the Output Enable Register	KK, HH
t <sub>OEHE</sub>	Enable Hold Time for the Output Enable Register	KK, HH
t <sub>OECLR2Q</sub>	Asynchronous Clear-to-Q of the Output Enable Register	II, EOUT
toeremclr	Asynchronous Clear Removal Time for the Output Enable Register	II, HH
toerecclr	Asynchronous Clear Recovery Time for the Output Enable Register	II, HH
t <sub>ICLKQ</sub>	Clock-to-Q of the Input Data Register	AA, EE
t <sub>ISUD</sub>	Data Setup Time for the Input Data Register	CC, AA
t <sub>IHD</sub>	Data Hold Time for the Input Data Register	CC, AA
t <sub>ISUE</sub>	Enable Setup Time for the Input Data Register	BB, AA
t <sub>IHE</sub>	Enable Hold Time for the Input Data Register	BB, AA
t <sub>ICLR2Q</sub>	Asynchronous Clear-to-Q of the Input Data Register	DD, EE
t <sub>IREMCLR</sub>	Asynchronous Clear Removal Time for the Input Data Register	DD, AA
t <sub>IRECCLR</sub>	Asynchronous Clear Recovery Time for the Input Data Register	DD, AA

Note: \*See Figure 2-27 on page 2-68 for more information.



# Input Register

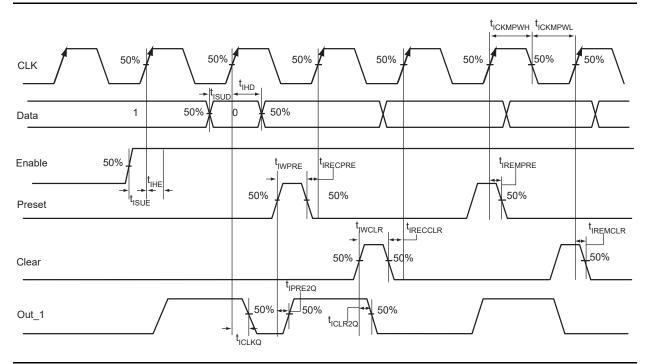


Figure 2-28 • Input Register Timing Diagram

## **Timing Characteristics**

1.5 V DC Core Voltage

Table 2-123 • Input Data Register Propagation Delays
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t <sub>ICLKQ</sub>	Clock-to-Q of the Input Data Register	0.42	ns
t <sub>ISUD</sub>	Data Setup Time for the Input Data Register	0.47	ns
t <sub>IHD</sub>	Data Hold Time for the Input Data Register	0.00	ns
t <sub>ISUE</sub>	Enable Setup Time for the Input Data Register	0.67	ns
t <sub>IHE</sub>	Enable Hold Time for the Input Data Register	0.00	ns
t <sub>ICLR2Q</sub>	Asynchronous Clear-to-Q of the Input Data Register	0.79	ns
t <sub>IPRE2Q</sub>	Asynchronous Preset-to-Q of the Input Data Register	0.79	ns
t <sub>IREMCLR</sub>	Asynchronous Clear Removal Time for the Input Data Register	0.00	ns
t <sub>IRECCLR</sub>	Asynchronous Clear Recovery Time for the Input Data Register	0.24	ns
t <sub>IREMPRE</sub>	Asynchronous Preset Removal Time for the Input Data Register	0.00	ns
t <sub>IRECPRE</sub>	Asynchronous Preset Recovery Time for the Input Data Register	0.24	ns
t <sub>IWCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Input Data Register	0.19	ns
t <sub>IWPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Input Data Register	0.19	ns
t <sub>ICKMPWH</sub>	Clock Minimum Pulse Width HIGH for the Input Data Register	0.31	ns
t <sub>ICKMPWL</sub>	Clock Minimum Pulse Width LOW for the Input Data Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## 1.2 V DC Core Voltage

Table 2-124 • Input Data Register Propagation Delays Commercial-Case Conditions:  $T_J = 70^{\circ}$ C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t <sub>ICLKQ</sub>	Clock-to-Q of the Input Data Register	0.68	ns
t <sub>ISUD</sub>	Data Setup Time for the Input Data Register	0.97	ns
t <sub>IHD</sub>	Data Hold Time for the Input Data Register	0.00	ns
t <sub>ISUE</sub>	Enable Setup Time for the Input Data Register	1.02	ns
t <sub>IHE</sub>	Enable Hold Time for the Input Data Register	0.00	ns
t <sub>ICLR2Q</sub>	Asynchronous Clear-to-Q of the Input Data Register	1.19	ns
t <sub>IPRE2Q</sub>	Asynchronous Preset-to-Q of the Input Data Register	1.19	ns
t <sub>IREMCLR</sub>	Asynchronous Clear Removal Time for the Input Data Register	0.00	ns
t <sub>IRECCLR</sub>	Asynchronous Clear Recovery Time for the Input Data Register	0.24	ns
t <sub>IREMPRE</sub>	Asynchronous Preset Removal Time for the Input Data Register	0.00	ns
t <sub>IRECPRE</sub>	Asynchronous Preset Recovery Time for the Input Data Register	0.24	ns
t <sub>IWCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Input Data Register	0.19	ns
t <sub>IWPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Input Data Register	0.19	ns
t <sub>ICKMPWH</sub>	Clock Minimum Pulse Width HIGH for the Input Data Register	0.31	ns
t <sub>ICKMPWL</sub>	Clock Minimum Pulse Width LOW for the Input Data Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



# **Output Register**

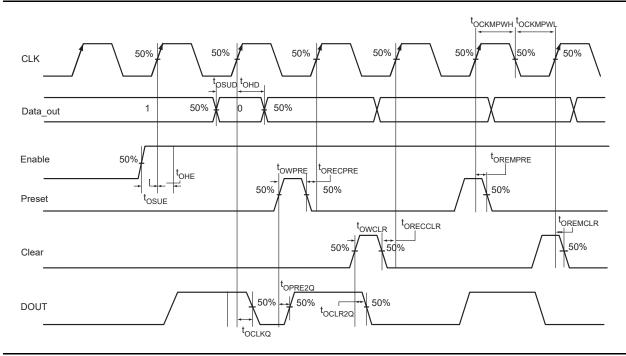


Figure 2-29 • Output Register Timing Diagram

## **Timing Characteristics**

1.5 V DC Core Voltage

Table 2-125 • Output Data Register Propagation Delays
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t <sub>OCLKQ</sub>	Clock-to-Q of the Output Data Register	1.00	ns
tosup	Data Setup Time for the Output Data Register	0.51	ns
t <sub>OHD</sub>	Data Hold Time for the Output Data Register	0.00	ns
t <sub>OSUE</sub>	Enable Setup Time for the Output Data Register	0.70	ns
t <sub>OHE</sub>	Enable Hold Time for the Output Data Register	0.00	ns
t <sub>OCLR2Q</sub>	Asynchronous Clear-to-Q of the Output Data Register	1.34	ns
t <sub>OPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Data Register	1.34	ns
t <sub>OREMCLR</sub>	Asynchronous Clear Removal Time for the Output Data Register	0.00	ns
torecclr	Asynchronous Clear Recovery Time for the Output Data Register	0.24	ns
t <sub>OREMPRE</sub>	Asynchronous Preset Removal Time for the Output Data Register	0.00	ns
t <sub>ORECPRE</sub>	Asynchronous Preset Recovery Time for the Output Data Register	0.24	ns
t <sub>OWCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Output Data Register	0.19	ns
t <sub>OWPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Output Data Register	0.19	ns
t <sub>OCKMPWH</sub>	Clock Minimum Pulse Width HIGH for the Output Data Register	0.31	ns
t <sub>OCKMPWL</sub>	Clock Minimum Pulse Width LOW for the Output Data Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## 1.2 V DC Core Voltage

Table 2-126 • Output Data Register Propagation Delays Commercial-Case Conditions:  $T_J = 70^{\circ}\text{C}$ , Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t <sub>OCLKQ</sub>	Clock-to-Q of the Output Data Register	1.52	ns
tosup	Data Setup Time for the Output Data Register	1.15	ns
t <sub>OHD</sub>	Data Hold Time for the Output Data Register	0.00	ns
t <sub>OSUE</sub>	Enable Setup Time for the Output Data Register	1.11	ns
t <sub>OHE</sub>	Enable Hold Time for the Output Data Register	0.00	ns
t <sub>OCLR2Q</sub>	Asynchronous Clear-to-Q of the Output Data Register	1.96	ns
t <sub>OPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Data Register	1.96	ns
t <sub>OREMCLR</sub>	Asynchronous Clear Removal Time for the Output Data Register	0.00	ns
t <sub>ORECCLR</sub>	Asynchronous Clear Recovery Time for the Output Data Register	0.24	ns
t <sub>OREMPRE</sub>	Asynchronous Preset Removal Time for the Output Data Register	0.00	ns
t <sub>ORECPRE</sub>	Asynchronous Preset Recovery Time for the Output Data Register	0.24	ns
t <sub>OWCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Output Data Register	0.19	ns
t <sub>OWPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Output Data Register	0.19	ns
t <sub>OCKMPWH</sub>	Clock Minimum Pulse Width HIGH for the Output Data Register	0.31	ns
t <sub>OCKMPWL</sub>	Clock Minimum Pulse Width LOW for the Output Data Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



# **Output Enable Register**

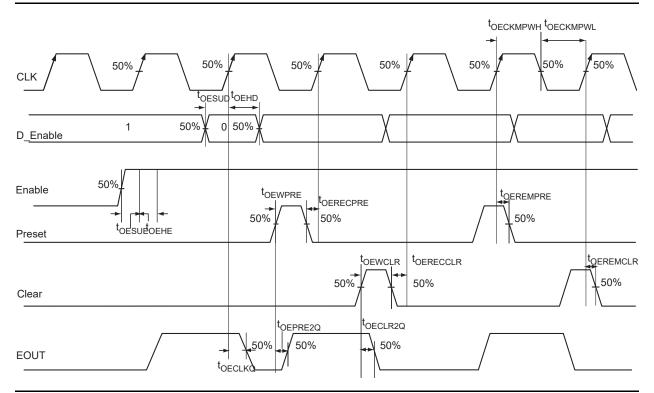


Figure 2-30 • Output Enable Register Timing Diagram

## **Timing Characteristics**

1.5 V DC Core Voltage

Table 2-127 • Output Enable Register Propagation Delays
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t <sub>OECLKQ</sub>	Clock-to-Q of the Output Enable Register	0.75	ns
t <sub>OESUD</sub>	Data Setup Time for the Output Enable Register	0.51	ns
t <sub>OEHD</sub>	Data Hold Time for the Output Enable Register	0.00	ns
t <sub>OESUE</sub>	Enable Setup Time for the Output Enable Register	0.73	ns
t <sub>OEHE</sub>	Enable Hold Time for the Output Enable Register	0.00	ns
t <sub>OECLR2Q</sub>	Asynchronous Clear-to-Q of the Output Enable Register	1.13	ns
t <sub>OEPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Enable Register	1.13	ns
t <sub>OEREMCLR</sub>	Asynchronous Clear Removal Time for the Output Enable Register	0.00	ns
toerecclr	Asynchronous Clear Recovery Time for the Output Enable Register	0.24	ns
t <sub>OEREMPRE</sub>	Asynchronous Preset Removal Time for the Output Enable Register	0.00	ns
t <sub>OERECPRE</sub>	Asynchronous Preset Recovery Time for the Output Enable Register	0.24	ns
t <sub>OEWCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Output Enable Register	0.19	ns
t <sub>OEWPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Output Enable Register	0.19	ns
t <sub>OECKMPWH</sub>	Clock Minimum Pulse Width HIGH for the Output Enable Register	0.31	ns
t <sub>OECKMPWL</sub>	Clock Minimum Pulse Width LOW for the Output Enable Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## 1.2 V DC Core Voltage

Table 2-128 • Output Enable Register Propagation Delays Commercial-Case Conditions:  $T_J = 70^{\circ}\text{C}$ , Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t <sub>OECLKQ</sub>	Clock-to-Q of the Output Enable Register	1.10	ns
t <sub>OESUD</sub>	Data Setup Time for the Output Enable Register	1.15	ns
t <sub>OEHD</sub>	Data Hold Time for the Output Enable Register	0.00	ns
t <sub>OESUE</sub>	Enable Setup Time for the Output Enable Register	1.22	ns
t <sub>OEHE</sub>	Enable Hold Time for the Output Enable Register	0.00	ns
t <sub>OECLR2Q</sub>	Asynchronous Clear-to-Q of the Output Enable Register	1.65	ns
t <sub>OEPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Enable Register	1.65	ns
t <sub>OEREMCLR</sub>	Asynchronous Clear Removal Time for the Output Enable Register	0.00	ns
t <sub>OERECCLR</sub>	Asynchronous Clear Recovery Time for the Output Enable Register	0.24	ns
t <sub>OEREMPRE</sub>	Asynchronous Preset Removal Time for the Output Enable Register	0.00	ns
t <sub>OERECPRE</sub>	Asynchronous Preset Recovery Time for the Output Enable Register	0.24	ns
t <sub>OEWCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Output Enable Register	0.19	ns
t <sub>OEWPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Output Enable Register	0.19	ns
t <sub>OECKMPWH</sub>	Clock Minimum Pulse Width HIGH for the Output Enable Register	0.31	ns
t <sub>OECKMPWL</sub>	Clock Minimum Pulse Width LOW for the Output Enable Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



# **DDR Module Specifications**

# Input DDR Module

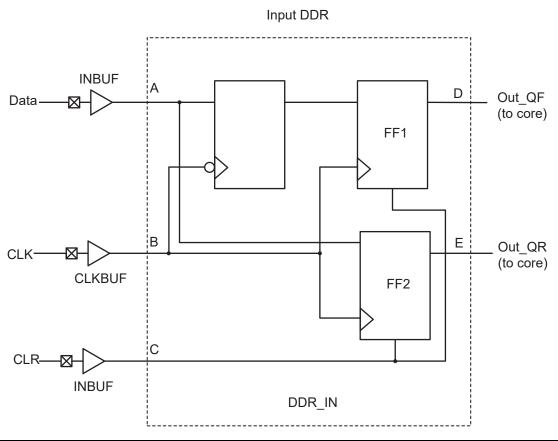


Figure 2-31 • Input DDR Timing Model

Table 2-129 • Parameter Definitions

Parameter Name	Parameter Definition	Measuring Nodes (from, to)
t <sub>DDRICLKQ1</sub>	Clock-to-Out Out_QR	B, D
t <sub>DDRICLKQ2</sub>	Clock-to-Out Out_QF	B, E
t <sub>DDRISUD</sub>	Data Setup Time of DDR input	A, B
t <sub>DDRIHD</sub>	Data Hold Time of DDR input	A, B
t <sub>DDRICLR2Q1</sub>	Clear-to-Out Out_QR	C, D
t <sub>DDRICLR2Q2</sub>	Clear-to-Out Out_QF	C, E
t <sub>DDRIREMCLR</sub>	Clear Removal	C, B
t <sub>DDRIRECCLR</sub>	Clear Recovery	C, B



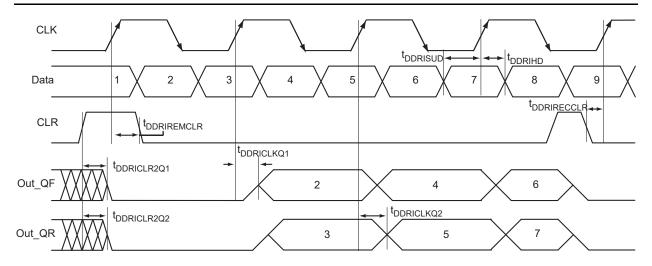


Figure 2-32 • Input DDR Timing Diagram

## **Timing Characteristics**

1.5 V DC Core Voltage

Table 2-130 • Input DDR Propagation Delays

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t <sub>DDRICLKQ1</sub>	Clock-to-Out Out_QR for Input DDR	0.48	ns
t <sub>DDRICLKQ2</sub>	Clock-to-Out Out_QF for Input DDR	0.65	ns
t <sub>DDRISUD1</sub>	Data Setup for Input DDR (negedge)	0.50	ns
t <sub>DDRISUD2</sub>	Data Setup for Input DDR (posedge)	0.40	ns
t <sub>DDRIHD1</sub>	Data Hold for Input DDR (negedge)	0.00	ns
t <sub>DDRIHD2</sub>	Data Hold for Input DDR (posedge)	0.00	ns
t <sub>DDRICLR2Q1</sub>	Asynchronous Clear to Out Out_QR for Input DDR	0.82	ns
t <sub>DDRICLR2Q2</sub>	Asynchronous Clear-to-Out Out_QF for Input DDR	0.98	ns
t <sub>DDRIREMCLR</sub>	Asynchronous Clear Removal Time for Input DDR	0.00	ns
t <sub>DDRIRECCLR</sub>	Asynchronous Clear Recovery Time for Input DDR	0.23	ns
t <sub>DDRIWCLR</sub>	Asynchronous Clear Minimum Pulse Width for Input DDR	0.19	ns
t <sub>DDRICKMPWH</sub>	Clock Minimum Pulse Width HIGH for Input DDR	0.31	ns
t <sub>DDRICKMPWL</sub>	Clock Minimum Pulse Width LOW for Input DDR	0.28	ns
F <sub>DDRIMAX</sub>	Maximum Frequency for Input DDR	250.00	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## 1.2 V DC Core Voltage

Table 2-131 • Input DDR Propagation Delays
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t <sub>DDRICLKQ1</sub>	Clock-to-Out Out_QR for Input DDR	0.76	ns
t <sub>DDRICLKQ2</sub>	Clock-to-Out Out_QF for Input DDR	0.94	ns
t <sub>DDRISUD1</sub>	Data Setup for Input DDR (negedge)	0.93	ns
t <sub>DDRISUD2</sub>	Data Setup for Input DDR (posedge)	0.84	ns
t <sub>DDRIHD1</sub>	Data Hold for Input DDR (negedge)	0.00	ns
t <sub>DDRIHD2</sub>	Data Hold for Input DDR (posedge)	0.00	ns
t <sub>DDRICLR2Q1</sub>	Asynchronous Clear to Out Out_QR for Input DDR	1.23	ns
t <sub>DDRICLR2Q2</sub>	Asynchronous Clear-to-Out Out_QF for Input DDR	1.42	ns
t <sub>DDRIREMCLR</sub>	Asynchronous Clear Removal Time for Input DDR	0.00	ns
t <sub>DDRIRECCLR</sub>	Asynchronous Clear Recovery Time for Input DDR	0.24	ns
t <sub>DDRIWCLR</sub>	Asynchronous Clear Minimum Pulse Width for Input DDR	0.19	ns
t <sub>DDRICKMPWH</sub>	Clock Minimum Pulse Width HIGH for Input DDR	0.31	ns
t <sub>DDRICKMPWL</sub>	Clock Minimum Pulse Width LOW for Input DDR	0.28	ns
F <sub>DDRIMAX</sub>	Maximum Frequency for Input DDR	160.00	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



# **Output DDR Module**

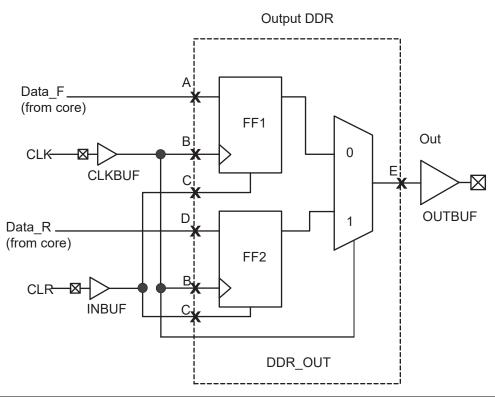


Figure 2-33 • Output DDR Timing Model

Table 2-132 • Parameter Definitions

Parameter Name	Parameter Definition	Measuring Nodes (from, to)
t <sub>DDROCLKQ</sub>	Clock-to-Out	B, E
t <sub>DDROCLR2Q</sub>	Asynchronous Clear-to-Out	C, E
t <sub>DDROREMCLR</sub>	Clear Removal	C, B
t <sub>DDRORECCLR</sub>	Clear Recovery	C, B
t <sub>DDROSUD1</sub>	Data Setup Data_F	A, B
t <sub>DDROSUD2</sub>	Data Setup Data_R	D, B
t <sub>DDROHD1</sub>	Data Hold Data_F	A, B
t <sub>DDROHD2</sub>	Data Hold Data_R	D, B



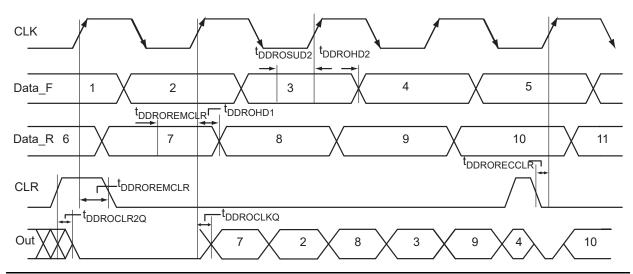


Figure 2-34 • Output DDR Timing Diagram



## **Timing Characteristics**

## 1.5 V DC Core Voltage

Table 2-133 • Output DDR Propagation Delays
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t <sub>DDROCLKQ</sub>	Clock-to-Out of DDR for Output DDR	1.07	ns
t <sub>DDROSUD1</sub>	Data_F Data Setup for Output DDR	0.67	ns
t <sub>DDROSUD2</sub>	Data_R Data Setup for Output DDR	0.67	ns
t <sub>DDROHD1</sub>	Data_F Data Hold for Output DDR	0.00	ns
t <sub>DDROHD2</sub>	Data_R Data Hold for Output DDR	0.00	ns
t <sub>DDROCLR2Q</sub>	Asynchronous Clear-to-Out for Output DDR	1.38	ns
t <sub>DDROREMCLR</sub>	Asynchronous Clear Removal Time for Output DDR	0.00	ns
t <sub>DDRORECCLR</sub>	Asynchronous Clear Recovery Time for Output DDR	0.23	ns
t <sub>DDROWCLR1</sub>	Asynchronous Clear Minimum Pulse Width for Output DDR	0.19	ns
t <sub>DDROCKMPWH</sub>	Clock Minimum Pulse Width HIGH for the Output DDR	0.31	ns
t <sub>DDROCKMPWL</sub>	Clock Minimum Pulse Width LOW for the Output DDR	0.28	ns
F <sub>DDOMAX</sub>	Maximum Frequency for the Output DDR	250.00	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

## 1.2 V DC Core Voltage

Table 2-134 • Output DDR Propagation Delays
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t <sub>DDROCLKQ</sub>	Clock-to-Out of DDR for Output DDR	1.60	ns
t <sub>DDROSUD1</sub>	Data_F Data Setup for Output DDR	1.09	ns
t <sub>DDROSUD2</sub>	Data_R Data Setup for Output DDR	1.16	ns
t <sub>DDROHD1</sub>	Data_F Data Hold for Output DDR	0.00	ns
t <sub>DDROHD2</sub>	Data_R Data Hold for Output DDR	0.00	ns
t <sub>DDROCLR2Q</sub>	Asynchronous Clear-to-Out for Output DDR	1.99	ns
t <sub>DDROREMCLR</sub>	Asynchronous Clear Removal Time for Output DDR	0.00	ns
t <sub>DDRORECCLR</sub>	Asynchronous Clear Recovery Time for Output DDR	0.24	ns
t <sub>DDROWCLR1</sub>	Asynchronous Clear Minimum Pulse Width for Output DDR	0.19	ns
t <sub>DDROCKMPWH</sub>	Clock Minimum Pulse Width HIGH for the Output DDR	0.31	ns
t <sub>DDROCKMPWL</sub>	Clock Minimum Pulse Width LOW for the Output DDR	0.28	ns
F <sub>DDOMAX</sub>	Maximum Frequency for the Output DDR	160.00	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



# **VersaTile Characteristics**

# **VersaTile Specifications as a Combinatorial Module**

The IGLOOe library offers all combinations of LUT-3 combinatorial functions. In this section, timing characteristics are presented for a sample of the library. For more details, refer to the *IGLOO*, *Fusion*, and *ProASIC3 Macro Library Guide*.

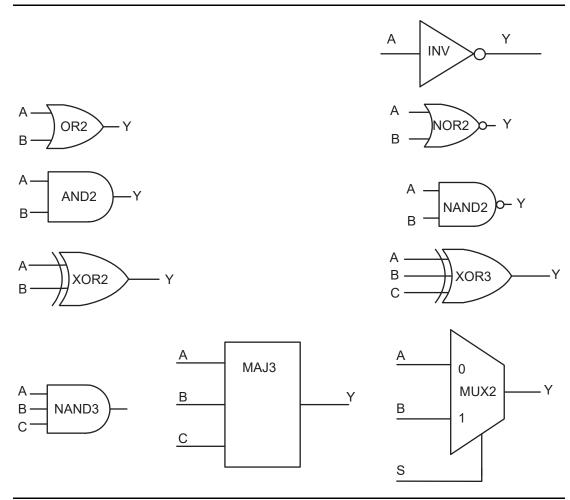


Figure 2-35 • Sample of Combinatorial Cells



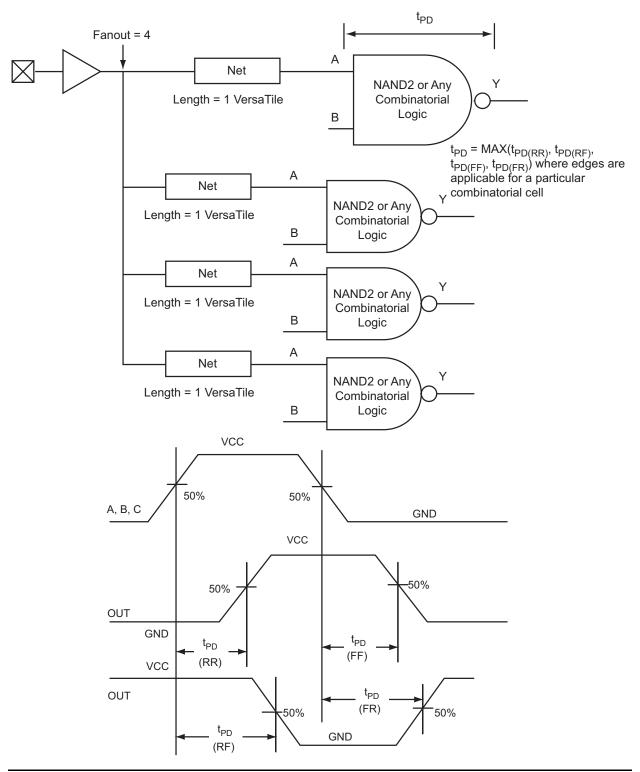


Figure 2-36 • Timing Model and Waveforms



# **Timing Characteristics**

## 1.5 V DC Core Voltage

Table 2-135 • Combinatorial Cell Propagation Delays

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Combinatorial Cell	Equation	Parameter	Std.	Units
INV	Y = !A	t <sub>PD</sub>	0.80	ns
AND2	Y = A · B	t <sub>PD</sub>	0.84	ns
NAND2	Y = !(A · B)	t <sub>PD</sub>	0.90	ns
OR2	Y = A + B	t <sub>PD</sub>	1.19	ns
NOR2	Y = !(A + B)	t <sub>PD</sub>	1.10	ns
XOR2	Y = A ⊕ B	t <sub>PD</sub>	1.37	ns
MAJ3	Y = MAJ(A, B, C)	t <sub>PD</sub>	1.33	ns
XOR3	$Y = A \oplus B \oplus C$	t <sub>PD</sub>	1.79	ns
MUX2	Y = A !S + B S	t <sub>PD</sub>	1.48	ns
AND3	Y = A · B · C	t <sub>PD</sub>	1.21	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

## 1.2 V DC Core Voltage

Table 2-136 • Combinatorial Cell Propagation Delays

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Combinatorial Cell	Equation	Parameter	Std.	Units
INV	Y = !A	t <sub>PD</sub>	1.35	ns
AND2	Y = A · B	t <sub>PD</sub>	1.42	ns
NAND2	Y = !(A · B)	t <sub>PD</sub>	1.58	ns
OR2	Y = A + B	t <sub>PD</sub>	2.10	ns
NOR2	Y = !(A + B)	t <sub>PD</sub>	1.94	ns
XOR2	Y = A ⊕ B	t <sub>PD</sub>	2.33	ns
MAJ3	Y = MAJ(A, B, C)	t <sub>PD</sub>	2.34	ns
XOR3	Y = A ⊕ B ⊕ C	t <sub>PD</sub>	3.05	ns
MUX2	Y = A !S + B S	t <sub>PD</sub>	2.64	ns
AND3	$Y = A \cdot B \cdot C$	t <sub>PD</sub>	2.10	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



## **VersaTile Specifications as a Sequential Module**

The IGLOOe library offers a wide variety of sequential cells, including flip-flops and latches. Each has a data input and optional enable, clear, or preset. In this section, timing characteristics are presented for a representative sample from the library. For more details, refer to the IGLOO, Fusion, and ProASIC3 Macro Library Guide.

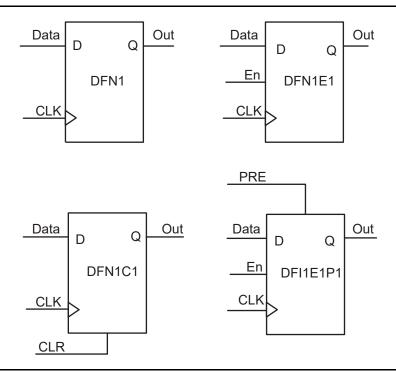


Figure 2-37 • Sample of Sequential Cells



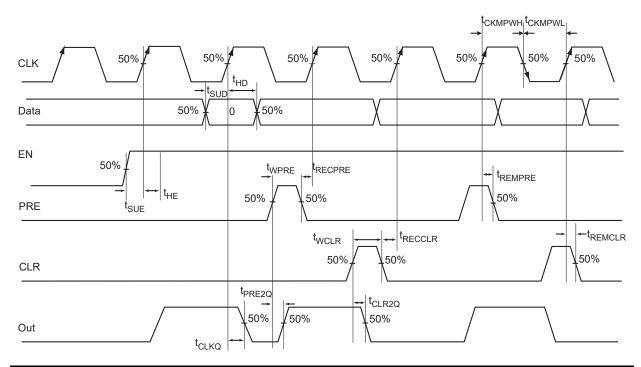


Figure 2-38 • Timing Model and Waveforms

## **Timing Characteristics**

1.5 V DC Core Voltage

Table 2-137 • Register Delays
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t <sub>CLKQ</sub>	Clock-to-Q of the Core Register	0.89	ns
t <sub>SUD</sub>	Data Setup Time for the Core Register	0.81	ns
t <sub>HD</sub>	Data Hold Time for the Core Register	0.00	ns
t <sub>SUE</sub>	Enable Setup Time for the Core Register	0.73	ns
t <sub>HE</sub>	Enable Hold Time for the Core Register	0.00	ns
t <sub>CLR2Q</sub>	Asynchronous Clear-to-Q of the Core Register	0.60	ns
t <sub>PRE2Q</sub>	Asynchronous Preset-to-Q of the Core Register	0.62	ns
t <sub>REMCLR</sub>	Asynchronous Clear Removal Time for the Core Register	0.00	ns
t <sub>RECCLR</sub>	Asynchronous Clear Recovery Time for the Core Register	0.24	ns
t <sub>REMPRE</sub>	Asynchronous Preset Removal Time for the Core Register	0.00	ns
t <sub>RECPRE</sub>	Asynchronous Preset Recovery Time for the Core Register	0.23	ns
t <sub>WCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Core Register	0.30	ns
t <sub>WPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Core Register	0.30	ns
t <sub>CKMPWH</sub>	Clock Minimum Pulse Width HIGH for the Core Register	0.56	ns
t <sub>CKMPWL</sub>	Clock Minimum Pulse Width LOW for the Core Register	0.56	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## 1.2 V DC Core Voltage

Table 2-138 • Register Delays

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t <sub>CLKQ</sub>	Clock-to-Q of the Core Register	1.61	ns
t <sub>SUD</sub>	Data Setup Time for the Core Register	1.17	ns
$t_{HD}$	Data Hold Time for the Core Register	0.00	ns
t <sub>SUE</sub>	Enable Setup Time for the Core Register	1.29	ns
t <sub>HE</sub>	Enable Hold Time for the Core Register	0.00	ns
t <sub>CLR2Q</sub>	Asynchronous Clear-to-Q of the Core Register	0.87	ns
t <sub>PRE2Q</sub>	Asynchronous Preset-to-Q of the Core Register	0.89	ns
t <sub>REMCLR</sub>	Asynchronous Clear Removal Time for the Core Register	0.00	ns
t <sub>RECCLR</sub>	Asynchronous Clear Recovery Time for the Core Register	0.24	ns
t <sub>REMPRE</sub>	Asynchronous Preset Removal Time for the Core Register	0.00	ns
t <sub>RECPRE</sub>	Asynchronous Preset Recovery Time for the Core Register	0.24	ns
t <sub>WCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Core Register	0.46	ns
t <sub>WPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Core Register	0.46	ns
t <sub>CKMPWH</sub>	Clock Minimum Pulse Width HIGH for the Core Register	0.95	ns
t <sub>CKMPWL</sub>	Clock Minimum Pulse Width LOW for the Core Register	0.95	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



# **Global Resource Characteristics**

# **AGLE600 Clock Tree Topology**

Clock delays are device-specific. Figure 2-39 is an example of a global tree used for clock routing. The global tree presented in Figure 2-39 is driven by a CCC located on the west side of the AGLE600 device. It is used to drive all D-flip-flops in the device.

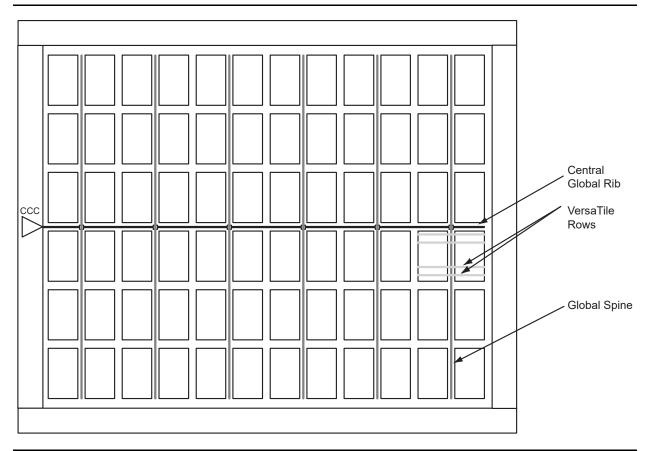


Figure 2-39 • Example of Global Tree Use in an AGLE600 Device for Clock Routing



## **Global Tree Timing Characteristics**

Global clock delays include the central rib delay, the spine delay, and the row delay. Delays do not include I/O input buffer clock delays, as these are I/O standard–dependent, and the clock may be driven and conditioned internally by the CCC module. For more details on clock conditioning capabilities, refer to the "Clock Conditioning Circuits" section on page 2-91. Table 2-139 and Table 2-141 present minimum and maximum global clock delays within the device. Minimum and maximum delays are measured with minimum and maximum loading.

#### **Timing Characteristics**

#### 1.5 V DC Core Voltage

Table 2-139 • AGLE600 Global Resource

Commercial-Case Conditions: T<sub>.I</sub> = 70°C, VCC = 1.425 V

			Std.	
Parameter	Description	Min. <sup>1</sup>	Max. <sup>2</sup>	Units
t <sub>RCKL</sub>	Input Low Delay for Global Clock	1.48	1.82	ns
t <sub>RCKH</sub>	Input High Delay for Global Clock	1.52	1.94	ns
t <sub>RCKMPWH</sub>	Minimum Pulse Width High for Global Clock	1.18		ns
t <sub>RCKMPWL</sub>	Minimum Pulse Width Low for Global Clock	1.15		ns
t <sub>RCKSW</sub>	Maximum Skew for Global Clock		0.42	ns

#### Notes:

- Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-140 • AGLE3000 Global Resource
Commercial-Case Conditions: T<sub>.I</sub> = 70°C, VCC = 1.425 V

		Std.		
Parameter	Description	Min. <sup>1</sup>	Max. <sup>2</sup>	Units
t <sub>RCKL</sub>	Input Low Delay for Global Clock	2.00	2.34	ns
t <sub>RCKH</sub>	Input High Delay for Global Clock	2.09	2.51	ns
t <sub>RCKMPWH</sub>	Minimum Pulse Width High for Global Clock	1.18		ns
t <sub>RCKMPWL</sub>	Minimum Pulse Width Low for Global Clock	1.15		ns
t <sub>RCKSW</sub>	Maximum Skew for Global Clock		0.42	ns

#### Notes:

- Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



#### 1.2 V DC Core Voltage

Table 2-141 • AGLE600 Global Resource

Commercial-Case Conditions: T<sub>J</sub> = 70°C, VCC = 1.14 V

			Std.	
Parameter	Description	Min. <sup>1</sup>	Max. <sup>2</sup>	Units
t <sub>RCKL</sub>	Input Low Delay for Global Clock	2.22	2.67	ns
t <sub>RCKH</sub>	Input High Delay for Global Clock	2.32	2.93	ns
t <sub>RCKMPWH</sub>	Minimum Pulse Width HIGH for Global Clock	1.40		ns
t <sub>RCKMPWL</sub>	Minimum Pulse Width LOW for Global Clock	1.65		ns
t <sub>RCKSW</sub>	Maximum Skew for Global Clock		0.61	ns

#### Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.

Table 2-142 • AGLE3000 Global Resource Commercial-Case Conditions: T<sub>J</sub> = 70°C, VCC = 1.14 V

			Std.		
Parameter	Description	Mir	1. <sup>1</sup>	Max. <sup>2</sup>	Units
t <sub>RCKL</sub>	Input Low Delay for Global Clock	2.8	33	3.27	ns
t <sub>RCKH</sub>	Input High Delay for Global Clock	3.0	00	3.61	ns
t <sub>RCKMPWH</sub>	Minimum Pulse Width HIGH for Global Clock	1.4	10		ns
t <sub>RCKMPWL</sub>	Minimum Pulse Width LOW for Global Clock	1.0	35		ns
t <sub>RCKSW</sub>	Maximum Skew for Global Clock			0.61	ns

#### Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.



# **Clock Conditioning Circuits**

## **CCC Electrical Specifications**

**Timing Characteristics** 

Table 2-143 • IGLOOe CCC/PLL Specification
For IGLOOe V2 or V5 Devices, 1.5 V DC Core Supply Voltage

Min.	Тур.	Max.	Units
1.5		250	MHz
0.75		250	MHz
		100	MHz
	360 <sup>4</sup>		ps
		32	ns
		1	
Max	Peak-to-Pea	ak Period Jitte	er
1 Global Network Used	External FB Used	3 Global Networks Used	
0.50%	0.75%	0.70%	
1.00%	1.50%	1.20%	
2.50%	3.75%	2.75%	
		300	μs
		6.0	ms
		2.5	ns
		1.5	ns
48.5		51.5	%
1.25		15.65	ns
0.469		15.65	ns
	3.5		ns
	1.5 0.75 Max 1 Global Network Used 0.50% 1.00% 2.50%	1.5 0.75  360 <sup>4</sup> Max Peak-to-Peat 1 Global Network Used 0.50% 1.00% 1.50% 2.50% 3.75%  48.5 1.25 0.469	1.5   250   100   360 <sup>4</sup>   32   1   1   1   1   1   1   1   1   1

#### Notes:

- 1. Maximum value obtained for a Std. speed grade device in Worst Case Commercial Conditions. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.
- 2. This delay is a function of voltage and temperature. See Table 2-6 on page 2-6 and Table 2-7 on page 2-6 for deratings.
- 3.  $T_J = 25^{\circ}C$ , VCC = 1.5 V
- 4. When the CCC/PLL core is generated by Microsemi core generator software, not all delay values of the specified delay increments are available. Refer to the Libero SoC Online Help associated with the core for more information.
- 5. Tracking jitter is defined as the variation in clock edge position of PLL outputs with reference to the PLL input clock edge. Tracking jitter does not measure the variation in PLL output period, which is covered by the period jitter parameter.
- 6. For definitions of Type 1 and Type 2, refer to the PLL Block Diagram in the "Clock Conditioning Circuits in IGLOO and ProASIC3 Devices" chapter of the IGLOOe FPGA Fabric User's Guide.



Table 2-144 • IGLOOe CCC/PLL Specification
For IGLOOe V2 Devices, 1.2 V DC Core Supply Voltage

Parameter	Min.	Тур.	Max.	Units
Clock Conditioning Circuitry Input Frequency f <sub>IN_CCC</sub>	1.5		160	MHz
Clock Conditioning Circuitry Output Frequency f <sub>OUT_CCC</sub>	0.75		160	MHz
Serial Clock (SCLK) for Dynamic PLL <sup>1</sup>			60	MHz
Delay Increments in Programmable Delay Blocks <sup>2, 3</sup>		580 <sup>4</sup>		ps
Number of Programmable Values in Each Programmable Delay Block			32	
Input Cycle-to-Cycle Jitter (peak magnitude)			0.25	ns
CCC Output Peak-to-Peak Period Jitter F <sub>CCC_OUT</sub> <sup>5</sup>	Мах	Peak-to-Pe	ak Period Jitt	er
	1 Global Network Used	External FB Used	3 Global Networks Used	
0.75 MHz to 24 MHz	0.50%	0.75%	0.70%	
24 MHz to 100 MHz	1.00%	1.50%	1.20%	
100 MHz to 160 MHz	2.50%	3.75%	2.75%	
Acquisition Time				
LockControl = 0			300	μs
LockControl = 1			6.0	ms
Tracking Jitter <sup>6</sup>				
LockControl = 0			4	ns
LockControl = 1			3	ns
Output Duty Cycle	48.5		51.5	%
Delay Range in Block: Programmable Delay 1 <sup>2, 3, 7</sup>	2.3		20.86	ns
Delay Range in Block: Programmable Delay 2 <sup>2, 3, 7</sup>	0.863		20.86	ns
Delay Range in Block: Fixed Delay <sup>2, 3</sup>		5.7		ns

#### Notes:

- 1. Maximum value obtained for a Std. speed grade device in Worst Case Commercial Conditions. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.
- 2. This delay is a function of voltage and temperature. See Table 2-6 on page 2-6 and Table 2-7 on page 2-6 for deratings.
- 3.  $T_{.J} = 25^{\circ}C$ , VCC = 1.5 V
- 4. When the CCC/PLL core is generated by Microsemi core generator software, not all delay values of the specified delay increments are available. Refer to the Libero SoC Online Help associated with the core for more information.
- 5. VCO output jitter is calculated as a percentage of the VCO frequency. The jitter (in ps) can be calculated by multiplying the VCO period by the per cent jitter. The VCO jitter (in ps) applies to CCC\_OUT regardless of the output divider settings. For example, if the jitter on VCO is 300 ps, the jitter on CCC\_OUT is also 300 ps, regardless of the output divider settings.
- 6. Tracking jitter is defined as the variation in clock edge position of PLL outputs with reference to PLL input clock edge. Tracking jitter does not measure the variation in PLL output period, which is covered by period jitter parameter.
- 7. For definitions of Type 1 and Type 2, refer to the PLL Block Diagram in the "Clock Conditioning Circuits in IGLOO and ProASIC3 Devices" chapter of the IGLOOe FPGA Fabric User's Guide.



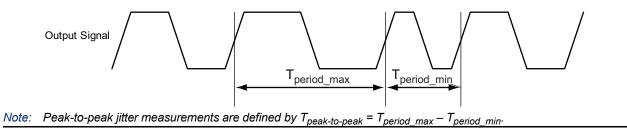


Figure 2-40 • Peak-to-Peak Jitter Definition



# **Embedded SRAM and FIFO Characteristics**

# **SRAM**

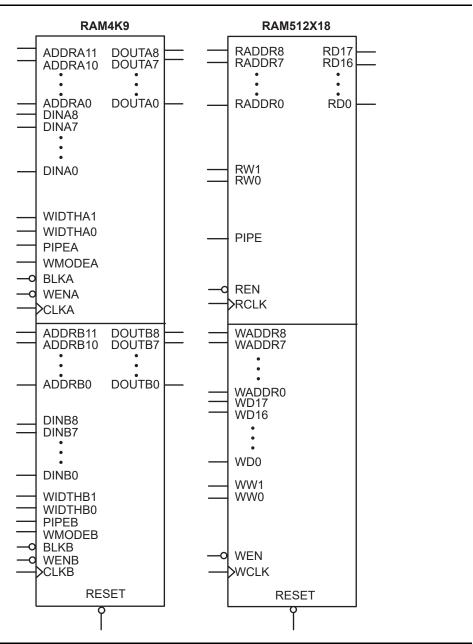


Figure 2-41 • RAM Models



## **Timing Waveforms**

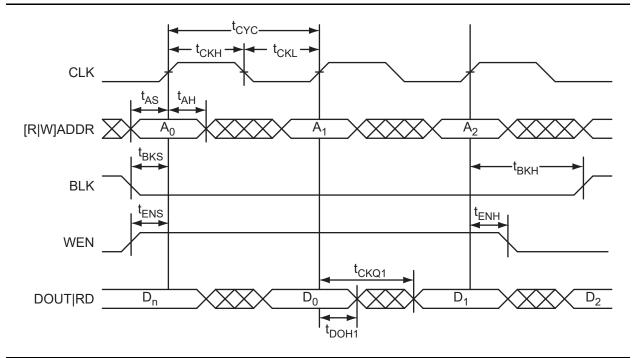


Figure 2-42 • RAM Read for Pass-Through Output. Applicable to Both RAM4K9 and RAM512X18.

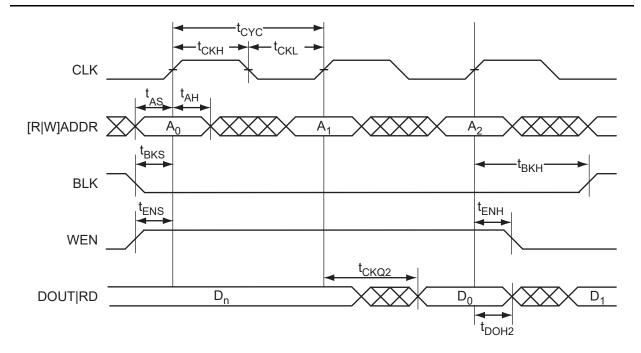


Figure 2-43 • RAM Read for Pipelined Output. Applicable to Both RAM4K9 and RAM512X18.



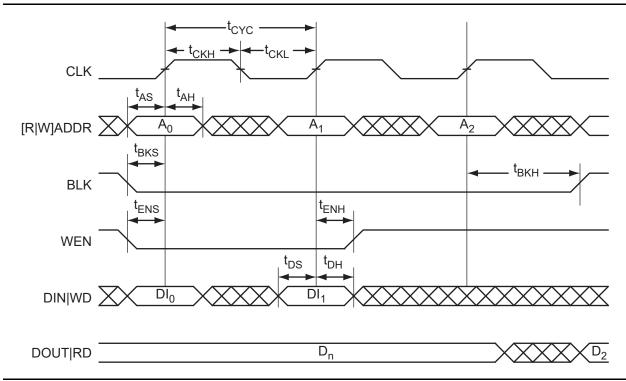


Figure 2-44 • RAM Write, Output Retained. Applicable to both RAM4K9 and RAM512X18.

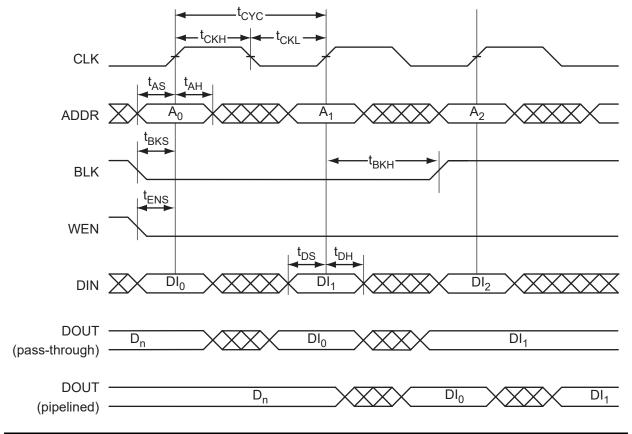


Figure 2-45 • RAM Write, Output as Write Data (WMODE = 1). Applicable to RAM4K9 Only.



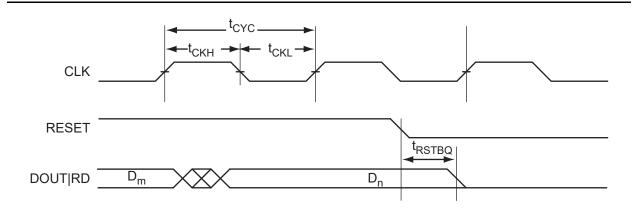


Figure 2-46 • RAM Reset



## **Timing Characteristics**

Applies to 1.5 V DC Core Voltage

Table 2-145 • RAM4K9

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t <sub>AS</sub>	Address Setup Time	0.83	ns
t <sub>AH</sub>	Address Hold Time	0.16	ns
t <sub>ENS</sub>	REN, WEN Setup Time	0.81	ns
t <sub>ENH</sub>	REN, WEN Hold Time	0.16	ns
t <sub>BKS</sub>	BLK Setup Time	1.65	ns
t <sub>BKH</sub>	BLK Hold Time	0.16	ns
t <sub>DS</sub>	Input Data (DIN) Setup Time	0.71	ns
t <sub>DH</sub>	Input Data (DIN) Hold Time	0.36	ns
t <sub>CKQ1</sub>	Clock HIGH to New Data Valid on DOUT (output retained, WMODE = 0)	3.53	ns
	Clock HIGH to New Data Valid on DOUT (flow-through, WMODE = 1)	3.06	ns
t <sub>CKQ2</sub>	Clock HIGH to New Data Valid on DOUT (pipelined)	1.81	ns
t <sub>C2CWWL</sub> 1	Address collision clk-to-clk delay for reliable write after write on same address; applicable to closing edge	0.23	ns
t <sub>C2CRWH</sub> 1	Address collision clk-to-clk delay for reliable read access after write on same address; applicable to opening edge	0.35	ns
t <sub>C2CWRH</sub> <sup>1</sup>	Address collision clk-to-clk delay for reliable write access after read on same address; applicable to opening edge	0.41	ns
t <sub>RSTBQ</sub>	RESET Low to Data Out Low on DOUT (flow-through)	2.06	ns
	RESET Low to Data Out Low on DOUT (pipelined)	2.06	ns
t <sub>REMRSTB</sub>	RESET Removal	0.61	ns
t <sub>RECRSTB</sub>	RESET Recovery	3.21	ns
t <sub>MPWRSTB</sub>	RESET Minimum Pulse Width	0.68	ns
t <sub>CYC</sub>	Clock Cycle Time	6.24	ns
F <sub>MAX</sub>	Maximum Frequency	160	MHz

#### Notes:

- For more information, refer to the application note Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



Table 2-146 • RAM512X18 Commercial-Case Conditions:  $T_J = 70^{\circ}$ C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t <sub>AS</sub>	Address Setup Time	0.83	ns
t <sub>AH</sub>	Address Hold Time	0.16	ns
t <sub>ENS</sub>	REN, WEN Setup Time	0.73	ns
t <sub>ENH</sub>	REN, WEN Hold Time	0.08	ns
t <sub>DS</sub>	Input Data (WD) Setup Time	0.71	ns
t <sub>DH</sub>	Input Data (WD) Hold Time	0.36	ns
t <sub>CKQ1</sub>	Clock HIGH to New Data Valid on RD (output retained, WMODE = 0)	4.21	ns
t <sub>CKQ2</sub>	Clock HIGH to New Data Valid on RD (pipelined)	1.71	ns
t <sub>C2CRWH</sub> 1	Address collision clk-to-clk delay for reliable read access after write on same address; applicable to opening edge	0.35	ns
t <sub>C2CWRH</sub> 1	Address collision clk-to-clk delay for reliable write access after read on same address; applicable to opening edge	0.42	ns
t <sub>RSTBQ</sub>	RESET Low to Data Out Low on RD (flow-through)	2.06	ns
	RESET Low to Data Out Low on RD (pipelined)	2.06	ns
t <sub>REMRSTB</sub>	RESET Removal	0.61	ns
t <sub>RECRSTB</sub>	RESET Recovery	3.21	ns
t <sub>MPWRSTB</sub>	RESET Minimum Pulse Width	0.68	ns
t <sub>CYC</sub>	Clock Cycle Time	6.24	ns
F <sub>MAX</sub>	Maximum Frequency	160	MHz

#### Notes:

- 1. For more information, refer to the application note Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



### Applies to 1.2 V DC Core Voltage

Table 2-147 • RAM4K9

Commercial-Case Conditions:  $T_J = 70$ °C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t <sub>AS</sub>	Address Setup Time	1.53	ns
t <sub>AH</sub>	Address Hold Time	0.29	ns
t <sub>ENS</sub>	REN, WEN Setup Time	1.50	ns
t <sub>ENH</sub>	REN, WEN Hold Time	0.29	ns
t <sub>BKS</sub>	BLK Setup Time	3.05	ns
t <sub>BKH</sub>	BLK Hold Time	0.29	ns
t <sub>DS</sub>	Input Data (DIN) Setup Time	1.33	ns
t <sub>DH</sub>	Input Data (DIN) Hold Time	0.66	ns
t <sub>CKQ1</sub>	Clock High to New Data Valid on DOUT (output retained, WMODE = 0)	6.61	ns
	Clock High to New Data Valid on DOUT (flow-through, WMODE = 1)	5.72	ns
t <sub>CKQ2</sub>	Clock High to New Data Valid on DOUT (pipelined)	3.38	ns
t <sub>C2CWWL</sub> 1	Address collision clk-to-clk delay for reliable write after write on same address; applicable to closing edge	0.30	ns
t <sub>C2CRWH</sub> 1	Address collision clk-to-clk delay for reliable read access after write on same address; applicable to opening edge		ns
t <sub>C2CWRH</sub> 1	Address collision clk-to-clk delay for reliable write access after read on same address; applicable to opening edge	1.01	ns
t <sub>RSTBQ</sub>	RESET Low to Data Out Low on DOUT (pass-through)	3.86	ns
	RESET Low to Data Out Low on DOUT (pipelined)	3.86	ns
t <sub>REMRSTB</sub>	RESET Removal	1.12	ns
t <sub>RECRSTB</sub>	RESET Recovery	5.93	ns
t <sub>MPWRSTB</sub>	RESET Minimum Pulse Width	1.18	ns
t <sub>CYC</sub>	Clock Cycle Time	10.90	ns
F <sub>MAX</sub>	Maximum Frequency	92	MHz

#### Notes:

2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

For more information, refer to the application note Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs.



Table 2-148 • RAM512X18 Commercial-Case Conditions:  $T_J = 70^{\circ}$ C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t <sub>AS</sub>	Address Setup Time	1.53	ns
t <sub>AH</sub>	Address Hold Time	0.29	ns
t <sub>ENS</sub>	REN, WEN Setup Time	1.36	ns
t <sub>ENH</sub>	REN, WEN Hold Time	0.15	ns
t <sub>DS</sub>	Input Data (WD) Setup Time	1.33	ns
t <sub>DH</sub>	Input Data (WD) Hold Time	0.66	ns
t <sub>CKQ1</sub>	Clock High to New Data Valid on RD (output retained)	7.88	ns
t <sub>CKQ2</sub>	Clock High to New Data Valid on RD (pipelined)	3.20	ns
t <sub>C2CRWH</sub> 1	Address collision clk-to-clk delay for reliable read access after write on same address; applicable to opening edge	0.87	ns
t <sub>C2CWRH</sub> 1	Address collision clk-to-clk delay for reliable write access after read on same address; applicable to opening edge	1.04	ns
t <sub>RSTBQ</sub>	RESET Low to Data Out Low on RD (flow-through)	3.86	ns
	RESET Low to Data Out Low on RD (pipelined)	3.86	ns
t <sub>REMRSTB</sub>	RESET Removal	1.12	ns
t <sub>RECRSTB</sub>	RESET Recovery	5.93	ns
t <sub>MPWRSTB</sub>	RESET Minimum Pulse Width	1.18	ns
t <sub>CYC</sub>	Clock Cycle Time	10.90	ns
F <sub>MAX</sub>	Maximum Frequency	92	MHz

#### Notes:

- 1. For more information, refer to the application note Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## **FIFO**

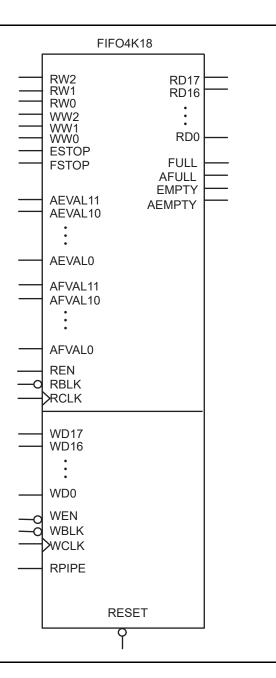


Figure 2-47 • FIFO Model



## **Timing Waveforms**

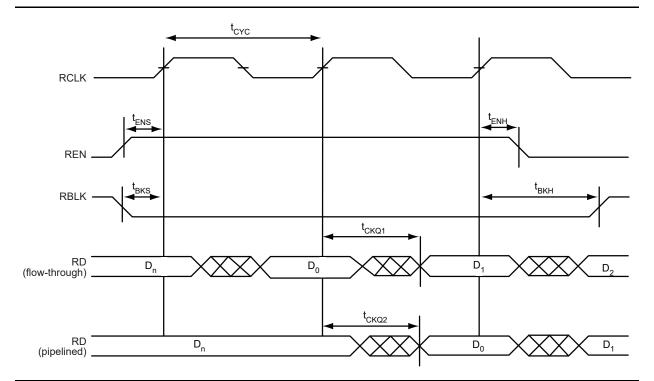


Figure 2-48 • FIFO Read

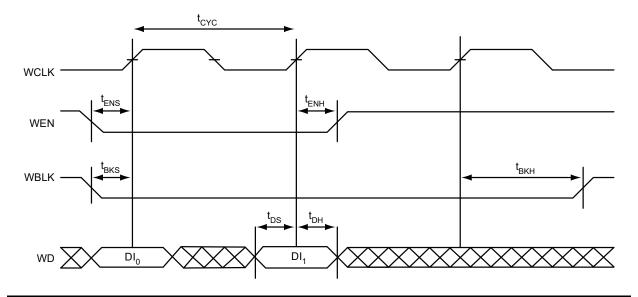


Figure 2-49 • FIFO Write



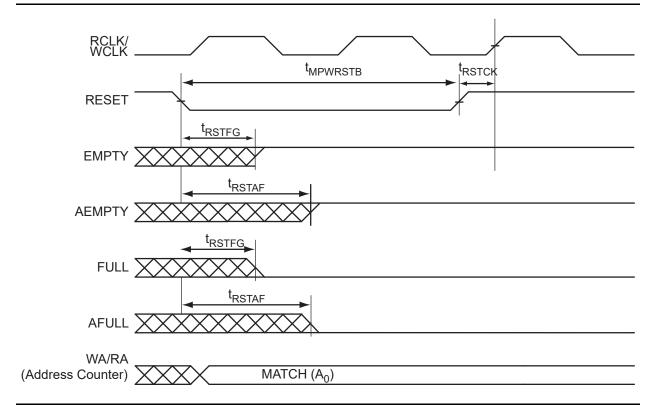


Figure 2-50 • FIFO Reset

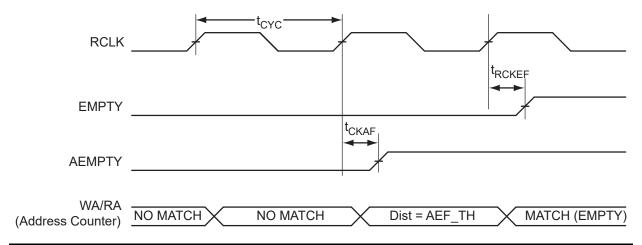


Figure 2-51 • FIFO EMPTY Flag and AEMPTY Flag Assertion



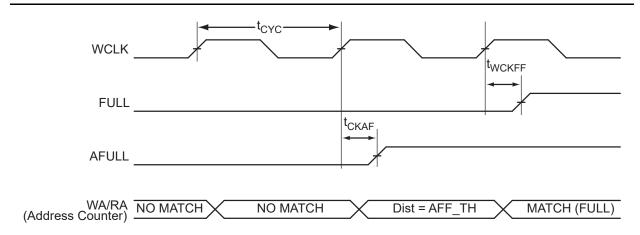


Figure 2-52 • FIFO FULL Flag and AFULL Flag Assertion

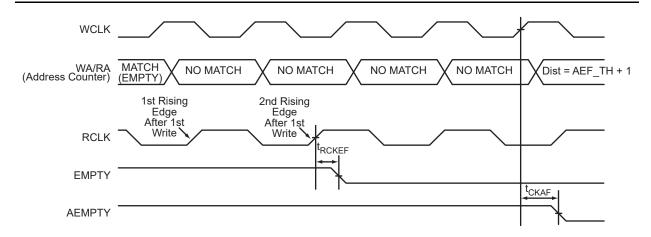


Figure 2-53 • FIFO EMPTY Flag and AEMPTY Flag Deassertion

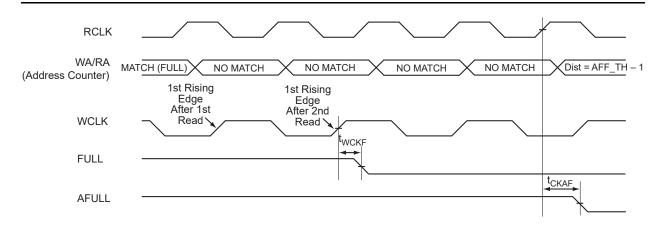


Figure 2-54 • FIFO FULL Flag and AFULL Flag Deassertion



## **Timing Characteristics**

Applies to 1.5 V DC Core Voltage

Table 2-149 • FIFO

Commercial-Case Conditions:  $T_J = 70$ °C, VCC = 1.425 V

Parameter	Description	Std.	Units
t <sub>ENS</sub>	REN, WEN Setup Time	1.99	ns
t <sub>ENH</sub>	REN, WEN Hold Time	0.16	ns
t <sub>BKS</sub>	BLK Setup Time	0.30	ns
t <sub>BKH</sub>	BLK Hold Time	0.00	ns
t <sub>DS</sub>	Input Data (WD) Setup Time	0.76	ns
t <sub>DH</sub>	Input Data (WD) Hold Time	0.25	ns
t <sub>CKQ1</sub>	Clock HIGH to New Data Valid on RD (pass-through)	3.33	ns
t <sub>CKQ2</sub>	Clock HIGH to New Data Valid on RD (pipelined)	1.80	ns
t <sub>RCKEF</sub>	RCLK HIGH to Empty Flag Valid	3.53	ns
t <sub>WCKFF</sub>	WCLK HIGH to Full Flag Valid	3.35	ns
t <sub>CKAF</sub>	Clock HIGH to Almost Empty/Full Flag Valid	12.85	ns
t <sub>RSTFG</sub>	RESET LOW to Empty/Full Flag Valid	3.48	ns
t <sub>RSTAF</sub>	RESET LOW to Almost Empty/Full Flag Valid	12.72	ns
t <sub>RSTBQ</sub>	RESET LOW to Data Out LOW on RD (pass-through)	2.02	ns
	RESET LOW to Data Out LOW on RD (pipelined)	2.02	ns
t <sub>REMRSTB</sub>	RESET Removal	0.61	ns
t <sub>RECRSTB</sub>	RESET Recovery	3.21	ns
t <sub>MPWRSTB</sub>	RESET Minimum Pulse Width	0.68	ns
t <sub>CYC</sub>	Clock Cycle Time	6.24	ns
F <sub>MAX</sub>	Maximum Frequency	160	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## Applies to 1.2 V DC Core Voltage

Table 2-150 • FIFO

Commercial-Case Conditions:  $T_J = 70$ °C, VCC = 1.14 V

Parameter	Description	Std.	Units
t <sub>ENS</sub>	REN, WEN Setup Time	4.13	ns
t <sub>ENH</sub>	REN, WEN Hold Time	0.31	ns
t <sub>BKS</sub>	BLK Setup Time	0.47	ns
t <sub>BKH</sub>	BLK Hold Time	0.00	ns
t <sub>DS</sub>	Input Data (WD) Setup Time	1.56	ns
t <sub>DH</sub>	Input Data (WD) Hold Time	0.49	ns
t <sub>CKQ1</sub>	Clock HIGH to New Data Valid on RD (pass-through)	6.80	ns
t <sub>CKQ2</sub>	Clock HIGH to New Data Valid on RD (pipelined)	3.62	ns
t <sub>RCKEF</sub>	RCLK HIGH to Empty Flag Valid	7.23	ns
t <sub>WCKFF</sub>	WCLK HIGH to Full Flag Valid	6.85	ns
t <sub>CKAF</sub>	Clock HIGH to Almost Empty/Full Flag Valid	26.61	ns
t <sub>RSTFG</sub>	RESET LOW to Empty/Full Flag Valid	7.12	ns
t <sub>RSTAF</sub>	RESET LOW to Almost Empty/Full Flag Valid	26.33	ns
t <sub>RSTBQ</sub>	RESET LOW to Data Out LOW on RD (pass-through)	4.09	ns
	RESET LOW to Data Out LOW on RD (pipelined)	4.09	ns
t <sub>REMRSTB</sub>	RESET Removal	1.23	ns
t <sub>RECRSTB</sub>	RESET Recovery	6.58	ns
t <sub>MPWRSTB</sub>	RESET Minimum Pulse Width	1.18	ns
t <sub>CYC</sub>	Clock Cycle Time	10.90	ns
F <sub>MAX</sub>	Maximum Frequency	92	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.

## **Embedded FlashROM Characteristics**

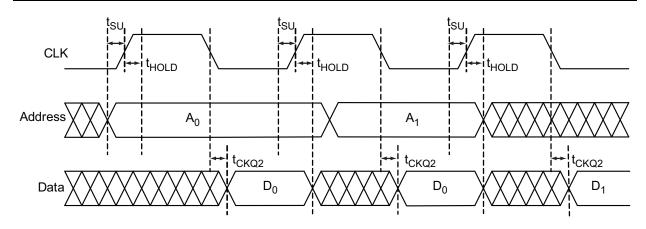


Figure 2-55 • Timing Diagram

## **Timing Characteristics**

Applies to 1.5 V DC Core Voltage

Table 2-151 • Embedded FlashROM Access Time Commercial-Case Conditions:  $T_J = 70$ °C, VCC = 1.425 V

Parameter	Description	Std.	Units
t <sub>SU</sub>	Address Setup Time	0.58	ns
t <sub>HOLD</sub>	Address Hold Time	0.00	ns
t <sub>CK2Q</sub>	Clock-to-Out	34.14	ns
F <sub>MAX</sub>	Maximum Clock Frequency	15	MHz

### Applies to 1.2 V DC Core Voltage

Table 2-152 • Embedded FlashROM Access Time Commercial-Case Conditions:  $T_J = 70^{\circ}C$ , VCC = 1.14 V

Parameter	Description	Std.	Units
t <sub>SU</sub>	Address Setup Time	0.59	ns
t <sub>HOLD</sub>	Address Hold Time	0.00	ns
t <sub>CK2Q</sub>	Clock-to-Out	52.90	ns
F <sub>MAX</sub>	Maximum Clock Frequency	10	MHz



## **JTAG 1532 Characteristics**

JTAG timing delays do not include JTAG I/Os. To obtain complete JTAG timing, add I/O buffer delays to the corresponding standard selected; refer to the I/O timing characteristics in the "User I/O Characteristics" section on page 2-16 for more details.

#### **Timing Characteristics**

Applies to 1.2 V DC Core Voltage

Table 2-153 • JTAG 1532

Commercial-Case Conditions: T<sub>J</sub> = 70°C, VCC = 1.14 V

Parameter	Description	Std.	Units
t <sub>DISU</sub>	Test Data Input Setup Time	1.50	ns
t <sub>DIHD</sub>	Test Data Input Hold Time	3.00	ns
t <sub>TMSSU</sub>	Test Mode Select Setup Time	1.50	ns
t <sub>TMDHD</sub>	Test Mode Select Hold Time	3.00	ns
t <sub>TCK2Q</sub>	Clock to Q (data out)	11.00	ns
t <sub>RSTB2Q</sub>	Reset to Q (data out)	30.00	ns
F <sub>TCKMAX</sub>	TCK Maximum Frequency	9.00	MHz
t <sub>TRSTREM</sub>	ResetB Removal Time	1.18	ns
t <sub>TRSTREC</sub>	ResetB Recovery Time	0.00	ns
t <sub>TRSTMPW</sub>	ResetB Minimum Pulse	TBD	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.

#### Applies to 1.5 V DC Core Voltage

Table 2-154 • JTAG 1532

Commercial-Case Conditions:  $T_J = 70$ °C, VCC = 1.425 V

Parameter	Description	Std.	Units
t <sub>DISU</sub>	Test Data Input Setup Time	1.00	ns
t <sub>DIHD</sub>	Test Data Input Hold Time	2.00	ns
t <sub>TMSSU</sub>	Test Mode Select Setup Time	1.00	ns
t <sub>TMDHD</sub>	Test Mode Select Hold Time	2.00	ns
t <sub>TCK2Q</sub>	Clock to Q (data out)	8.00	ns
t <sub>RSTB2Q</sub>	Reset to Q (data out)	25.00	ns
F <sub>TCKMAX</sub>	TCK Maximum Frequency	15.00	MHz
t <sub>TRSTREM</sub>	ResetB Removal Time	0.58	ns
t <sub>TRSTREC</sub>	ResetB Recovery Time	0.00	ns
t <sub>TRSTMPW</sub>	ResetB Minimum Pulse	TBD	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## 3 – Pin Descriptions and Packaging

## **Supply Pins**

#### GND Ground

Ground supply voltage to the core, I/O outputs, and I/O logic.

#### GNDQ Ground (quiet)

Quiet ground supply voltage to input buffers of I/O banks. Within the package, the GNDQ plane is decoupled from the simultaneous switching noise originated from the output buffer ground domain. This minimizes the noise transfer within the package and improves input signal integrity. GNDQ must always be connected to GND on the board.

#### VCC Core Supply Voltage

Supply voltage to the FPGA core, nominally 1.5 V for IGLOOe V5 devices, and 1.2 V or 1.5 V for IGLOOe V2 devices. VCC is required for powering the JTAG state machine in addition to VJTAG. Even when a device is in bypass mode in a JTAG chain of interconnected devices, both VCC and VJTAG must remain powered to allow JTAG signals to pass through the device.

For IGLOOe V2 devices, VCC can be switched dynamically from 1.2 V to 1.5 V or vice versa. This allows in-system programming (ISP) when VCC is at 1.5 V and the benefit of low power operation when VCC is at 1.2 V.

#### VCCIBx I/O Supply Voltage

Supply voltage to the bank's I/O output buffers and I/O logic. Bx is the I/O bank number. There are up to eight I/O banks on IGLOOe devices plus a dedicated VJTAG bank. Each bank can have a separate VCCI connection. All I/Os in a bank will run off the same VCCIBx supply. VCCI can be 1.2 V, 1.5 V, 1.8 V, 2.5 V, or 3.3 V, nominal voltage. Unused I/O banks should have their corresponding VCCI pins tied to GND.

#### VMVx I/O Supply Voltage (quiet)

Quiet supply voltage to the input buffers of each I/O bank. *x* is the bank number. Within the package, the VMV plane biases the input stage of the I/Os in the I/O banks. This minimizes the noise transfer within the package and improves input signal integrity. Each bank must have at least one VMV connection, and no VMV should be left unconnected. All I/Os in a bank run off the same VMVx supply. VMV is used to provide a quiet supply voltage to the input buffers of each I/O bank. VMVx can be 1.2 V, 1.5 V, 1.8 V, 2.5 V, or 3.3 V, nominal voltage. Unused I/O banks should have their corresponding VMV pins tied to GND. VMV and VCCI should be at the same voltage within a given I/O bank. Used VMV pins must be connected to the corresponding VCCI pins of the same bank (i.e., VMV0 to VCCIB0, VMV1 to VCCIB1, etc.).

#### VCCPLA/B/C/D/E/F PLL Supply Voltage

Supply voltage to analog PLL, nominally 1.5 V or 1.2 V, depending on the device.

- 1.5 V for IGLOOe devices
- 1.2 V or 1.5 V for IGLOOe V2 devices

When the PLLs are not used, the place-and-route tool automatically disables the unused PLLs to lower power consumption. The user should tie unused VCCPLx and VCOMPLx pins to ground. Microsemi recommends tying VCCPLx to VCC and using proper filtering circuits to decouple VCC noise from the PLLs. Refer to the PLL Power Supply Decoupling section in the "Clock Conditioning Circuits in Low Power Flash FPGAs and Mixed Signal FPGAs" chapter in the *IGLOOe FPGA Fabric User's Guide* for a complete board solution for the PLL analog power supply and ground.

There are six VCCPLX pins on IGLOOe devices.



#### VCOMPLA/B/C/D/E/F PLL Ground

Ground to analog PLL power supplies. When the PLLs are not used, the place-and-route tool automatically disables the unused PLLs to lower power consumption. The user should tie unused VCCPLx and VCOMPLx pins to ground.

There are six VCOMPL pins (PLL ground) on IGLOOe devices.

#### **VJTAG**

#### **JTAG Supply Voltage**

Low power flash devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). Isolating the JTAG power supply in a separate I/O bank gives greater flexibility in supply selection and simplifies power supply and PCB design. If the JTAG interface is neither used nor planned for use, the VJTAG pin together with the TRST pin could be tied to GND. It should be noted that VCC is required to be powered for JTAG operation; VJTAG alone is insufficient. If a device is in a JTAG chain of interconnected boards, the board containing the device can be powered down, provided both VJTAG and VCC to the part remain powered; otherwise, JTAG signals will not be able to transition the device, even in bypass mode.

Microsemi recommends that VPUMP and VJTAG power supplies be kept separate with independent filtering capacitors rather than supplying them from a common rail.

#### **VPUMP**

#### **Programming Supply Voltage**

IGLOOe devices support single-voltage ISP of the configuration flash and FlashROM. For programming, VPUMP should be 3.3 V nominal. During normal device operation, VPUMP can be left floating or can be tied (pulled up) to any voltage between 0 V and the VPUMP maximum. Programming power supply voltage (VPUMP) range is listed in the datasheet.

When the VPUMP pin is tied to ground, it will shut off the charge pump circuitry, resulting in no sources of oscillation from the charge pump circuitry.

For proper programming,  $0.01 \mu F$  and  $0.33 \mu F$  capacitors (both rated at 16 V) are to be connected in parallel across VPUMP and GND, and positioned as close to the FPGA pins as possible.

Microsemi recommends that VPUMP and VJTAG power supplies be kept separate with independent filtering capacitors rather than supplying them from a common rail.

## **User-Defined Supply Pins**

#### **VREF**

#### I/O Voltage Reference

Reference voltage for I/O minibanks. VREF pins are configured by the user from regular I/Os, and any I/O in a bank, except JTAG I/Os, can be designated the voltage reference I/O. Only certain I/O standards require a voltage reference—HSTL (I) and (II), SSTL2 (I) and (II), SSTL3 (I) and (II), and GTL/GTL+. One VREF pin can support the number of I/Os available in its minibank.



## **User Pins**

#### O User Input/Output

The I/O pin functions as an input, output, tristate, or bidirectional buffer. Input and output signal levels are compatible with the I/O standard selected.

During programming, I/Os become tristated and weakly pulled up to VCCI. With VCCI, VMV, and VCC supplies continuously powered up, when the device transitions from programming to operating mode, the I/Os are instantly configured to the desired user configuration.

Unused I/Os are configured as follows:

- · Output buffer is disabled (with tristate value of high impedance)
- Input buffer is disabled (with tristate value of high impedance)
- · Weak pull-up is programmed

#### GL Globals

GL I/Os have access to certain clock conditioning circuitry (and the PLL) and/or have direct access to the global network (spines). Additionally, the global I/Os can be used as regular I/Os, since they have identical capabilities. Unused GL pins are configured as inputs with pull-up resistors.

See more detailed descriptions of global I/O connectivity in the "Clock Conditioning Circuits in Low Power Flash Devices and Mixed Signal FPGAs" chapter of the IGLOOe FPGA Fabric User's Guide. All inputs labeled GC/GF are direct inputs into the quadrant clocks. For example, if GAA0 is used for an input, GAA1 and GAA2 are no longer available for input to the quadrant globals. All inputs labeled GC/GF are direct inputs into the chip-level globals, and the rest are connected to the quadrant globals. The inputs to the global network are multiplexed, and only one input can be used as a global input.

Refer to the I/O Structure section of the IGLOOe FPGA Fabric User's Guide for an explanation of the naming of global pins.

#### FF Flash\*Freeze Mode Activation Pin

Flash\*Freeze mode is available on IGLOOe devices. The FF pin is a dedicated input pin used to enter and exit Flash\*Freeze mode. The FF pin is active low, has the same characteristics as a single-ended I/O, and must meet the maximum rise and fall times. When Flash\*Freeze mode is not used in the design, the FF pin is available as a regular I/O. The FF pin can be configured as a Schmitt trigger input.

When Flash\*Freeze mode is used, the FF pin must not be left floating to avoid accidentally entering Flash\*Freeze mode. While in Flash\*Freeze mode, the Flash\*Freeze pin should be constantly asserted.

The Flash\*Freeze pin can be used with any single-ended I/O standard supported by the I/O bank in which the pin is located, and input signal levels compatible with the I/O standard selected. The FF pin should be treated as a sensitive asynchronous signal. When defining pin placement and board layout, simultaneously switching outputs (SSOs) and their effects on sensitive asynchronous pins must be considered.

Unused FF or I/O pins are tristated with weak pull-up. This default configuration applies to both Flash\*Freeze mode and normal operation mode. No user intervention is required.



Table 3-1 shows the Flash\*Freeze pin location on the available packages. The Flash\*Freeze pin location is independent of device (except for a PQ208 package), allowing migration to larger or smaller IGLOO devices while maintaining the same pin location on the board. Refer to the "Flash\*Freeze Technology and Low Power Modes" chapter of the IGLOOe FPGA Fabric User's Guide for more information on I/O states during Flash\*Freeze mode.

Table 3-1 • Flash\*Freeze Pin Locations for IGLOOe Devices

Package	Flash*Freeze Pin	
FG256	Т3	
FG484	W6	

## **JTAG Pins**

Low power flash devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). VCC must also be powered for the JTAG state machine to operate, even if the device is in bypass mode; VJTAG alone is insufficient. Both VJTAG and VCC to the part must be supplied to allow JTAG signals to transition the device. Isolating the JTAG power supply in a separate I/O bank gives greater flexibility in supply selection and simplifies power supply and PCB design. If the JTAG interface is neither used nor planned for use, the VJTAG pin together with the TRST pin could be tied to GND.

#### TCK Test Clock

Test clock input for JTAG boundary scan, ISP, and UJTAG. The TCK pin does not have an internal pull-up/-down resistor. If JTAG is not used, Microsemi recommends tying off TCK to GND through a resistor placed close to the FPGA pin. This prevents JTAG operation in case TMS enters an undesired state.

Note that to operate at all VJTAG voltages, 500  $\Omega$  to 1 k $\Omega$  will satisfy the requirements. Refer to Table 3-2 for more information.

Table 3-2 • Recommended Tie-Off Values for the TCK and TRST Pins

VJTAG	Tie-Off Resistance <sup>1,2</sup>
VJTAG at 3.3 V	200 Ω to 1 kΩ
VJTAG at 2.5 V	200 Ω to 1 kΩ
VJTAG at 1.8 V	500 Ω to 1 kΩ
VJTAG at 1.5 V	500 Ω to 1 kΩ

#### Notes:

- 1. The TCK pin can be pulled-up or pulled-down.
- 2. The TRST pin is pulled-down.
- 3. Equivalent parallel resistance if more than one device is on the JTAG chain



Table 3-3 • TRST and TCK Pull-Down Recommendations

VJTAG	Tie-Off Resistance*
VJTAG at 3.3 V	200 Ω to 1 kΩ
VJTAG at 2.5 V	200 Ω to 1 kΩ
VJTAG at 1.8 V	500 Ω to 1 kΩ
VJTAG at 1.5 V	500 Ω to 1 kΩ

Note: Equivalent parallel resistance if more than one device is on the JTAG chain

#### TDI Test Data Input

Serial input for JTAG boundary scan, ISP, and UJTAG usage. There is an internal weak pull-up resistor on the TDI pin.

#### TDO Test Data Output

Serial output for JTAG boundary scan, ISP, and UJTAG usage.

#### TMS Test Mode Select

The TMS pin controls the use of the IEEE 1532 boundary scan pins (TCK, TDI, TDO, TRST). There is an internal weak pull-up resistor on the TMS pin.

#### TRST Boundary Scan Reset Pin

The TRST pin functions as an active-low input to asynchronously initialize (or reset) the boundary scan circuitry. There is an internal weak pull-up resistor on the TRST pin. If JTAG is not used, an external pull-down resistor could be included to ensure the test access port (TAP) is held in reset mode. The resistor values must be chosen from Table 3-2 and must satisfy the parallel resistance value requirement. The values in Table 3-2 correspond to the resistor recommended when a single device is used, and the equivalent parallel resistor when multiple devices are connected via a JTAG chain.

In critical applications, an upset in the JTAG circuit could allow entrance to an undesired JTAG state. In such cases, Microsemi recommends tying off TRST to GND through a resistor placed close to the FPGA pin.

Note that to operate at all VJTAG voltages, 500  $\Omega$  to 1 k $\Omega$  will satisfy the requirements.

## **Special Function Pins**

#### NC No Connect

This pin is not connected to circuitry within the device. These pins can be driven to any voltage or can be left floating with no effect on the operation of the device.

#### DC Do Not Connect

This pin should not be connected to any signals on the PCB. These pins should be left unconnected.

## **Packaging**

Semiconductor technology is constantly shrinking in size while growing in capability and functional integration. To enable next-generation silicon technologies, semiconductor packages have also evolved to provide improved performance and flexibility.

Microsemi consistently delivers packages that provide the necessary mechanical and environmental protection to ensure consistent reliability and performance. Microsemi IC packaging technology efficiently supports high-density FPGAs with large-pin-count Ball Grid Arrays (BGAs), but is also flexible enough to accommodate stringent form factor requirements for Chip Scale Packaging (CSP). In addition, Microsemi offers a variety of packages designed to meet your most demanding application and economic requirements for today's embedded and mobile systems.



## **Related Documents**

### **User's Guides**

IGLOOe FPGA Fabric User's Guide
http://www.microsemi.com/soc/documents/IGLOOe UG.pdf

## **Packaging Documents**

The following documents provide packaging information and device selection for low power flash devices.

#### **Product Catalog**

http://www.microsemi.com/soc/documents/ProdCat PIB.pdf

Lists devices currently recommended for new designs and the packages available for each member of the family. Use this document or the datasheet tables to determine the best package for your design, and which package drawing to use.

#### Package Mechanical Drawings

http://www.microsemi.com/soc/documents/PckgMechDrwngs.pdf

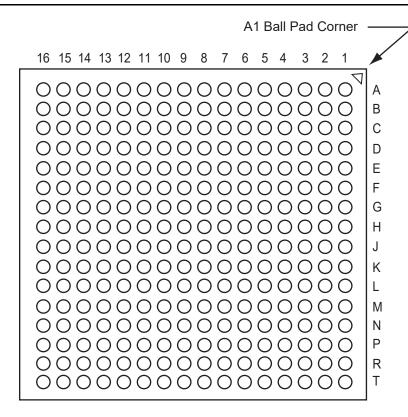
This document contains the package mechanical drawings for all packages currently or previously supplied by Microsemi. Use the bookmarks to navigate to the package mechanical drawings.

Additional packaging materials: http://www.microsemi.com/soc/products/solutions/package/docs.aspx.



## 4 – Package Pin Assignments

## **FG256**



Note: This is the bottom view of the package.

#### Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.microsemi.com/soc/products/solutions/package/docs.aspx.



FG256		FG256		FG256	
Pin Number	AGLE600 Function	Pin Number	AGLE600 Function	Pin Number	AGLE600 Function
A1	GND	C5	GAC0/IO02NDB0V0	E9	IO21NDB1V0
A2	GAA0/IO00NDB0V0	C6	GAC1/IO02PDB0V0	E10	VCCIB1
A3	GAA1/IO00PDB0V0	C7	IO15NDB0V2	E11	VCCIB1
A4	GAB0/IO01NDB0V0	C8	IO15PDB0V2	E12	VMV1
A5	IO05PDB0V0	C9	IO20PDB1V0	E13	GBC2/IO38PDB2V0
A6	IO10PDB0V1	C10	IO25NDB1V0	E14	IO37NDB2V0
A7	IO12PDB0V2	C11	IO27PDB1V0	E15	IO41NDB2V0
A8	IO16NDB0V2	C12	GBC0/IO33NDB1V1	E16	IO41PDB2V0
A9	IO23NDB1V0	C13	VCCPLB	F1	IO124PDB7V0
A10	IO23PDB1V0	C14	VMV2	F2	IO125PDB7V0
A11	IO28NDB1V1	C15	IO36NDB2V0	F3	IO126PDB7V0
A12	IO28PDB1V1	C16	IO42PDB2V0	F4	IO130NDB7V1
A13	GBB1/IO34PDB1V1	D1	IO128PDB7V1	F5	VCCIB7
A14	GBA0/IO35NDB1V1	D2	IO129PDB7V1	F6	GND
A15	GBA1/IO35PDB1V1	D3	GAC2/IO132PDB7V1	F7	VCC
A16	GND	D4	VCOMPLA	F8	VCC
B1	GAB2/IO133PDB7V1	D5	GNDQ	F9	VCC
B2	GAA2/IO134PDB7V1	D6	IO09NDB0V1	F10	VCC
В3	GNDQ	D7	IO09PDB0V1	F11	GND
B4	GAB1/IO01PDB0V0	D8	IO13PDB0V2	F12	VCCIB2
B5	IO05NDB0V0	D9	IO21PDB1V0	F13	IO38NDB2V0
В6	IO10NDB0V1	D10	IO25PDB1V0	F14	IO40NDB2V0
В7	IO12NDB0V2	D11	IO27NDB1V0	F15	IO40PDB2V0
B8	IO16PDB0V2	D12	GNDQ	F16	IO45PSB2V1
В9	IO20NDB1V0	D13	VCOMPLB	G1	IO124NDB7V0
B10	IO24NDB1V0	D14	GBB2/IO37PDB2V0	G2	IO125NDB7V0
B11	IO24PDB1V0	D15	IO39PDB2V0	G3	IO126NDB7V0
B12	GBC1/IO33PDB1V1	D16	IO39NDB2V0	G4	GFC1/IO120PPB7V0
B13	GBB0/IO34NDB1V1	E1	IO128NDB7V1	G5	VCCIB7
B14	GNDQ	E2	IO129NDB7V1	G6	VCC
B15	GBA2/IO36PDB2V0	E3	IO132NDB7V1	G7	GND
B16	IO42NDB2V0	E4	IO130PDB7V1	G8	GND
C1	IO133NDB7V1	E5	VMV0	G9	GND
C2	IO134NDB7V1	E6	VCCIB0	G10	GND
C3	VMV7	E7	VCCIB0	G11	VCC
C4	VCCPLA	E8	IO13NDB0V2	G12	VCCIB2



FG256			FG256		FG256	
Pin Number	AGLE600 Function	Pin Number	AGLE600 Function	Pin Number	AGLE600 Function	
G13	GCC1/IO50PPB2V1	K1	GFC2/IO115PSB6V1	M5	VMV5	
G14	IO44NDB2V1	K2	IO113PPB6V1	M6	VCCIB5	
G15	IO44PDB2V1	K3	IO112PDB6V1	M7	VCCIB5	
G16	IO49NSB2V1	K4	IO112NDB6V1	M8	IO84NDB5V0	
H1	GFB0/IO119NPB7V0	K5	VCCIB6	M9	IO84PDB5V0	
H2	GFA0/IO118NDB6V1	K6	VCC	M10	VCCIB4	
НЗ	GFB1/IO119PPB7V0	K7	GND	M11	VCCIB4	
H4	VCOMPLF	K8	GND	M12	VMV3	
H5	GFC0/IO120NPB7V0	K9	GND	M13	VCCPLD	
H6	VCC	K10	GND	M14	GDB1/IO66PPB3V1	
H7	GND	K11	VCC	M15	GDC1/IO65PDB3V1	
H8	GND	K12	VCCIB3	M16	IO61NDB3V1	
H9	GND	K13	IO54NPB3V0	N1	IO105PDB6V0	
H10	GND	K14	IO57NPB3V0	N2	IO105NDB6V0	
H11	VCC	K15	IO55NPB3V0	N3	GEC1/IO104PPB6V0	
H12	GCC0/IO50NPB2V1	K16	IO57PPB3V0	N4	VCOMPLE	
H13	GCB1/IO51PPB2V1	L1	IO113NPB6V1	N5	GNDQ	
H14	GCA0/IO52NPB3V0	L2	IO109PPB6V0	N6	GEA2/IO101PPB5V2	
H15	VCOMPLC	L3	IO108PDB6V0	N7	IO92NDB5V1	
H16	GCB0/IO51NPB2V1	L4	IO108NDB6V0	N8	IO90NDB5V1	
J1	GFA2/IO117PSB6V1	L5	VCCIB6	N9	IO82NDB5V0	
J2	GFA1/IO118PDB6V1	L6	GND	N10	IO74NDB4V1	
J3	VCCPLF	L7	VCC	N11	IO74PDB4V1	
J4	IO116NDB6V1	L8	VCC	N12	GNDQ	
J5	GFB2/IO116PDB6V1	L9	VCC	N13	VCOMPLD	
J6	VCC	L10	VCC	N14	VJTAG	
J7	GND	L11	GND	N15	GDC0/IO65NDB3V1	
J8	GND	L12	VCCIB3	N16	GDA1/IO67PDB3V1	
J9	GND	L13	GDB0/IO66NPB3V1	P1	GEB1/IO103PDB6V0	
J10	GND	L14	IO60NDB3V1	P2	GEB0/IO103NDB6V0	
J11	VCC	L15	IO60PDB3V1	P3	VMV6	
J12	GCB2/IO54PPB3V0	L16	IO61PDB3V1	P4	VCCPLE	
J13	GCA1/IO52PPB3V0	M1	IO109NPB6V0	P5	IO101NPB5V2	
J14	GCC2/IO55PPB3V0	M2	IO106NDB6V0	P6	IO95PPB5V1	
J15	VCCPLC	M3	IO106PDB6V0	P7	IO92PDB5V1	
J16	GCA2/IO53PSB3V0	M4	GEC0/IO104NPB6V0	P8	IO90PDB5V1	

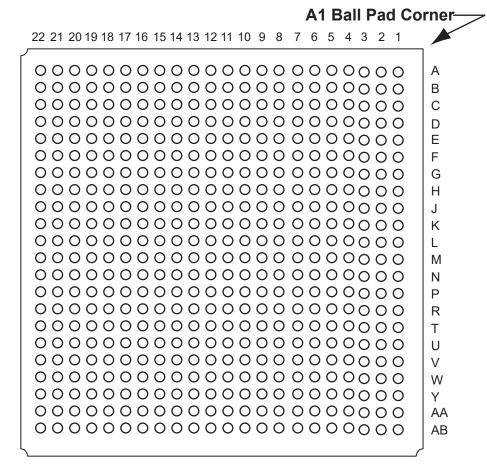


FG256		
Pin Number	AGLE600 Function	
P9	IO82PDB5V0	
P10	IO76NDB4V1	
P11	IO76PDB4V1	
P12	VMV4	
P13	TCK	
P14	VPUMP	
P15	TRST	
P16	GDA0/IO67NDB3V1	
R1	GEA1/IO102PDB6V0	
R2	GEA0/IO102NDB6V0	
R3	GNDQ	
R4	GEC2/IO99PDB5V2	
R5	IO95NPB5V1	
R6	IO91NDB5V1	
R7	IO91PDB5V1	
R8	IO83NDB5V0	
R9	IO83PDB5V0	
R10	IO77NDB4V1	
R11	IO77PDB4V1	
R12	IO69NDB4V0	
R13	GDB2/IO69PDB4V0	
R14	TDI	
R15	GNDQ	
R16	TDO	
T1	GND	
T2	IO100NDB5V2	
ТЗ	FF/GEB2/IO100PDB5 V2	
T4	IO99NDB5V2	
T5	IO88NDB5V0	
T6	IO88PDB5V0	
T7	IO89NSB5V0	
Т8	IO80NSB4V1	
Т9	IO81NDB4V1	
T10	IO81PDB4V1	
T11	IO70NDB4V0	

FG256		
Pin Number	AGLE600 Function	
T12	GDC2/IO70PDB4V0	
T13	IO68NDB4V0	
T14	GDA2/IO68PDB4V0	
T15	TMS	
T16	GND	



## **FG484**



Note: This is the bottom view of the package.

#### Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.microsemi.com/soc/products/solutions/package/docs.aspx.



Pin Number         AGLE3000 Function           A1         GND           A2         GND           A3         VCCIB0           A4         IO10NDB0V1           A5         IO10PDB0V1           A6         IO16NDB0V1           A7         IO16PDB0V1           A8         IO18PDB0V2           A9         IO24PDB0V2           A10         IO28NDB0V3           A11         IO28PDB0V3           A12         IO46PDB1V0           A13         IO54PDB1V1           A14         IO56NDB1V1           A15         IO56PDB1V1           A16         IO64NDB1V2           A17         IO64PDB1V2           A18         IO72NDB1V3           A19         IO74NDB1V4           A20         VCCIB1           A21         GND           A22         GND           AA1         GND           AA2         VCCIB6           AA3         IO228PDB5V4           AA4         IO224PDB5V3           AA5         IO218NDB5V3           AA6         IO218PDB5V2           AA8         IO212PDB5V2           AA8 <td< th=""><th colspan="3">FG484</th></td<>	FG484		
A1         GND           A2         GND           A3         VCCIB0           A4         IO10NDB0V1           A5         IO10PDB0V1           A6         IO16NDB0V1           A7         IO16PDB0V1           A8         IO18PDB0V2           A9         IO24PDB0V2           A10         IO28NDB0V3           A11         IO28PDB0V3           A12         IO46PDB1V0           A13         IO54PDB1V1           A14         IO56NDB1V1           A15         IO56PDB1V1           A16         IO64NDB1V2           A17         IO64PDB1V2           A18         IO72NDB1V3           A19         IO74NDB1V4           A20         VCCIB1           A21         GND           A22         GND           AA1         GND           AA2         VCCIB6           AA3         IO228PDB5V4           AA4         IO224PDB5V3           AA5         IO218NDB5V3           AA6         IO218PDB5V2           AA8         IO212PDB5V2           AA9         IO198PDB5V0			
A2         GND           A3         VCCIB0           A4         IO10NDB0V1           A5         IO10PDB0V1           A6         IO16NDB0V1           A7         IO16PDB0V1           A8         IO18PDB0V2           A9         IO24PDB0V2           A10         IO28NDB0V3           A11         IO28PDB0V3           A12         IO46PDB1V0           A13         IO54PDB1V1           A14         IO56NDB1V1           A15         IO56PDB1V1           A16         IO64NDB1V2           A17         IO64PDB1V2           A18         IO72NDB1V3           A19         IO74NDB1V4           A20         VCCIB1           A21         GND           A22         GND           AA1         GND           AA2         VCCIB6           AA3         IO228PDB5V4           AA4         IO224PDB5V3           AA5         IO218NDB5V3           AA6         IO212NDB5V2           AA8         IO212PDB5V2           AA9         IO198PDB5V0	Number	AGLE3000 Function	
A3 VCCIB0  A4 IO10NDB0V1  A5 IO10PDB0V1  A6 IO16NDB0V1  A7 IO16PDB0V1  A8 IO18PDB0V2  A9 IO24PDB0V2  A10 IO28NDB0V3  A11 IO28PDB0V3  A12 IO46PDB1V0  A13 IO54PDB1V1  A14 IO56NDB1V1  A15 IO56PDB1V1  A16 IO64NDB1V2  A17 IO64PDB1V2  A18 IO72NDB1V3  A19 IO74NDB1V4  A20 VCCIB1  A21 GND  A22 GND  AA1 GND  AA2 VCCIB6  AA3 IO228PDB5V4  AA4 IO224PDB5V3  AA5 IO218NDB5V3  AA6 IO212PDB5V2  AA8 IO212PDB5V2  AA8 IO212PDB5V2  AA8 IO212PDB5V2  AA8 IO212PDB5V2  AA8 IO212PDB5V2  AA8 IO212PDB5V2		GND	
A4 IO10NDB0V1 A5 IO10PDB0V1 A6 IO16NDB0V1 A7 IO16PDB0V1 A8 IO18PDB0V2 A9 IO24PDB0V2 A10 IO28NDB0V3 A11 IO28PDB0V3 A12 IO46PDB1V0 A13 IO54PDB1V1 A14 IO56NDB1V1 A15 IO56PDB1V1 A16 IO64NDB1V2 A17 IO64PDB1V2 A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA5 IO218NDB5V3 AA6 IO218PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2	A2	GND	
A5 IO10PDB0V1 A6 IO16NDB0V1 A7 IO16PDB0V1 A8 IO18PDB0V2 A9 IO24PDB0V2 A10 IO28NDB0V3 A11 IO28PDB0V3 A12 IO46PDB1V0 A13 IO54PDB1V1 A14 IO56NDB1V1 A15 IO56PDB1V1 A16 IO64NDB1V2 A17 IO64PDB1V2 A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA5 IO218NDB5V3 AA6 IO218PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A3	VCCIB0	
A6 IO16NDB0V1 A7 IO16PDB0V1 A8 IO18PDB0V2 A9 IO24PDB0V2 A10 IO28NDB0V3 A11 IO28PDB0V3 A12 IO46PDB1V0 A13 IO54PDB1V1 A14 IO56NDB1V1 A15 IO56PDB1V1 A16 IO64NDB1V2 A17 IO64PDB1V2 A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA6 IO218NDB5V3 AA6 IO218PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2	A4	IO10NDB0V1	
A7 IO16PDB0V1 A8 IO18PDB0V2 A9 IO24PDB0V2 A10 IO28NDB0V3 A11 IO28PDB0V3 A12 IO46PDB1V0 A13 IO54PDB1V1 A14 IO56NDB1V1 A15 IO56PDB1V1 A16 IO64NDB1V2 A17 IO64PDB1V2 A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA6 IO218NDB5V3 AA6 IO212NDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A5	IO10PDB0V1	
A8 IO18PDB0V2 A9 IO24PDB0V2 A10 IO28NDB0V3 A11 IO28PDB0V3 A11 IO28PDB1V0 A13 IO54PDB1V1 A14 IO56NDB1V1 A15 IO56PDB1V1 A16 IO64NDB1V2 A17 IO64PDB1V2 A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA5 IO218NDB5V3 AA6 IO212NDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A6	IO16NDB0V1	
A9 IO24PDB0V2 A10 IO28NDB0V3 A11 IO28PDB0V3 A12 IO46PDB1V0 A13 IO54PDB1V1 A14 IO56NDB1V1 A15 IO56PDB1V1 A16 IO64NDB1V2 A17 IO64PDB1V2 A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND A41 GND A42 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA6 IO218NDB5V3 AA7 IO212NDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A7	IO16PDB0V1	
A10 IO28NDB0V3 A11 IO28PDB0V3 A12 IO46PDB1V0 A13 IO54PDB1V1 A14 IO56NDB1V1 A15 IO56PDB1V1 A16 IO64NDB1V2 A17 IO64PDB1V2 A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA5 IO218NDB5V3 AA6 IO218PDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A8	IO18PDB0V2	
A11 IO28PDB0V3 A12 IO46PDB1V0 A13 IO54PDB1V1 A14 IO56NDB1V1 A15 IO56PDB1V1 A16 IO64NDB1V2 A17 IO64PDB1V2 A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA5 IO218NDB5V3 AA6 IO212NDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A9	IO24PDB0V2	
A12 IO46PDB1V0 A13 IO54PDB1V1 A14 IO56NDB1V1 A15 IO56PDB1V1 A16 IO64NDB1V2 A17 IO64PDB1V2 A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA6 IO218NDB5V3 AA6 IO212NDB5V2 AA8 IO212PDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A10	IO28NDB0V3	
A13 IO54PDB1V1 A14 IO56NDB1V1 A15 IO56PDB1V1 A16 IO64NDB1V2 A17 IO64PDB1V2 A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA5 IO218NDB5V3 AA6 IO218PDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A11	IO28PDB0V3	
A14 IO56NDB1V1 A15 IO56PDB1V1 A16 IO64NDB1V2 A17 IO64PDB1V2 A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA6 IO218NDB5V3 AA6 IO218NDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A12	IO46PDB1V0	
A15 IO56PDB1V1 A16 IO64NDB1V2 A17 IO64PDB1V2 A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA5 IO218NDB5V3 AA6 IO218PDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A13	IO54PDB1V1	
A16	A14	IO56NDB1V1	
A17 IO64PDB1V2 A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA5 IO218NDB5V3 AA6 IO218PDB5V3 AA7 IO212NDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A15	IO56PDB1V1	
A18 IO72NDB1V3 A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA5 IO218NDB5V3 AA6 IO218PDB5V3 AA7 IO212NDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A16	IO64NDB1V2	
A19 IO74NDB1V4 A20 VCCIB1 A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA5 IO218NDB5V3 AA6 IO218PDB5V3 AA7 IO212NDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A17	IO64PDB1V2	
A20 VCCIB1  A21 GND  A22 GND  AA1 GND  AA2 VCCIB6  AA3 IO228PDB5V4  AA4 IO224PDB5V3  AA5 IO218NDB5V3  AA6 IO218PDB5V3  AA7 IO212NDB5V2  AA8 IO212PDB5V2  AA9 IO198PDB5V0	A18	IO72NDB1V3	
A21 GND A22 GND AA1 GND AA2 VCCIB6 AA3 IO228PDB5V4 AA4 IO224PDB5V3 AA5 IO218NDB5V3 AA6 IO218PDB5V3 AA7 IO212NDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	A19	IO74NDB1V4	
A22 GND  AA1 GND  AA2 VCCIB6  AA3 IO228PDB5V4  AA4 IO224PDB5V3  AA5 IO218NDB5V3  AA6 IO218PDB5V3  AA7 IO212NDB5V2  AA8 IO212PDB5V2  AA9 IO198PDB5V0	A20	VCCIB1	
AA1 GND  AA2 VCCIB6  AA3 IO228PDB5V4  AA4 IO224PDB5V3  AA5 IO218NDB5V3  AA6 IO218PDB5V3  AA7 IO212NDB5V2  AA8 IO212PDB5V2  AA9 IO198PDB5V0	A21	GND	
AA2 VCCIB6  AA3 IO228PDB5V4  AA4 IO224PDB5V3  AA5 IO218NDB5V3  AA6 IO218PDB5V3  AA7 IO212NDB5V2  AA8 IO212PDB5V2  AA9 IO198PDB5V0	A22	GND	
AA3 IO228PDB5V4  AA4 IO224PDB5V3  AA5 IO218NDB5V3  AA6 IO218PDB5V3  AA7 IO212NDB5V2  AA8 IO212PDB5V2  AA9 IO198PDB5V0	AA1	GND	
AA4 IO224PDB5V3  AA5 IO218NDB5V3  AA6 IO218PDB5V3  AA7 IO212NDB5V2  AA8 IO212PDB5V2  AA9 IO198PDB5V0	AA2	VCCIB6	
AA5 IO218NDB5V3  AA6 IO218PDB5V3  AA7 IO212NDB5V2  AA8 IO212PDB5V2  AA9 IO198PDB5V0	AA3	IO228PDB5V4	
AA6 IO218PDB5V3  AA7 IO212NDB5V2  AA8 IO212PDB5V2  AA9 IO198PDB5V0	AA4	IO224PDB5V3	
AA7 IO212NDB5V2 AA8 IO212PDB5V2 AA9 IO198PDB5V0	AA5	IO218NDB5V3	
AA8 IO212PDB5V2 AA9 IO198PDB5V0	AA6	IO218PDB5V3	
AA9 IO198PDB5V0	AA7	IO212NDB5V2	
	AA8	IO212PDB5V2	
AA10 IO198NDB5V0	AA9	IO198PDB5V0	
	AA10	IO198NDB5V0	
AA11 IO188PPB4V4	AA11	IO188PPB4V4	
AA12 IO180NDB4V3	AA12	IO180NDB4V3	
AA13 IO180PDB4V3	AA13	IO180PDB4V3	

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FG484		
Pin Number	AGLE3000 Function	
AA14	IO170NDB4V2	
AA15	IO170PDB4V2	
AA16	IO166NDB4V1	
AA17	IO166PDB4V1	
AA18	IO160NDB4V0	
AA19	IO160PDB4V0	
AA20	IO158NPB4V0	
AA21	VCCIB3	
AA22	GND	
AB1	GND	
AB2	GND	
AB3	VCCIB5	
AB4	IO216NDB5V2	
AB5	IO216PDB5V2	
AB6	IO210NDB5V2	
AB7	IO210PDB5V2	
AB8	IO208NDB5V1	
AB9	IO208PDB5V1	
AB10	IO197NDB5V0	
AB11	IO197PDB5V0	
AB12	IO174NDB4V2	
AB13	IO174PDB4V2	
AB14	IO172NDB4V2	
AB15	IO172PDB4V2	
AB16	IO168NDB4V1	
AB17	IO168PDB4V1	
AB18	IO162NDB4V1	
AB19	IO162PDB4V1	
AB20	VCCIB4	
AB21	GND	
AB22	GND	
B1	GND	
B2	VCCIB7	
В3	IO06PPB0V0	
B4	IO08NDB0V0	

FG484		
Pin Number	AGLE3000 Function	
B5	IO08PDB0V0	
B6	IO14NDB0V1	
B7	IO14PDB0V1	
B8	IO18NDB0V2	
B9	IO24NDB0V2	
B10	IO34PDB0V4	
B11	IO40PDB0V4	
B12	IO46NDB1V0	
B13	IO54NDB1V1	
B14	IO62NDB1V2	
B15	IO62PDB1V2	
B16	IO68NDB1V3	
B17	IO68PDB1V3	
B18	IO72PDB1V3	
B19	IO74PDB1V4	
B20	IO76NPB1V4	
B21	VCCIB2	
B22	GND	
C1	VCCIB7	
C2	IO303PDB7V3	
C3	IO305PDB7V3	
C4	IO06NPB0V0	
C5	GND	
C6	IO12NDB0V1	
C7	IO12PDB0V1	
C8	VCC	
C9	VCC	
C10	IO34NDB0V4	
C11	IO40NDB0V4	
C12	IO48NDB1V0	
C13	IO48PDB1V0	
C14	VCC	
C15	VCC	
C16	IO70NDB1V3	
C17	IO70PDB1V3	



FG484		
Pin Number	AGLE3000 Function	
C18	GND	
C19	IO76PPB1V4	
C20	IO88NDB2V0	
C21	IO94PPB2V1	
C22	VCCIB2	
D1	IO293PDB7V2	
D2	IO303NDB7V3	
D3	IO305NDB7V3	
D4	GND	
D5	GAA0/IO00NDB0V0	
D6	GAA1/IO00PDB0V0	
D7	GAB0/IO01NDB0V0	
D8	IO20PDB0V2	
D9	IO22PDB0V2	
D10	IO30PDB0V3	
D11	IO38NDB0V4	
D12	IO52NDB1V1	
D13	IO52PDB1V1	
D14	IO66NDB1V3	
D15	IO66PDB1V3	
D16	GBB1/IO80PDB1V4	
D17	GBA0/IO81NDB1V4	
D18	GBA1/IO81PDB1V4	
D19	GND	
D20	IO88PDB2V0	
D21	IO90PDB2V1	
D22	IO94NPB2V1	
E1	IO293NDB7V2	
E2	IO299PPB7V3	
E3	GND	
E4	GAB2/IO308PDB7V4	
E5	GAA2/IO309PDB7V4	
E6	GNDQ	
E7	GAB1/IO01PDB0V0	
E8	IO20NDB0V2	
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	FG484
	FG484
Pin Number	AGLE3000 Function
E9	IO22NDB0V2
E10	IO30NDB0V3
E11	IO38PDB0V4
E12	IO44NDB1V0
E13	IO58NDB1V2
E14	IO58PDB1V2
E15	GBC1/IO79PDB1V4
E16	GBB0/IO80NDB1V4
E17	GNDQ
E18	GBA2/IO82PDB2V0
E19	IO86NDB2V0
E20	GND
E21	IO90NDB2V1
E22	IO98PDB2V2
F1	IO299NPB7V3
F2	IO301NDB7V3
F3	IO301PDB7V3
F4	IO308NDB7V4
F5	IO309NDB7V4
F6	VMV7
F7	VCCPLA
F8	GAC0/IO02NDB0V0
F9	GAC1/IO02PDB0V0
F10	IO32NDB0V3
F11	IO32PDB0V3
F12	IO44PDB1V0
F13	IO50NDB1V1
F14	IO60PDB1V2
F15	GBC0/IO79NDB1V4
F16	VCCPLB
F17	VMV2
F18	IO82NDB2V0
F19	IO86PDB2V0
F20	IO96PDB2V1
F21	IO96NDB2V1

FG484		
Pin		
Number	AGLE3000 Function	
F22	IO98NDB2V2	
G1	IO289NDB7V1	
G2	IO289PDB7V1	
G3	IO291PPB7V2	
G4	IO295PDB7V2	
G5	IO297PDB7V2	
G6	GAC2/IO307PDB7V4	
G7	VCOMPLA	
G8	GNDQ	
G9	IO26NDB0V3	
G10	IO26PDB0V3	
G11	IO36PDB0V4	
G12	IO42PDB1V0	
G13	IO50PDB1V1	
G14	IO60NDB1V2	
G15	GNDQ	
G16	VCOMPLB	
G17	GBB2/IO83PDB2V0	
G18	IO92PDB2V1	
G19	IO92NDB2V1	
G20	IO102PDB2V2	
G21	IO102NDB2V2	
G22	IO105NDB2V2	
H1	IO286PSB7V1	
H2	IO291NPB7V2	
НЗ	VCC	
H4	IO295NDB7V2	
H5	IO297NDB7V2	
H6	IO307NDB7V4	
H7	IO287PDB7V1	
H8	VMV0	
H9	VCCIB0	
H10	VCCIB0	
H11	IO36NDB0V4	
H12	IO42NDB1V0	



FG484		
Pin		
Number	AGLE3000 Function	
H13	VCCIB1	
H14	VCCIB1	
H15	VMV1	
H16	GBC2/IO84PDB2V0	
H17	IO83NDB2V0	
H18	IO100NDB2V2	
H19	IO100PDB2V2	
H20	VCC	
H21	VMV2	
H22	IO105PDB2V2	
J1	IO285NDB7V1	
J2	IO285PDB7V1	
J3	VMV7	
J4	IO279PDB7V0	
J5	IO283PDB7V1	
J6	IO281PDB7V0	
J7	IO287NDB7V1	
J8	VCCIB7	
J9	GND	
J10	VCC	
J11	VCC	
J12	VCC	
J13	VCC	
J14	GND	
J15	VCCIB2	
J16	IO84NDB2V0	
J17	IO104NDB2V2	
J18	IO104PDB2V2	
J19	IO106PPB2V3	
J20	GNDQ	
J21	IO109PDB2V3	
J22	IO107PDB2V3	
K1	IO277NDB7V0	
K2	IO277PDB7V0	
K3	GNDQ	

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	FG484
Pin Number	AGLE3000 Function
K4	IO279NDB7V0
K5	IO283NDB7V1
K6	IO281NDB7V0
K7	GFC1/IO275PPB7V0
K8	VCCIB7
K9	VCC
K10	GND
K11	GND
K12	GND
K13	GND
K14	VCC
K15	VCCIB2
K16	GCC1/IO112PPB2V3
K17	IO108NDB2V3
K18	IO108PDB2V3
K19	IO110NPB2V3
K20	IO106NPB2V3
K21	IO109NDB2V3
K22	IO107NDB2V3
L1	IO257PSB6V2
L2	IO276PDB7V0
L3	IO276NDB7V0
L4	GFB0/IO274NPB7V0
L5	GFA0/IO273NDB6V4
L6	GFB1/IO274PPB7V0
L7	VCOMPLF
L8	GFC0/IO275NPB7V0
L9	VCC
L10	GND
L11	GND
L12	GND
L13	GND
L14	VCC
L15	GCC0/IO112NPB2V3
L16	GCB1/IO113PPB2V3

	FG484
Pin	
Number	AGLE3000 Function
L17	GCA0/IO114NPB3V0
L18	VCOMPLC
L19	GCB0/IO113NPB2V3
L20	IO110PPB2V3
L21	IO111NDB2V3
L22	IO111PDB2V3
M1	GNDQ
M2	IO255NPB6V2
M3	IO272NDB6V4
M4	GFA2/IO272PDB6V4
M5	GFA1/IO273PDB6V4
M6	VCCPLF
M7	IO271NDB6V4
M8	GFB2/IO271PDB6V4
M9	VCC
M10	GND
M11	GND
M12	GND
M13	GND
M14	VCC
M15	GCB2/IO116PPB3V0
M16	GCA1/IO114PPB3V0
M17	GCC2/IO117PPB3V0
M18	VCCPLC
M19	GCA2/IO115PDB3V0
M20	IO115NDB3V0
M21	IO126PDB3V1
M22	IO124PSB3V1
N1	IO255PPB6V2
N2	IO253NDB6V2
N3	VMV6
N4	GFC2/IO270PPB6V4
N5	IO261PPB6V3
N6	IO263PDB6V3
N7	IO263NDB6V3



Pin Number         AGLE3000 Function           N8         VCCIB6           N9         VCC           N10         GND           N11         GND           N12         GND           N13         GND           N14         VCC           N15         VCCIB3           N16         IO116NPB3V0           N17         IO132NPB3V2           N18         IO117NPB3V0           N19         IO132PPB3V2           N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16 </th <th></th> <th>FG484</th>		FG484
N8         VCCIB6           N9         VCC           N10         GND           N11         GND           N12         GND           N13         GND           N14         VCC           N15         VCCIB3           N16         IO116NPB3V0           N17         IO132NPB3V2           N18         IO117NPB3V0           N19         IO132PPB3V2           N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17		
N9         VCC           N10         GND           N11         GND           N12         GND           N13         GND           N14         VCC           N15         VCCIB3           N16         IO116NPB3V0           N17         IO132NPB3V2           N18         IO117NPB3V0           N19         IO132PPB3V2           N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO259PDB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18 <th>Number</th> <th>AGLE3000 Function</th>	Number	AGLE3000 Function
N10         GND           N11         GND           N12         GND           N13         GND           N14         VCC           N15         VCCIB3           N16         IO116NPB3V0           N17         IO132NPB3V2           N18         IO117NPB3V0           N19         IO132PPB3V2           N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO138PDB3V3	N8	VCCIB6
N11         GND           N12         GND           N13         GND           N14         VCC           N15         VCCIB3           N16         IO116NPB3V0           N17         IO132NPB3V2           N18         IO117NPB3V0           N19         IO132PPB3V2           N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	N9	VCC
N12         GND           N13         GND           N14         VCC           N15         VCCIB3           N16         IO116NPB3V0           N17         IO132NPB3V2           N18         IO117NPB3V0           N19         IO132PPB3V2           N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V3	N10	GND
N13         GND           N14         VCC           N15         VCCIB3           N16         IO116NPB3V0           N17         IO132NPB3V2           N18         IO117NPB3V0           N19         IO132PPB3V2           N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V3           P19         IO138PDB3V3	N11	GND
N14         VCC           N15         VCCIB3           N16         IO116NPB3V0           N17         IO132NPB3V2           N18         IO117NPB3V0           N19         IO132PPB3V2           N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V3           P19         IO138PDB3V3	N12	GND
N15         VCCIB3           N16         IO116NPB3V0           N17         IO132NPB3V2           N18         IO117NPB3V0           N19         IO132PPB3V2           N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259NDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V3           P19         IO138PDB3V3	N13	GND
N16         IO116NPB3V0           N17         IO132NPB3V2           N18         IO117NPB3V0           N19         IO132PPB3V2           N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V3	N14	VCC
N17         IO132NPB3V2           N18         IO117NPB3V0           N19         IO132PPB3V2           N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259NDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V3	N15	VCCIB3
N18         IO117NPB3V0           N19         IO132PPB3V2           N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V3	N16	IO116NPB3V0
N19         IO132PPB3V2           N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259NDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V3           P19         IO138PDB3V3	N17	IO132NPB3V2
N20         GNDQ           N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V3           P19         IO138PDB3V3	N18	IO117NPB3V0
N21         IO126NDB3V1           N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	N19	IO132PPB3V2
N22         IO128PDB3V1           P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	N20	GNDQ
P1         IO247PDB6V1           P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	N21	IO126NDB3V1
P2         IO253PDB6V2           P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	N22	IO128PDB3V1
P3         IO270NPB6V4           P4         IO261NPB6V3           P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	P1	IO247PDB6V1
P4       IO261NPB6V3         P5       IO249PPB6V1         P6       IO259PDB6V3         P7       IO259NDB6V3         P8       VCCIB6         P9       GND         P10       VCC         P11       VCC         P12       VCC         P13       VCC         P14       GND         P15       VCCIB3         P16       GDB0/IO152NPB3V4         P17       IO136NDB3V2         P18       IO136PDB3V2         P19       IO138PDB3V3	P2	IO253PDB6V2
P5         IO249PPB6V1           P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	P3	IO270NPB6V4
P6         IO259PDB6V3           P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	P4	IO261NPB6V3
P7         IO259NDB6V3           P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	P5	IO249PPB6V1
P8         VCCIB6           P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	P6	IO259PDB6V3
P9         GND           P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	P7	IO259NDB6V3
P10         VCC           P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	P8	VCCIB6
P11         VCC           P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	P9	GND
P12         VCC           P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	P10	VCC
P13         VCC           P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	P11	VCC
P14         GND           P15         VCCIB3           P16         GDB0/IO152NPB3V4           P17         IO136NDB3V2           P18         IO136PDB3V2           P19         IO138PDB3V3	P12	VCC
P15 VCCIB3  P16 GDB0/IO152NPB3V4  P17 IO136NDB3V2  P18 IO136PDB3V2  P19 IO138PDB3V3	P13	VCC
P16 GDB0/IO152NPB3V4 P17 IO136NDB3V2 P18 IO136PDB3V2 P19 IO138PDB3V3	P14	GND
P17 IO136NDB3V2 P18 IO136PDB3V2 P19 IO138PDB3V3	P15	VCCIB3
P18 IO136PDB3V2 P19 IO138PDB3V3	P16	GDB0/IO152NPB3V4
P19 IO138PDB3V3	P17	IO136NDB3V2
	P18	IO136PDB3V2
P20 VMV3	P19	IO138PDB3V3
	P20	VMV3

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D' .	FG484
Pin Number	AGLE3000 Function
P21	IO130PDB3V2
P22	IO128NDB3V1
R1	IO247NDB6V1
R2	IO245PDB6V1
R3	VCC
R4	IO249NPB6V1
R5	IO251NDB6V2
R6	IO251PDB6V2
R7	GEC0/IO236NPB6V0
R8	VMV5
R9	VCCIB5
R10	VCCIB5
R11	IO196NDB5V0
R12	IO196PDB5V0
R13	VCCIB4
R14	VCCIB4
R15	VMV3
R16	VCCPLD
R17	GDB1/IO152PPB3V4
R18	GDC1/IO151PDB3V4
R19	IO138NDB3V3
R20	VCC
R21	IO130NDB3V2
R22	IO134PDB3V2
T1	IO243PPB6V1
T2	IO245NDB6V1
T3	IO243NPB6V1
T4	IO241PDB6V0
T5	IO241NDB6V0
T6	GEC1/IO236PPB6V0
T7	VCOMPLE
T8	GNDQ
Т9	GEA2/IO233PPB5V4
T10	IO206NDB5V1
T11	IO202NDB5V1

	FG484
Pin Number	AGLE3000 Function
T12	IO194NDB5V0
T13	IO186NDB4V4
T14	IO186PDB4V4
T15	GNDQ
T16	VCOMPLD
T17	VJTAG
T18	GDC0/IO151NDB3V4
T19	GDA1/IO153PDB3V4
T20	IO144PDB3V3
T21	IO140PDB3V3
T22	IO134NDB3V2
U1	IO240PPB6V0
U2	IO238PDB6V0
U3	IO238NDB6V0
U4	GEB1/IO235PDB6V0
U5	GEB0/IO235NDB6V0
U6	VMV6
U7	VCCPLE
U8	IO233NPB5V4
U9	IO222PPB5V3
U10	IO206PDB5V1
U11	IO202PDB5V1
U12	IO194PDB5V0
U13	IO176NDB4V2
U14	IO176PDB4V2
U15	VMV4
U16	TCK
U17	VPUMP
U18	TRST
U19	GDA0/IO153NDB3V4
U20	IO144NDB3V3
U21	IO140NDB3V3
U22	IO142PDB3V3
V1	IO239PDB6V0



	FG484
Pin Number	AGLE3000 Function
V3	GND
V4	GEA1/IO234PDB6V0
V5	GEA0/IO234NDB6V0
V6	GNDQ
V7	GEC2/IO231PDB5V4
V8	IO222NPB5V3
V9	IO204NDB5V1
V10	IO204PDB5V1
V11	IO195NDB5V0
V12	IO195PDB5V0
V13	IO178NDB4V3
V14	IO178PDB4V3
V15	IO155NDB4V0
V16	GDB2/IO155PDB4V0
V17	TDI
V18	GNDQ
V19	TDO
V20	GND
V21	IO146PDB3V4
V22	IO142NDB3V3
W1	IO239NDB6V0
W2	IO237PDB6V0
W3	IO230PSB5V4
W4	GND
W5	IO232NDB5V4
W6	FF/GEB2/IO232PDB5 V4
W7	IO231NDB5V4
W8	IO214NDB5V2
W9	IO214PDB5V2
W10	IO200NDB5V0
W11	IO192NDB4V4
W12	IO184NDB4V3
W13	IO184PDB4V3
W14	IO156NDB4V0

	FG484
Pin	
Number	AGLE3000 Function
W15	GDC2/IO156PDB4V0
W16	IO154NDB4V0
W17	GDA2/IO154PDB4V0
W18	TMS
W19	GND
W20	IO150NDB3V4
W21	IO146NDB3V4
W22	IO148PPB3V4
Y1	VCCIB6
Y2	IO237NDB6V0
Y3	IO228NDB5V4
Y4	IO224NDB5V3
Y5	GND
Y6	IO220NDB5V3
Y7	IO220PDB5V3
Y8	VCC
Y9	VCC
Y10	IO200PDB5V0
Y11	IO192PDB4V4
Y12	IO188NPB4V4
Y13	IO187PSB4V4
Y14	VCC
Y15	VCC
Y16	IO164NDB4V1
Y17	IO164PDB4V1
Y18	GND
Y19	IO158PPB4V0
Y20	IO150PDB3V4
Y21	IO148NPB3V4
Y22	VCCIB3



## 5 - Datasheet Information

## **List of Changes**

The following table lists critical changes that were made in each revision of the IGLOOe datasheet.

Revision	Changes	Page
Revision 14	All references to FBGA package FG896 have been removed from this document.	
(October 2019)	The maximum user I/Os specification in "Features and Benefits" and Table 1 • IGLOOe Product Family were revised to reflect current specifications.	I
	The maximum user I/Os specification in "General Description" section was revised to reflect current specifications.	
	The "IGLOOe Ordering Information" and "Temperature Grade Offerings" section ambient temperature specifications were revised to reflect junction temperature specifications.	III, IV
	Ambient Temperature specifications have been removed from Table 2-2 • Recommended Operating Conditions <sup>1</sup> . Note 2 was added.	2-2
Revision 13 (December 2012)	The "IGLOOe Ordering Information" section has been updated to mention "Y" as "Blank" mentioning "Device Does Not Include License to Implement IP Based on the Cryptography Research, Inc. (CRI) Patent Portfolio" (SAR 43176).  Also added the missing heading 'Supply Voltage' under V2.	II
	The note in Table 2-143 • IGLOOe CCC/PLL Specification and Table 2-144 • IGLOOe CCC/PLL Specification referring the reader to SmartGen was revised to refer instead to the online help associated with the core (SAR 42568).	2-91, 2-92
	Live at Power-Up (LAPU) has been replaced with 'Instant On'.	NA
Revision 12 (September 2012)	The "Security" section was modified to clarify that Microsemi does not support read-back of programmed data.	1-2
	Libero Integrated Design Environment (IDE) was changed to Libero System-on-Chip (SoC) throughout the document (SAR 40272).	N/A



Revision	Changes	Page
Revision 11 (August 2012)	The drive strength, IOL, and IOH value for 3.3 V GTL and 2.5 V GTL was changed from 25 mA to 20 mA in the following tables (SAR 37180):	
	Table 2-21 • Summary of Maximum and Minimum DC Input and Output Levels,	2-20
	Table 2-25 • Summary of I/O Timing Characteristics—Software Default Settings	2-25
	Table 2-26 • Summary of I/O Timing Characteristics—Software Default Settings	2-26
	Table 2-28 • I/O Output Buffer Maximum Resistances <sup>1</sup>	2-28
	Table 2-73 • Minimum and Maximum DC Input and Output Levels	2-51
	Table 2-77 • Minimum and Maximum DC Input and Output Levels	2-53
	Also added note stating "Output drive strength is below JEDEC specification." for Tables 2-25, 2-26, and 2-28.	
	Additionally, the IOL and IOH values for 3.3 V GTL+ and 2.5 V GTL+ were corrected from 51 to 35 (for 3.3 V GTL+) and from 40 to 33 (for 2.5 V GTL+) in table Table 2-21 (SAR 39713).	
	In Table 2-117 • Minimum and Maximum DC Input and Output Levels, VIL and VIH were revised so that the maximum is 3.6 V for all listed values of VCCI (SAR 37183).	2-65
	The following sentence was removed from the "VMVx I/O Supply Voltage (quiet)" section in the "Pin Descriptions and Packaging" section: "Within the package, the VMV plane is decoupled from the simultaneous switching noise originating from the output buffer VCCI domain" and replaced with "Within the package, the VMV plane biases the input stage of the I/Os in the I/O banks" (SAR 38318). The datasheet mentions that "VMV pins must be connected to the corresponding VCCI pins" for an ESD enhancement.	3-1



Revision	Changes	Page
Revision 10 (April 2012)	In Table 2-2 • Recommended Operating Conditions <sup>1</sup> , VPUMP programming voltage for operation was changed from "0 to 3.45 V" to "0 to 3.6 V" (SAR 32256). Values for VCCPLL at 1.2–1.5 V DC core supply voltage were changed from "1.14 to 1.26 V" to "1.14 to 1.575 V" (SAR 34701).	2-2
	The tables in the "Quiescent Supply Current" section were updated with revised notes on IDD. Table 2-8 • Power Supply State per Mode is new (SARs 34745, 36949).	2-7
	$t_{\text{DOUT}}$ was corrected to $t_{\text{DIN}}$ in Figure 2-4 • Input Buffer Timing Model and Delays (example) (SAR 37105).	2-17
	"TBD" for 3.3 V LVCMOS Wide Range in Table 2-28 • I/O Output Buffer Maximum Resistances <sup>1</sup> and Table 2-30 • I/O Short Currents IOSH/IOSL was replaced by "Same as regular 3.3 V LVCMOS" (SAR 33855). Values were also added for 1.2 V LVCMOS and 1.2 V LVCMOS Wide Range.	2-28, 2-30
	The formulas in the table notes for Table 2-29 • I/O Weak Pull-Up/Pull-Down Resistances were corrected (SAR 34753).	2-29
	IOSH and IOSL values were added to 3.3 V LVCMOS Wide Range Table 2-40 • Minimum and Maximum DC Input and Output Levels, 1.2 V LVCMOS Table 2-64 • Minimum and Maximum DC Input and Output Levels, and 1.2 V LVCMOS Wide Range Table 2-68 • Minimum and Maximum DC Input and Output Levels (SAR 33855).	2-35, 2-47, 2-48
	Figure 2-48 • FIFO Read and Figure 2-49 • FIFO Write have been added (SAR 34844).	2-103
	Values for $F_{DDRIMAX}$ and $F_{DDOMAX}$ were added to the tables in the Input DDR "Timing Characteristics" section and Output DDR "Timing Characteristics" section (SAR 34802).	2-77,2- 81
	Minimum pulse width High and Low values were added to the tables in the "Global Tree Timing Characteristics" section. The maximum frequency for global clock parameter was removed from these tables because a frequency on the global is only an indication of what the global network can do. There are other limiters such as the SRAM, I/Os, and PLL. SmartTime software should be used to determine the design frequency (SAR 36952).	2-89
Revision 9 (March 2012)	The "In-System Programming (ISP) and Security" section and "Security" section were revised to clarify that although no existing security measures can give an absolute guarantee, Microsemi FPGAs implement the best security available in the industry (SAR 34665).	I, 1-2
	The Y security option and Licensed DPA Logo were added to the "IGLOOe Ordering Information" section. The trademarked Licensed DPA Logo identifies that a product is covered by a DPA counter-measures license from Cryptography Research (SAR 34725).	III
	The following sentence was removed from the "Advanced Architecture" section:	1-3
	"In addition, extensive on-chip programming circuitry allows for rapid, single-voltage (3.3 V) programming of IGLOOe devices via an IEEE 1532 JTAG interface" (SAR 34685).	
	The "Specifying I/O States During Programming" section is new (SAR 34696).	1-7
	Values for VCCPLL at 1.5 V DC core supply voltage were changed from "1.4 to 1.6 V" to "1.425 to 1.575 V" in Table 2-2 • Recommended Operating Conditions <sup>1</sup> (SAR 32292).	2-2
	The reference to guidelines for global spines and VersaTile rows, given in the "Global Clock Contribution—P <sub>CLOCK</sub> " section, was corrected to the "Spine Architecture" section of the Global Resources chapter in the <i>IGLOOe FPGA Fabric User's Guide</i> (SAR 34731).	2-13



Revision	Changes	Page
Revision 9 (continued)	The example in the paragraph above Table 2-31 • Duration of Short Circuit Event before Failure was revised to change the maximum temperature from 110°C to 100°C, with an example of six months instead of three months (SAR 32287).	2-31
	The notes regarding drive strength in the "Summary of I/O Timing Characteristics – Default I/O Software Settings" section, "3.3 V LVCMOS Wide Range" section and "1.2 V LVCMOS Wide Range" section tables were revised for clarification. They now state that the minimum drive strength for the default software configuration when run in wide range is $\pm 100~\mu A$ . The drive strength displayed in software is supported in normal range only. For a detailed I/V curve, refer to the IBIS models (SAR 34766).	2-23, 2-35, 2-48
	The AC Loading figures in the "Single-Ended I/O Characteristics" section were updated to match tables in the "Summary of I/O Timing Characteristics – Default I/O Software Settings" section (SAR 34886).	2-32
	The following sentence was deleted from the "2.5 V LVCMOS" section (SAR 34793): "It uses a 5 V-tolerant input buffer and push-pull output buffer."	2-38
	Table 2-143 • IGLOOe CCC/PLL Specification and Table 2-144 • IGLOOe CCC/PLL Specification were updated. A note was added to both tables indicating that when the CCC/PLL core is generated by Microsemi core generator software, not all delay values of the specified delay increments are available (SAR 34818).	2-91, 2-92
	The following figures were deleted. Reference was made to a new application note, Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs, which covers these cases in detail (SAR 34869).	
	Figure 2-46 • Write Access after Write onto Same Address	
	Figure 2-47 • Read Access after Write onto Same Address	
	Figure 2-48 • Write Access after Read onto Same Address	2-95,
	The port names in the SRAM "Timing Waveforms", SRAM "Timing Characteristics" tables, Figure 2-50 • FIFO Reset, and the FIFO "Timing Characteristics" tables were revised to ensure consistency with the software names (SAR 35749).	2-98, 2-104, 2-106
	The "Pin Descriptions and Packaging" chapter is new (SAR 34768).	3-1
	Package names used in the "Package Pin Assignments" section were revised to match standards given in <i>Package Mechanical Drawings</i> (SAR 34768)	4-1
July 2010	The versioning system for datasheets has been changed. Datasheets are assigned a revision number that increments each time the datasheet is revised. The "IGLOOe Device Status" table on page II indicates the status for each device in the device family.	N/A

Revision	Changes	Page
Revision 8 (Nov 2009)	The version changed to v2.0 for IGLOOe datasheet chapters, indicating the datasheet contains information based on final characterization.	N/A
Product Brief v2.0	The "Pro (Professional) I/O" section was revised to add "Hot-swappable and cold-sparing I/Os."	I
	The "Reprogrammable Flash Technology" section was revised to add "250 MHz (1.5 V systems) and 160 MHz (1.2 V systems) System Performance."	I
	Definitions of hot-swap and cold-sparing were added to the "Pro I/Os with Advanced I/O Standards" section.	1-7
DC and Switching Characteristics v2.0	3.3 V LVCMOS and 1.2 V LVCMOS Wide Range support was added to the datasheet. This affects all tables that contained 3.3 V LVCMOS and 1.2 V LVCMOS data.	N/A



Revision	Changes	Page
	IIL and IIH input leakage current information was added to all "Minimum and Maximum DC Input and Output Levels" tables.	N/A
	Values for 1.2 V wide range DC core supply voltage were added to Table 2-2 • Recommended Operating Conditions <sup>1</sup> . Table notes regarding 3.3 V wide range and the core voltage required for programming were added to the table.	2-2
	The data in Table 2-6 • Temperature and Voltage Derating Factors for Timing Delays (1.5 V DC core supply voltage) and Table 2-7 • Temperature and Voltage Derating Factors for Timing Delays (1.2 V DC core supply voltage) was revised.	2-6
	3.3 V LVCMOS wide range data was included in Table 2-13 • Summary of I/O Input Buffer Power (per pin) – Default I/O Software Settings and Table 2-14 • Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings <sup>1</sup> . Table notes were added in connection with this data.	2-9, 2-10
	The temperature was revised from 110°C to 100°C in Table 2-31 • Duration of Short Circuit Event before Failure and Table 2-33 • I/O Input Rise Time, Fall Time, and Related I/O Reliability*.	2-31, 2-31
	The tables in the "Overview of I/O Performance" section and "Detailed I/O DC Characteristics" sectionwere revised to include 3.3 V LVCMOS and 1.2 V LVCMOS wide range.	2-20, 2-28
	Most tables were updated in the following sections, revising existing values and adding information for 3.3 V and 1.2 V wide range: "Single-Ended I/O Characteristics"	2-32, 2-51, 2-62
	"Voltage-Referenced I/O Characteristics" "Differential I/O Characteristics"	
	The value for "Delay range in block: fixed delay" was revised in Table 2-143 • IGLOOe CCC/PLL Specification and Table 2-144 • IGLOOe CCC/PLL Specification.	2-91, 2-92
	The timing characteristics tables for RAM4K9 and RAM512X18 were updated, including renaming of the address collision parameters.	2-98 – 2-101
Revision 7 (Apr 2009) Product Brief v1.4 DC and Switching Characteristics Advance v0.4	The -F speed grade is no longer offered for IGLOOe devices and was removed from the documentation. The speed grade column and note regarding -F speed grade were removed from "IGLOOe Ordering Information". The "Speed Grade and Temperature Grade Matrix" section was removed.	III, IV



Revision	Changes	Page
Revision 6 (Feb 2009) Product Brief v1.3	The "Pro (Professional) I/O" section was revised to add two bullets regarding wide range power supply voltage support.	1
	3.0 V was added to the list of supported voltages in the "Pro I/Os with Advanced I/O Standards" section. The "Wide Range I/O Support" section is new.	1-7
Revision 5 (Oct 2008) Product Brief v1.2	The Quiescent Current values in Table 1 • IGLOOe Product Family table were updated.	I
Revision 4 (Jul 2008) Product Brief v1.1 DC and Switching Characteristics Advance v0.3	As a result of the Libero IDE v8.4 release, Actel now offers a wide range of core voltage support. The document was updated to change 1.2 V / 1.5 V to 1.2 V to 1.5 V.	N/A
Revision 3 (Jun 2008) DC and Switching Characteristics Advance v0.2	Tables have been updated to reflect default values in the software. The default I/O capacitance is 5 pF. Tables have been updated to include the LVCMOS 1.2 V I/O set.  DDR Tables have two additional data points added to reflect both edges for Input DDR setup and hold time.  The power data table has been updated to match SmartPower data rather then simulation values.	N/A
	Table 2-144 • IGLOOe CCC/PLL Specification was updated to add VMV to the VCCI parameter row and remove the word "output" from the parameter description for VCCI. Table note 3 was added.	2-92
	Table 2-2 • Recommended Operating Conditions <sup>1</sup> was updated to include the T <sub>J</sub> parameter. Table note 9 is new.	2-2
	In Table 2-3 • Flash Programming Limits – Retention, Storage, and Operating Temperature1, the maximum operating junction temperature was changed from 110° to 100°.	2-3
	VMV was removed from Table 2-4 • Overshoot and Undershoot Limits 1, 3. The title of the table was revised to remove "as measured on quiet I/Os." Table note 2 was revised to remove "estimated SSO density over cycles." Table note 3 was deleted.	2-3
	The "PLL Behavior at Brownout Condition" section is new.	2-4
	Figure 2-2 • V2 Devices – I/O State as a Function of VCCI and VCC Voltage Levels is new.	2-5
	EQ 2 was updated. The temperature was changed to 100°C, and therefore the end result changed.	2-6
	The table notes for Table 2-9 • Quiescent Supply Current (IDD), IGLOOe Flash*Freeze Mode*, Table 2-10 • Quiescent Supply Current (IDD) Characteristics, IGLOOe Sleep Mode*, and Table 2-11 • Quiescent Supply Current (IDD) Characteristics, IGLOOe Shutdown Mode* were updated to remove VMV and include PDC6 and PDC7. VCCI and VJTAG were removed from the statement about IDD in the table note for Table 2-11 • Quiescent Supply Current (IDD) Characteristics, IGLOOe Shutdown Mode*.	2-7
	Note 2 of Table 2-12 • Quiescent Supply Current (IDD) Characteristics, No Flash*Freeze Mode <sup>1</sup> was updated to include VCCPLL. Note 4 was updated to include PDC6 and PDC7.	2-8
	Table note 3 was added to Table 2-13 • Summary of I/O Input Buffer Power (per pin) – Default I/O Software Settings and referenced for 1.2 V LVCMOS.	2-9



Revision	Changes	Page
Revision 3 (cont'd)	Table 2-14 • Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings <sup>1</sup> was updated to change PDC3 to PDC7. The table notes were updated to reflect that power was measured on VCCI <sub>.</sub> Table note 4 is new.	2-10
	Table 2-16 • Different Components Contributing to the Static Power Consumption in IGLOO Devices and Table 2-18 • Different Components Contributing to the Static Power Consumption in IGLOO Devices were updated to add PDC6 and PDC7, and to change the definition for PDC5 to bank quiescent power.	2-11, 2-12
	A table subtitle was added for Table 2-18 • Different Components Contributing to the Static Power Consumption in IGLOO Devices.	2-12
	The "Total Static Power Consumption—P <sub>STAT</sub> " section was updated to revise the calculation of P <sub>STAT</sub> , including PDC6 and PDC7.	2-13
	Footnote 1 was updated to include information about $P_{AC13}$ . The PLL Contribution equation was changed from: $P_{PLL} = P_{AC13} + P_{AC14} * FCLKOUT$ to $PPLL = P_{DC4} + P_{AC13} * F_{CLKOUT}$ .	2-14
	The "Timing Model" was updated to be consistent with the revised timing numbers.	2-16
	In Table 2-22 • Summary of Maximum and Minimum DC Input Levels, $\rm T_J$ was changed to $\rm T_A$ in notes 1 and 2.	2-22
	Table 2-22 • Summary of Maximum and Minimum DC Input Levels was updated to included a hysteresis value for 1.2 V LVCMOS (Schmitt trigger mode).	2-22
	All AC Loading figures for single-ended I/O standards were changed from Datapaths at 35 pF to 5 pF.	N/A
	The "1.2 V LVCMOS (JESD8-12A)" section is new.	2-47
Revision 2 (Jun 2008) Product Brief v1.0	The product brief section of the datasheet was divided into two sections and given a version number, starting at v1.0. The first section of the document includes features, benefits, ordering information, and temperature and speed grade offerings. The second section is a device family overview.	N/A
Revision 2 (cont'd) Packaging v1.1	The naming conventions changed for the following pins in the "FG484" for the A3GLE600:  Pin Number New Function Name J19 IO45PPB2V1 K20 IO45NPB2V1 M2 IO114NPB6V1 N1 IO114PPB6V1 N4 GFC2/IO115PPB6V1 P3 IO115NPB6V1	N/A
Revision 1 (Mar 2008) Product Brief rev. 1	The "Low Power" section was updated to change "1.2 V and 1.5 V Core Voltage" to "1.2 V and 1.5 V Core and I/O Voltage." The text "(from 25 $\mu$ W)" was removed from "Low Power Active FPGA Operation." 1.2_V was added to the list of core and I/O voltages in the "Pro (Professional) I/O"	l, 1-7
Revision 0 (Jan 2008)	and "Pro I/Os with Advanced I/O Standards" section sections.  This document was previously in datasheet Advance v0.4. As a result of moving to the handbook format, Actel has restarted the version numbers. The new version number is 51700096-001-0.	N/A



Revision	Changes	Page
Advance v0.4 (December 2007)	The Table 1 • IGLOOe Product Family table was updated to change the maximum number of user I/Os for AGLE3000.	I
	The "IGLOOe FPGAs Package Sizes Dimensions" table table is new. Package dimensions were removed from the "I/Os Per Package <sup>1</sup> " table. The number of I/Os was updated for FG896.	II
	A note regarding marking information was added to the "IGLOOe Ordering Information" table.	III
	Table 2-4 • IGLOOe CCC/PLL Specification and Table 2-5 • IGLOOe CCC/PLL Specification were updated.	2-18, 2-19
	The "During Flash*Freeze Mode" section was updated to include information about the output of the I/O to the FPGA core.	2-60
	Figure 2-38 • Flash*Freeze Mode Type 1 – Timing Diagram was updated to modify the LSICC signal.	2-56
	Table 2-32 • Flash*Freeze Pin Location in IGLOOe Family Packages (device-independent) was updated for the FG896 package.	2-64
	Figure 2-40 • Flash*Freeze Mode Type 2 – Timing Diagram was updated to modify the LSICC Signal.	2-58
	Information regarding calculation of the quiescent supply current was added to the "Quiescent Supply Current" section.	3-6
	Table 3-8 • Quiescent Supply Current (IDD), IGLOOe Flash*Freeze Mode† was updated.	3-6
	Table 3-9 • Quiescent Supply Current (IDD), IGLOOe Sleep Mode (VCC = 0 V)† was updated.	3-6
	Table 3-11 • Quiescent Supply Current, No IGLOOe Flash*Freeze Mode1 was updated.	3-6
	Table 3-99 • Minimum and Maximum DC Input and Output Levels was updated.	3-51
	Table 3-136 • JTAG 1532 and Table 3-135 • JTAG 1532 were updated.	3-95
	The "484-Pin FBGA" table for AGLE3000 is new.	4-11
	The "896-Pin FBGA" package and table for AGLE3000 is new.	4-16
Advance v0.3 (September 2007)	Cortex-M1 device information was added to the Table 1 • IGLOOe Product Family table, the "I/Os Per Package 1" table, "IGLOOe Ordering Information", and "Temperature Grade Offerings".	
Advance v0.2	The words "ambient temperature" were added to the temperature range in the "IGLOOe Ordering Information", "Temperature Grade Offerings", and "Speed Grade and Temperature Grade Matrix" sections.	III, IV
	The $T_J$ parameter in Table 3-2 • Recommended Operating Conditions was changed to $T_A$ , ambient temperature, and table notes 6–8 were added.	3-2

## **Datasheet Categories**

#### **Categories**

In order to provide the latest information to designers, some datasheet parameters are published before data has been fully characterized from silicon devices. The data provided for a given device, as highlighted in the "IGLOOe Device Status" table, is designated as either "Product Brief," "Advance," "Preliminary," or "Production." The definitions of these categories are as follows:

#### **Product Brief**

The product brief is a summarized version of a datasheet (advance or production) and contains general product information. This document gives an overview of specific device and family information.

#### Advance

This version contains initial estimated information based on simulation, other products, devices, or speed grades. This information can be used as estimates, but not for production. This label only applies to the DC and Switching Characteristics chapter of the datasheet and will only be used when the data has not been fully characterized.

#### **Preliminary**

The datasheet contains information based on simulation and/or initial characterization. The information is believed to be correct, but changes are possible.

#### **Production**

This version contains information that is considered to be final.

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